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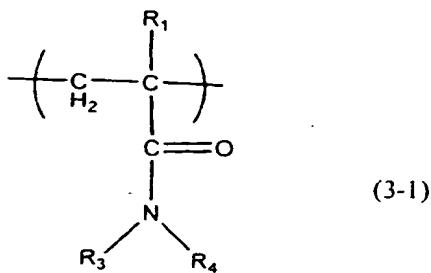
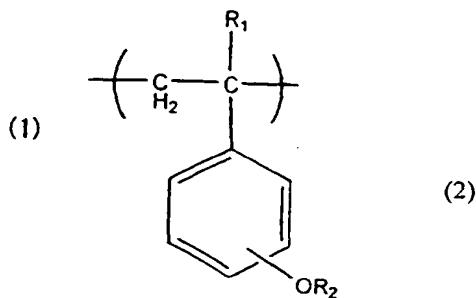
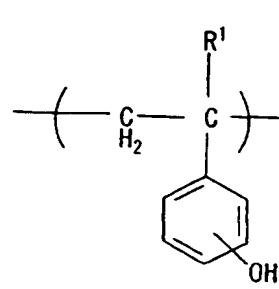
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(54) Radiation-sensitive resin composition

(57) A chemically amplified radiation-sensitive resin composition comprising a specific copolymer and a photoacid generator, wherein the copolymer contains the following recurring unit (1) and/or the recurring unit (2), and the recurring unit (3-1),

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wherein R¹ is a hydrogen or methyl, R² is a C₄₋₁₀ tertiary alkyl, R³ and R⁴ are a hydrogen, C₁₋₁₂ alkyl, C₆₋₁₅ aromatic, C₁₋₁₂ alkoxy, or R³ and R⁴ may form, in combination and together with the nitrogen atom with which the R³ and R⁴ groups bond, a C₃₋₁₅ cyclic structure, provided that R³ and R⁴ are not a hydrogen atom at the same time. The composition effectively responds to various radiations, exhibits excellent resolution and pattern configuration and minimal iso-dense bias, and can form fine patterns at a high precision and in a stable manner.

DescriptionBACKGROUND OF THE INVENTION5 Field of the Invention

[0001] The present invention relates to a radiation-sensitive resin composition and, more particularly, to a radiation-sensitive resin composition suitable as a chemically amplified positive-tone resist and a chemically amplified negative-tone resist for ultra-microprocessing using various types of radiation such as ultraviolet radiation, deep ultraviolet radiation, X-rays, and charged particle rays.

Description of the Background Art

[0002] In the field of microfabrication represented by fabrication of integrated circuit devices, the design rules have become more and more minute in order to achieve higher integration. In recent years, development of a lithographic process enabling high accuracy microfabrication with a line width of 0.3 μ m or less in a stable manner has been strongly demanded.

[0003] However, it is difficult to form such a fine pattern with high accuracy using a conventional method which utilizes visible rays (wavelength: 700-400 nm) or near ultraviolet rays (wavelength: 400-300 nm). To deal with this problem, a lithographic process using radiation with a shorter wavelength (wavelength: 300 nm or less) which can achieve a wider depth of focus and is effective for ensuring design rules with minimum dimensions has been proposed.

[0004] As a lithographic process using radiation with a short wavelength, processes using deep ultraviolet rays such as a KrF excimer laser (wavelength: 248 nm) or an ArF excimer laser (wavelength: 193 nm), X-rays such as synchrotron radiation, and charged particle rays such as ultra-deep ultraviolet rays or electron beams have been proposed. International Business Machines Corporation (IBM) has proposed a "chemically-amplified resist" as a resist exhibiting high resolution for such short wavelength radiation. At present, improvement of the chemically amplified resist is actively being undertaken.

[0005] The chemically-amplified resist contains a photoacid generator which generates an acid upon irradiation (hereinafter called "exposure"). Chemical changes in the resist film (changes in polarity, breakage of a chemical bond, cross-linking reaction, etc.) caused by the catalytic action of an acid changes solubility of the exposed area in a developer. A pattern is formed utilizing this phenomenon.

[0006] As such a chemically-amplified resist exhibiting comparatively good resist performance, a resist comprising a resin in which an alkali affinitive group in an alkali-soluble resin is protected by a group such as a ketal group (Japanese Patent Application Laid-open No. 140666/1995) or an acetal group (Japanese Patent Applications Laid-open No. 161436/1990, No. 249682/1993), a resist comprising a copolymer containing a t-butoxy(α -methyl) styrene unit, hydroxy (α -methyl) styrene unit, and t-butyl (meth)acrylate unit (Japanese Patent Application Laid-open No. 211258/1992), and the like are known.

[0007] However, since these chemically-amplified resists have peculiar problems, various problems in putting these resists to practical use for microfabrication with a design line width of 0.25 μ m or less have been pointed out.

[0008] One serious problem is a change in the resist patterns such as a change in the line width or change into T-character configuration according to post exposure delay (PED), which is a period of time from exposure to post bake.

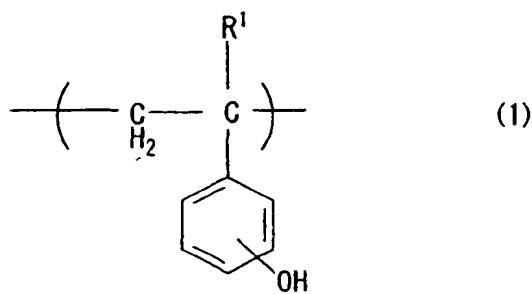
[0009] In recent years, the device structure has become more and more complicated. This requires a resist with excellent processing performance for narrow space (dark field) patterns of which the space width is narrower than an ordinary line width.

[0010] Another problem brought about by microprocessing and complication of lithographic processes is an iso-dense bias, which is a critical dimension (CD) difference between isolated patterns and dense patterns.

[0011] An object of the present invention is to provide a radiation-sensitive resin composition useful as a positive-tone or negative-tone chemically amplified resist, effectively responding to various radiations, exhibiting excellent resolution and pattern configuration, the pattern configuration and line width being affected by PED to a minimal extent, particularly excelling in narrow space processing performance, a minimal iso-dense bias, CD uniformity in various pattern designs, and capable of forming fine patterns at a high precision and in a stable manner.

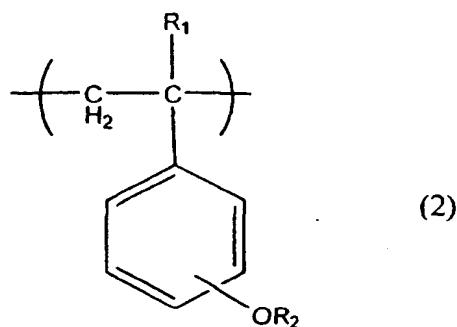
SUMMARY OF THE INVENTION

[0012] According to the present invention, the above object can be achieved by a positive-tone radiation-sensitive resin composition comprising (A1) a copolymer which comprises a recurring unit shown by the following formula (1) and/or a recurring unit shown by the following formula (2), and a recurring unit shown by the following formula (3-1), and (B) a photoacid generator,



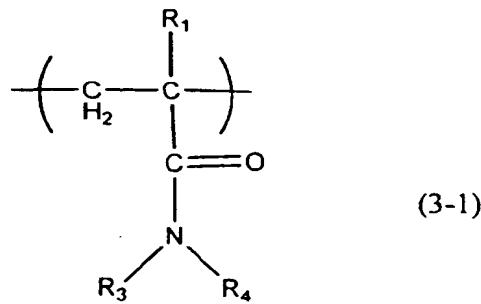
wherein R¹ represents a hydrogen atom or a methyl group;

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30 wherein R¹ represents a hydrogen atom or a methyl group, and R² represents a tertiary alkyl group having 4-10 carbon atoms;

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45 wherein R¹ represents a hydrogen atom or a methyl group, R³ and R⁴ individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted aromatic group having 6-15 carbon atoms, or a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or R³ and R⁴ may form, in combination and together with the nitrogen atom with which the R³ and R⁴ groups bond, a cyclic structure having 3-15 carbon atoms, provided that R³ and R⁴ are not a hydrogen atom at the same time.

50 [0013] The above object can also be achieved in the present invention by a negative-tone radiation-sensitive resin composition comprising (A2) a copolymer which comprises a recurring unit shown by the above formula (1) and a recurring unit shown by the above formula (3-1), (B) a photoacid generator, and (C) a compound which can cross-link the copolymer (A1) in the presence of an acid.

55 [0014] The above object can further be achieved in the present invention by a radiation-sensitive resin composition comprising (A3-1) a resin comprising a recurring unit shown by the following formula (3-2), which is insoluble or scarcely soluble in alkali and becomes alkali soluble by the action of an acid, and (B) a photoacid generator,

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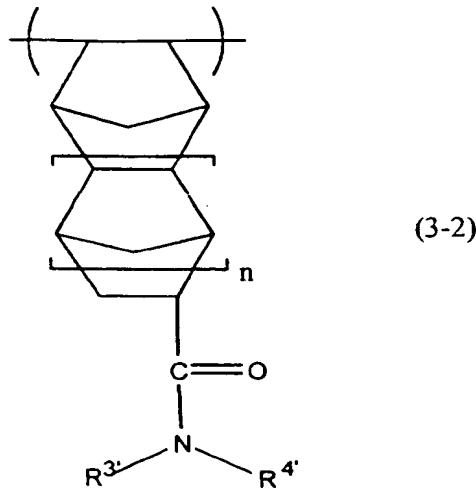
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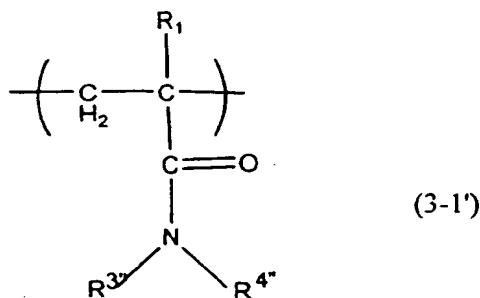
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$R^{3'}$ and $R^{4'}$ individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or a substituted or unsubstituted alkoxy carbonyl group having 2-13 carbon atoms, or $R^{3'}$ and $R^{4'}$ may form, in combination and together with the nitrogen atom with which the $R^{3'}$ and $R^{4'}$ groups bond, a cyclic structure having 3-15 carbon atoms, and n is an integer of 0-3.

[0015] The above object can still further be achieved in the present invention by a radiation-sensitive resin composition comprising (A3-2) a resin comprising a recurring unit shown by the following formula (3-1') and an alicyclic skeleton, which is insoluble or scarcely soluble in alkali and becomes alkali soluble by the action of an acid, and (B) a photoacid generator,



wherein R^1 represents a hydrogen atom or a methyl group, $R^{3''}$ and $R^{4''}$ individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or a substituted or unsubstituted alkoxy carbonyl group having 2-13 carbon atoms, or $R^{3''}$ and $R^{4''}$ may form, in combination and together with the nitrogen atom with which the $R^{3''}$ and $R^{4''}$ groups bond, a cyclic structure having 3-10 carbon atoms.

[0016] The component (A3-1) and component (A3-2) may be hereinafter referred to as the component (A3).

[0017] Other objects, features and advantages of the invention will hereinafter become more readily apparent from the following description.

DETAILED DESCRIPTION OF THE INVENTION AND PREFERRED EMBODIMENTS

[0018] The present invention will be described in detail below.

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Component (A1)

[0019] The component (A1) in the positive-tone radiation-sensitive resin composition of the present invention is a

copolymer containing either one or both of a recurring unit shown by the above formula (1) (hereinafter referred to as "recurring unit (1)") and a recurring unit shown by the above formula (2) (hereinafter called "recurring unit (2)") and a recurring unit shown by the above formula (3-1) (hereinafter referred to as "recurring unit (3-1)"). Such a copolymer is hereinafter referred to as "copolymer (A1)."

5 [0020] In the resin (A1), each recurring unit (1), (2), and (3) may be used either individually or in combination of two or more, respectively.

[0021] When the copolymer (A1) contains only either one of the recurring unit (1) or the recurring unit (2), it is desirable to use other (co)polymers containing either the recurring unit (1) or the recurring unit (2) or both, so that the copolymer components in the positive-tone radiation sensitive composition of the present invention may, as a whole, contain all 10 of the recurring unit (1), recurring unit (2), and recurring unit (3-1). The copolymer (A1) and the other (co)polymers may hereinafter be referred to collectively as "copolymer component (A1)."

[0022] The following combinations (1) to (3) of the copolymers can be given as particularly preferred specific examples of the present invention:

15 (1) a copolymer (A1) containing the recurring unit (1), recurring unit (2), and recurring unit (3-1),
 (2) combination of a copolymer (A1) containing the recurring unit (1) and recurring unit (3-1) and another copolymer containing the recurring unit (1) and recurring unit (2), and
 (3) combination of a copolymer (A1) containing the recurring unit (2) and recurring unit (3-1) and another copolymer containing the recurring unit (1) and recurring unit (2).

20 [0023] The content of the recurring unit (1) in all copolymers in the positive tone radiation sensitive composition is 20-90 mol%, preferably 30-85 mol%, and still more preferably 40-80 mol% of the total amount of the recurring units (1), (2), and (3-1). If the content of the recurring unit (1) is too small, sensitivity as a resist tends to decrease. If the content is too large, the resulting pattern shape may be impaired.

25 [0024] The amount of the recurring unit (2) is usually 5-50 mol%, preferably 5-30 mol% of the total amount of the recurring units (1), (2), and (3-1). If the content of the recurring unit (2) is too small, pattern resolution as a resist tends to decrease. If the content is too large, environmental resistance may be impaired.

[0025] The amount of the recurring unit (3-1) is usually 0.01-30 mol%, preferably 0.1-20 mol% of the total amount 30 of the recurring units (1), (2), and (3-1). If the content of the recurring unit (3-1) is too small, iso-dense bias as a resist tends to be impaired. If the content is too large, solubility in solvents tends to decrease.

Recurring unit (1)

35 [0026] As examples of preferable monomers which provide the recurring unit (1) in the copolymer (A1), o-hydroxy-styrene, m-hydroxystyrene, p-hydroxystyrene, o-hydroxy- α -methylstyrene, m-hydroxy- α -methylstyrene, p-hydroxy- α -methylstyrene, and the like can be given. These monomers may be used either individually or in combination of two or more.

Recurring unit (2)

40 [0027] As examples of the tertiary alkyl group having 4-10 carbon atoms represented by R² in the recurring unit (2), a t-butyl group, 1,1-dimethylpropyl group, 1,1-dimethylbutyl group, 1,1-dimethylpentyl group, 1,1-dimethylhexyl group, 1,1-dimethylheptyl group, 1,1-dimethyloctyl group, 1-methyl-1-ethylpropyl group, 1-methyl-1-ethylbutyl group, 1-methyl-1-ethylpentyl group, 1-methyl-1-ethylhexyl group, 1-methyl-1-ethylheptyl, methylcyclohexyl group, 1-ethylcyclohexyl group, 1-methylcyclopentyl group, 1-ethylcyclopentyl group, 1-benzylisobutanyl group, 2-norbornaneisobutanyl group, methyladamantyl group, and the like can be given.

[0028] As examples of preferable monomers which provide the recurring unit (2), a p-t-butoxystyrene, p-1,1-dimethylpropoxystyrene, p-1,1-dimethylbutoxystyrene, p-1,1-dimethylpentyloxystyrene, 1,1-dimethylhexyloxystyrene, p-1,1-dimethylheptyloxystyrene, p-1,1-dimethyloctyloxystyrene, p-(2-phenyl-2-propyloxy)styrene, p-t-butoxy- α -methylstyrene, p-1,1-dimethylpropoxy- α -methylstyrene, p-1,1-dimethylbutoxy- α -methylstyrene, p-1,1-dimethylpentyloxy- α -methylstyrene, p-1,1-dimethylhexyloxy- α -methylstyrene, p-1,1-dimethylheptyloxy- α -methylstyrene, p-1,1-dimethyloctyloxy- α -methylstyrene, methylcyclohexyloxystyrene, 1-ethylcyclohexyloxystyrene, 1-methylcyclopentyloxystyrene, 1-ethylcyclopentyloxystyrene, 1-benzylisobutanyloxystyrene and 2-norbornaneisobutanyloxystyrene, methyladamantyloxystyrene, and the like can be given. These monomers may be used either individually or in combination of 55 two or more.

Recurring unit (3-1)

[0029] Given as examples of alkyl groups having 1-12 carbon atoms represented by R³ or R⁴ in the recurring unit (3-1) are linear, branched, or cyclic alkyl groups such as a methyl group, ethyl group, n-propyl group, i-propyl group, n-butyl group, 2-methylpropyl group, 1-methylpropyl group, t-butyl group, n-pentyl group, neopentyl group, n-hexyl group, cyclopentyl group, and cyclohexyl group; linear, branched, or cyclic hydroxyalkyl groups such as a hydroxymethyl group, 2-hydroxyethyl group, 3-hydroxypropyl group, 4-hydroxybutyl group, 3-hydroxycyclopentyl group, and 4-hydroxycyclohexyl group; linear, branched, or cyclic alkoxyalkyl groups such as a methoxymethyl group, ethoxymethyl group, i-butoxymethyl group, 2-methoxyethyl group, 2-ethoxyethyl group, 3-methoxypropyl group, 3-ethoxypropyl group, 4-methoxybutyl group, 4-ethoxybutyl group, 3-methoxycyclopentyl group, 3-ethoxycyclopentyl group, 4-methoxycyclohexyl group, and 4-ethoxycyclohexyl group; linear, branched, or cyclic carboxyalkyl groups such as a carboxymethyl group, 2-carboxyethyl group, 3-carboxypropyl group, 4-carboxybutyl group, 3-carboxycyclopentyl group, and 4-carboxycyclohexyl group; and linear, branched, or cyclic cyanoalkyl groups such as a cyanomethyl group, 2-cyanoethyl group, 3-cyanopropyl group, 4-cyanobutyl group, 3-cyanocyclopentyl group, and 4-cyanocyclohexyl group.

[0030] As examples of substituted or unsubstituted aromatic groups having 6-15 carbon atoms, a phenyl group, benzyl group, tosyl group, and ansyl group can be given.

[0031] The following groups can be given as examples of substituted or unsubstituted alkoxy groups having 1-12 carbon atoms represented by R³ or R⁴: linear, branched, or cyclic alkoxy groups such as a methoxy group, ethoxy group, n-propoxy group, i-propoxy group, n-butoxy group, 2-methylpropoxy group, 1-methylpropoxy group, t-butoxy group, n-pentyloxy group, n-hexyloxy group, and cyclopentyloxy group, and cyclohexyloxy group; linear, branched, or cyclic hydroxyalkoxy groups such as hydroxymethoxy group, 2-hydroxyethoxy group, 3-hydroxypropoxy group, 4-hydroxybutoxy group, 3-hydroxycyclopentyloxy group, and 4-hydroxycyclohexyloxy group; linear, branched, or cyclic alkoxyalkoxy groups such as methoxymethoxy group, ethoxymethoxy group, 2-methoxyethoxy group, 2-ethoxyethoxy group, 3-methoxypropoxy group, 3-ethoxypropoxy group, 4-methoxybutoxy group, 4-ethoxybutoxy group, 3-methoxycyclopentyloxy group, 4-methoxycyclohexyloxy group; linear, branched, or cyclic carboxyalkoxy groups such as carboxymethoxy group, 2-carboxyethoxy group, 3-carboxypropoxy group, 4-carboxybutoxy group, 3-carboxycyclopentyloxy group, and 4-carboxycyclohexyloxy group; and linear, branched, or cyclic cyanoalkoxy groups such as cyanomethoxy group, 2-cyanoethoxy group, 3-cyanopropoxy group, 4-cyanobutoxy group, 3-cyanocyclopentyloxy group, and 4-cyanocyclohexyloxy group.

[0032] The cyclic structure having 3-15 carbon atoms, formed by the groups R³ and R⁴ and the nitrogen atom with which the R³ and R⁴ groups bond, may further contain one or more types of hetero atoms such as an oxygen atom or nitrogen atom, in addition to the nitrogen atom with which the R³ and R⁴ groups bond.

[0033] Given as examples of such a cyclic structure, in terms of the cyclic structural group containing the nitrogen atom with which the R³ and R⁴ groups bond, are 1-pyrrolidinyl group, 1-pyrrolyl group, 2-pyrrolin-1-yl group and 3-pyrrolin-1-yl group, indolyl group, 2-iso-indolyl group, 1-imidazolyl group, 1-benzimidazolyl group, 2-phenylimidazolyl group, 2-phenyl-1-benzimidazolyl group, 2-imidazolin-1-yl group, 3-imidazolin-1-yl group, 1-pyrazolyl group, indazolyl group, 1-indolinyl group, 2-isoindolinyl group, 7-purinyl group, 9-carbazolyl group, 1-perimidinyl group, 10-phenothiazinyl group, 10-phenoxazinyl group, 1-piperidino group, and morpholino group.

[0034] The above-mentioned cyclic structure may contain one or more substituents of the types previously given as examples of substituents for alkyl groups, such as a hydroxyl group alkoxy group, carboxyl group, and cyano group.

[0035] Examples of monomers providing the recurring unit (3) include (meth)acrylamide, N-methyl(meth)acrylamide, N-ethyl(meth)acrylamide, N-cyclohexyl(meth)acrylamide, N-hydroxymethyl(meth)acrylamide, N-hydroxyethyl(meth)acrylamide, N-iso-butoxyethyl(meth)acrylamide, N-phenyl(meth)acrylamide, N-benzyl(meth)acrylamide, N,N-dimethyl(meth)acrylamide, N,N-diethyl (meth)acrylamide, N,N-dicyclohexyl(meth)acrylamide, N,N-dihydroxyethyl(meth)acrylamide, N,N-diphenyl(meth)acrylamide, N,N-dibutyl(meth)acrylamide, N,N-methylene-bis(acrylamide), 1-(meth)acryloyl pyrrolidine, 1-(meth)acryloyl pyrrolidine, 1-(meth)acryloyl(2-pyrroline), 1-(meth)acryloyl (3-pyrroline), 1-(meth)acryloyl indole, 2-(meth)acryloyl iso-indole, 1-(meth)acryloyl imidazole, 1-(meth)acryloyl benzimidazole, 1-(meth)acryloyl-2-phenylimidazole, 1-(meth)acryloyl-2-phenylbenzimidazole, 1-(meth)acryloyl-2-imidazole, 1-(meth)acryloyl-3-imidazole, 1-(meth)acryloyl pyrazoline, 1-(meth)acryloyl indazole, 1-(meth)acryloyl indoline, 2-(meth)acryloyl iso-indole, N-(meth)acryloyl carbazole, 7-(meth)acryloyl purine, 9-(meth)acryloyl carbazole, 1-(meth)acryloyl perimidine, 10-(meth)acryloyl phenothiazine, 10-(meth)acryloyl phenoxazine, 1-(meth)acryloyl piperidine, 1-(meth)acryloyl morpholine, N-(meth)acryloyl piperazine, N-(meth)acryloyl piperidine, N-(meth)acryloyl pyrazoline, N-(meth)acryloyl triazole, 7-(meth)acryloyl adenine, 7-(meth)acryloyl quanine, 1-(meth)acryloyl thymine, 1-(meth)acryloyl cytosine, and 1-(meth)acryloyl uracil. These monomers may be used either individually or in combinations of two or more.

Other recurring units

[0036] The copolymer (A1) and the above-mentioned other copolymers may comprise one or more recurring units

other than the recurring units (1), (2), and (3-1) (hereinafter referred to as "other recurring units ①").

[0037] The following compounds can be given as examples of monomers providing such other recurring units ①: styrenes such as styrene, α -methylstyrene, α -methoxystyrene, m -methoxystyrene, and p -methoxystyrene; unsaturated carboxylic acids and acid anhydrides thereof such as (meth)acrylic acid, maleic acid, fumaric acid, crotonic acid, mesaconic acid, citraconic acid, and itaconic acid, maleic anhydride, and methylmaleic anhydride; esters of the above unsaturated carboxylic acids, such as methyl ester, ethyl ester, n -propyl ester, i -propyl ester, n -butyl ester, t -butyl ester, i -butyl ester, sec -butyl ester, n -amyl ester, 2-hydroxyethyl ester, 2,2-dimethyl-3-hydroxypropyl ester, benzyl ester, 1-methyl-1-ethylpropylmethyl ester, 1-methyl-1-ethylbutylmethyl ester, 1-methyl-1-ethylpentylmethyl ester, 1-methyl-1-ethylhexylmethyl ester, 1-methyl-1-ethylheptyl, methylcyclohexylmethyl ester, 1-ethylcyclohexylmethyl ester, 1-methylcyclopentylmethyl ester, 1-ethylcyclopentylmethyl ester, 1-benzylisobutanyl methyl ester, 2-norbornaneisobutanyl methyl ester, and methyladamantylmethyl ester; unsaturated nitrile compounds such as (meth)acrylonitrile, maleinitrile, fumaronitrile, mesaconitrile, citraconitrile, and itaconitrile; unsaturated amide compounds such as (meth)acrylamide, crotonamide, maleinamide, fumaramide, mesaconamide, citraconamide, and itaconamide; unsaturated imides such as maleimide and N -phenylmaleimide; unsaturated alcohols such as (meth)allylalcohol; vinyl anilines; vinyl pyridines; and other vinyl compounds such as N -vinyl- ϵ -caprolactam, N -vinylpyrrolidone, N -vinylimidazole, and N -vinylcarbazole.

[0038] These monomers may be used either individually or in combinations of two or more.

[0039] The content of the other recurring units ① in the copolymer components (A1) is usually 30 wt% or less of the total amount of the recurring units (1), (2), and (3-1).

[0040] The polystyrene-reduced weight average molecular weight (hereinafter referred to as "Mw") of the copolymer (A1) determined by gel permeation chromatography (hereinafter referred to as "GPC") is 1,000-100,000, preferably 3,000-40,000, and still more preferably 3,000-30,000. If Mw of the copolymer (A1) is less than 1,000, sensitivity and heat resistance as a resist tend to decrease. If Mw exceeds 100,000, solubility in a developer tends to decrease.

[0041] In the copolymer (A1), the ratio of Mw to Mn (polystyrene-reduced number average molecular weight determined by GPC) (Mw/Mn) is 1.0-5.0, and preferably 1.0-3.0. The Mw and the ratio of Mw to Mn of the copolymer (A1) apply to the other copolymers.

[0042] The copolymer (A1) is prepared using the following methods, for example.

(a) A method of copolymerizing a hydroxy(α -methyl)styrene with a monomer corresponding to the recurring unit (2) and a monomer corresponding to the recurring unit (3-1).

(b) A method of copolymerizing an acetoxy(α -methyl)styrene with a monomer corresponding to the recurring unit (2) and a monomer corresponding to the recurring unit (3-1), followed by hydrolysis and/or solvolysis of acetoxy groups in the copolymer using a basic catalyst.

(c) A method of copolymerizing a monomer corresponding to the recurring unit (2) and a monomer corresponding to the recurring unit (3-1), followed by hydrolysis and/or solvolysis of -OR² groups in the copolymer using an acidic catalyst.

[0043] The copolymerization by the methods (a) to (c) above is carried out by block polymerization, solution polymerization, precipitation polymerization, emulsion polymerization, suspension polymerization, block-suspension polymerization, and the like using an appropriate polymerization initiator such as a radical polymerization initiator or anionic polymerization initiator.

[0044] If necessary, the copolymer (A1) can be blended with a resin or a low molecular weight compound having good mutual solubility with the copolymer (A1) and not impairing homogeneity of the coating film when the composition is applied to a substrate.

Component (A-2)

[0045] The component (A2) in the negative tone radiation sensitive composition of the present invention is a copolymer comprising the recurring unit (1) and the recurring unit (3-1) (hereinafter referred to as "copolymer (A2)").

[0046] In the copolymer (A2), each of the recurring unit (1) and (3-1) may be used either individually or in combinations of two or more, respectively.

[0047] The copolymer (A2) may be used together with other (co)polymers in the negative tone radiation sensitive composition of the present invention. In addition, the copolymer (A2) may comprise recurring units other than the recurring unit (1) and the recurring unit (3-1) (the copolymer (A2) and other (co)polymers may hereinafter be collectively referred to as "copolymer component (A2)").

[0048] The content of the recurring unit (3-1) in the copolymer component (A2) of the negative tone radiation sensitive composition is usually 0.1-30 mol%, preferably 0.1-15 mol%, and still more preferably 0.1-10 mol% of the total amount of the recurring unit (1) and the recurring unit (3-1). If the content of the recurring unit (1) is too small, improvement in

the iso-dense bias may be insufficient; if the content is too large, sensitivity tends to decrease.

[0049] The monomers used for the copolymer (A1) can be preferably used as the monomers providing the recurring unit (1) and the recurring unit (3-1).

[0050] The copolymer (A2) and the above-mentioned other copolymers may optionally comprise the recurring unit (2) and the other recurring units (1). The content of the recurring unit (2) and the other recurring units (1) in the copolymer component (A2) of the negative tone radiation sensitive composition is 50 wt% or less, and preferably 30 wt% or less, of the total amount of the recurring units (1) and (3-1).

[0051] Mw of the copolymer (A2) is usually 500-100,000, preferably 1,000-50,000, and still more preferably 1,000-30,000. If Mw of the copolymer (A2) is less than 500, sensitivity and heat resistance as a resist tend to decrease.

If Mw exceeds 100,000, solubility in a developer tends to decrease.

[0052] Mw/Mn of the copolymer (A2) is 1.0-3.0, and preferably 1.0-2.0.

[0053] The copolymer (A2) is prepared using the following methods, for example.

(a') A method of copolymerizing a hydroxy(α -methyl)styrene with a monomer corresponding to the recurring unit (3-1).

(b') A method of copolymerizing an acetoxy(α -methyl)styrene with a monomer corresponding to the recurring unit (3-1), followed by hydrolysis and/or solvolysis of acetoxy groups in the copolymer using a basic catalyst.

(c') A method of copolymerizing a monomer corresponding to the recurring unit (2) and a monomer corresponding to the recurring unit (3-1), followed by hydrolysis and/or solvolysis of -OR² groups in the copolymer using a basic catalyst.

[0054] The copolymerization in the methods (a') to (c') is carried out by block polymerization, solution polymerization, precipitation polymerization, emulsion polymerization, suspension polymerization, block-suspension polymerization, and the like using an appropriate radical polymerization initiator.

[0055] If necessary, the copolymer (A2) can be blended with an alkali soluble resin or a low molecular weight compound having good mutual solubility with the copolymer (A2) and not impairing homogeneity of the coating film when the composition is applied to a substrate.

Component (A3)

[0056] The component (A3) of the present invention is a resin comprising a recurring unit shown by the formula (3-2) (hereinafter referred to as "recurring unit (3-2)", insoluble or scarcely soluble in alkali and becoming alkali soluble by the action of an acid (hereinafter referred to as "resin (A3-1)") or a resin comprising a recurring unit shown by the formula (3-1') (hereinafter referred to as "recurring unit (3-1')") and an alicyclic structure, insoluble or scarcely soluble in alkali and becoming alkali soluble by the action of an acid (hereinafter referred to as "resin (A3-2)").

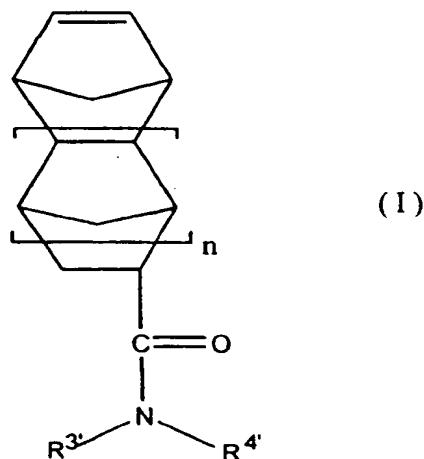
[0057] The resin (A3-1) or resin (A3-2) provides the radiation-sensitive resin composition of the present invention exhibiting superior transparency to radioactive rays, particularly to an ArF excimer laser, and exhibiting only a slight line width fluctuation due to an increase or decrease of a space width when the composition is used as a resist.

[0058] As groups represented by R³ or R⁴ in the formula (3-2), in addition to the groups previously mentioned as the groups represented by R³ or R⁴, the following substituted or unsubstituted alkoxy carbonyl groups having 2-13 carbon atoms can be given: a linear, branched, or cyclic alkoxy carbonyl groups such as a methoxycarbonyl group, ethoxycarbonyl group, n-propoxycarbonyl group, i-propoxycarbonyl group, n-butoxycarbonyl group, 2-methylpropoxycarbonyl group, 1-methylpropoxycarbonyl group, t-butoxycarbonyl group, n-pentyloxycarbonyl group, n-hexyloxycarbonyl group, cyclopentyloxycarbonyl group, and cyclohexyloxycarbonyl group; linear, branched, or cyclic hydroxy-alkoxy carbonyloxy groups such as a hydroxymethoxycarbonyl group, 2-hydroxyethoxycarbonyl group, 3-hydroxypropoxycarbonyl group, 4-hydroxybutoxycarbonyl group, 3-hydroxycyclopentyloxycarbonyl group, and 4-hydroxycyclohexyloxycarbonyl group; alkoxyalkoxycarbonyl groups such as a methoxymethoxycarbonyl group, ethoxyethoxycarbonyl group, 2-methoxyethoxycarbonyl group, 2-ethoxyethoxycarbonyl group, 3-methoxypropoxycarbonyl group, 3-ethoxypropoxycarbonyl group, 4-methoxybutoxycarbonyl group, 4-ethoxybutoxycarbonyl group, 3-methoxycyclopentyloxycarbonyl group, 3-ethoxycyclopentyloxycarbonyl group, 4-methoxycyclohexyloxycarbonyl group, and 4-ethoxycyclohexyloxycarbonyl group; linear, branched, or cyclic carboxyalkoxycarbonyloxy groups such as a carboxymethoxycarbonyl group, 2-carboxyethoxycarbonyl group, 3-carboxypropoxycarbonyl group, 4-carboxybutoxycarbonyl group, 3-carboxycyclopentyloxycarbonyl group, and 4-carboxycyclohexyloxycarbonyl group; and linear, branched, or cyclic cyanoalkoxycarbonyloxy groups such as a cyanomethoxycarbonyl group, 2-cyanoethoxycarbonyl group, 3-cyanopropoxycarbonyl group, 4-cyanobutoxycarbonyl group, 3-cyanocyclopentyloxycarbonyl group, and 4-cyanocyclohexyloxycarbonyl group.

[0059] As an integer n in the formula (3-2), either 0 or 1 is particularly preferable.

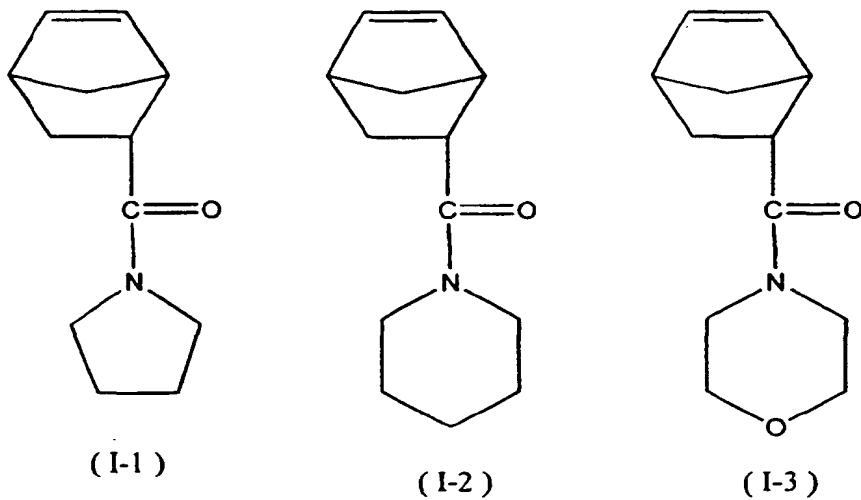
[0060] As examples of monomers which provide the recurring unit (3-2), norbornene derivatives shown by the fol-

following formula (I) (hereinafter called "norbornene derivatives (I)") can be given:



wherein R³, R⁴ and n have the same meanings as defined for the corresponding symbols in the formula (3-2).

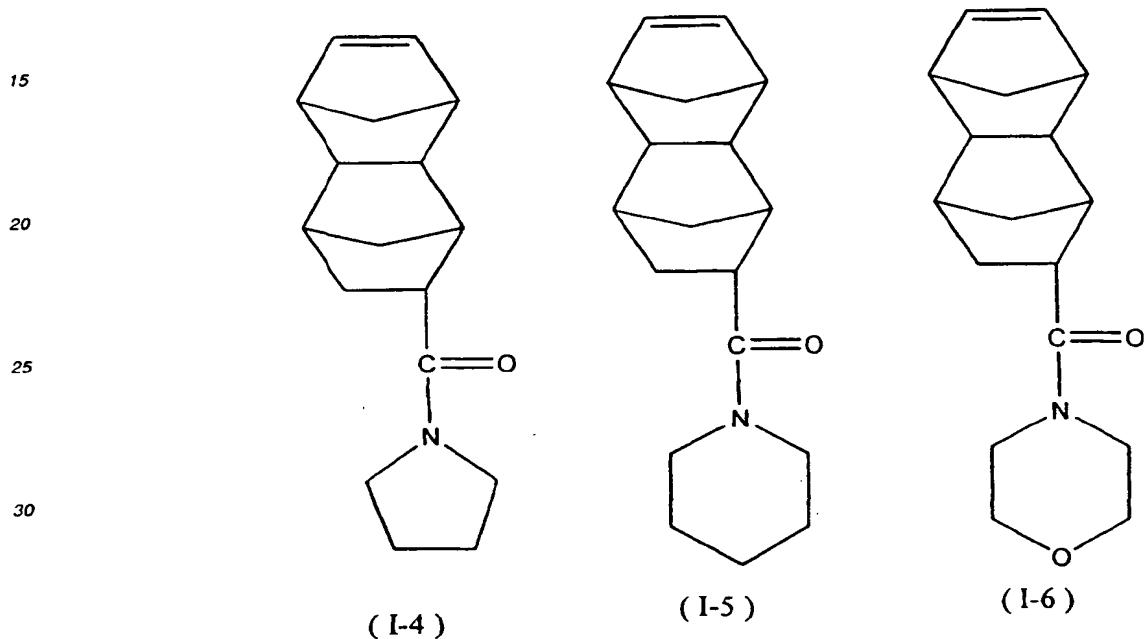
[0061] Examples of preferable norbornene derivatives (I) include: bicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide; bicyclo[2.2.1]hept-2-ene derivatives such as, N-methylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-dimethylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N-ethylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-diethylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N-methoxybicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-dimethoxybicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N-ethoxybicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-diethoxybicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N-methoxycarbonylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-di(methoxycarbonyl)bicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N-ethoxycarbonylbicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, N,N-di(ethoxycarbonyl)bicyclo[2.2.1]hept-2-ene-5-carboxylic acid amide, and bicyclo[2.2.1]hept-2-ene-5-carboxylic acid pyrrolidinyl, compounds represented by the following formula (I-1), (I-2), or (I-3).



tetracyclo[4.4.0.12.5.17.10]dodec-3-ene derivatives such as tetracyclo[4.4.0.12.5.17.10]dodec-3-ene-8-carboxylic acid amide,

N-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene-8-carboxylic acid amide,
N,N-dimethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene-8-carboxylic acid amide,
N-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene-8-carboxylic acid amide,

5 N,N-diethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N-methoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N,N-dimethoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N-ethoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide, and
 N,N-diethoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 10 N-methoxycarbonyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N,N-di(methoxycarbonyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N-ethoxycarbonyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,
 N,N-di(ethoxycarbonyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide, and
 compounds represented by the following formula (I-4), (I-5), or (I-6),



35 [0062] Of the above norbornene derivatives (I), bicyclo[2.2.1]hept-2-ene carboxylic acid amide, N,N-dimethylbicyclo[2.2.1]hept-2-ene carboxylic acid amide, N,N-diethylbicyclo[2.2.1]hept-2-ene carboxylic acid amide, the compound of the above formula (I-2), the compound of the above formula (I-3), tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene-8-carboxylic acid amide,

40 [0063] In the present invention, the norbornene derivatives (I) can be used either individually or in combination of two or more.
 [0064] The groups given for R³ and R⁴ in the formula (3-2) can be given as examples of the groups represented by R^{3*} and R^{4*} in the formula (3-1'), which include a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, and a substituted or unsubstituted alkoxy carbonyl group having 2-13 carbon atoms, as well as a cyclic structure having 3-15 carbon atoms formed by R^{3*} and R^{4*} together with the nitrogen atom with which the R^{3*} and R^{4*} groups bond.

45 [0065] Particularly preferable groups for R^{3*} and R^{4*} in the formula (3-1') are a hydrogen atom, methyl group, ethyl group, 2-hydroxyethyl group, and the like.
 [0066] As the group R¹ in the formula (3-1'), both the hydrogen atom and methyl group are preferable.
 [0067] As examples of monomers which provide the recurring unit (3-1'), monomers previously given in connection with the recurring unit (3-1) (hereinafter referred to from time to time as "(meth)acrylic acid derivatives (II)") can be given.
 [0068] Of these monomers, (meth)acrylamide, N,N-dimethyl(meth)acrylamide, (meth)acryloylmorpholine, and the

like are preferable.

[0069] In the present invention, the above monomers can be used either individually or in combination of two or more.
[0070] It is essential that the resin (A3-2) contain an alicyclic skeleton in the main chain and/or side chain of the

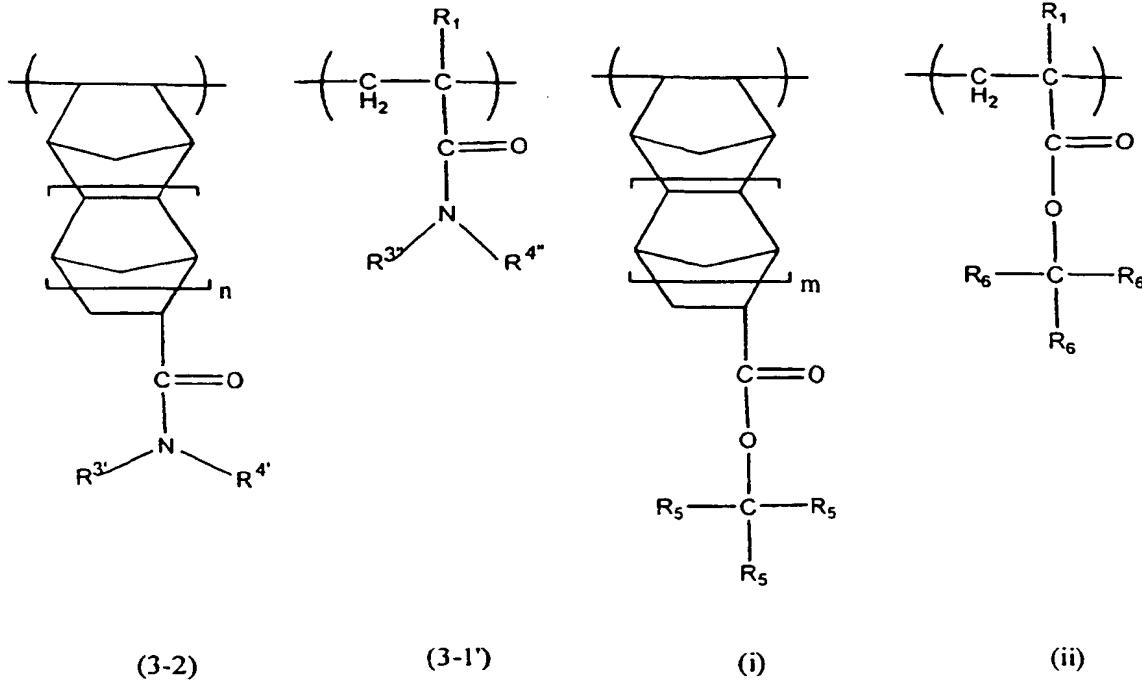
[00271] In addition, it is desirable that the resin (A3-1) and resin (A3-2) contain an oxygen atom in the main chain and/or side chain of the molecule.

[0071] In addition, it is desirable that the resin (A3-1) and resin (A3-2) contain acid-dissociating group-containing recurring units other than recurring units (3-2) and (3-1'), which dissociate in the presence of an acid to form an acidic functional group, such as carboxyl group or sulfonic acid group, in the resin.

[0072] As a preferable resin (A3-1) or (A3-2) of the present invention, a resin insoluble or scarcely soluble in alkali containing the recurring unit (3-2) and/or recurring unit (3-1'), and the recurring unit (i) and/or recurring unit (ii), shown in the following formula, and the resin insoluble in alkali containing the recurring unit (3-1') and the recurring unit (i).

10 by the following formulas, and becoming alkali soluble by the action of an acid can be given (such a resin is hereinafter referred to as "resin (α)"). A resin containing the recurring unit (3-2) and/or recurring unit (3-1') and the recurring unit (i) (hereinafter referred to as "resin (α 1)") and a resin containing the recurring unit (3-2) and/or recurring unit (3-1') and the recurring unit recurring unit (ii) (hereinafter referred to as "resin (α 2)") are particularly preferable, provided that the resin (α) and resin (α 2) must have an alicyclic skeleton in the main chain and/or side chain when these resins do not have the recurring unit (3-2) or recurring unit (i).
15

15 have the recurring unit (3-2) or recurring unit (i).



45 wherein R¹, R³, R⁴, R³¹, and R⁴¹ are the same as defined for the above; R⁵ individually represents a linear or branched alkyl group having 1-4 carbon atoms or a monovalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, provided that at least one R⁵ is a linear or branched alkyl group having 1-4 carbon atoms, or any two R⁵ groups form, in combination and together with the carbon atoms to which the two R⁵ groups bond, a divalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, with the remaining R⁵ groups being a linear or branched alkyl group having 1-4 carbon atoms; R⁶ individually represents a linear or branched alkyl group having 1-4 carbon atoms or a monovalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, provided that at least one R⁶ is a linear or branched alkyl group having 1-4 carbon atoms, or any two R⁶ groups form, in combination and together with the carbon atoms to which the two R⁶ groups bond, a divalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, with the remaining R⁵ groups being a linear or branched alkyl group having 1-4 carbon atoms; and m and n are an integer of 0-3.

55 [0073] As examples of the linear or branched alkyl group having 1-4 carbon atoms represented by R⁵ or R⁶, a methyl group, ethyl group, n-propyl group, i-propyl group, n-butyl group, 2-methylpropyl group, 1-methylpropyl group, and t-butyl group can be given.

[0074] Of these alkyl groups, a methyl group and thyl group are particularly preferable.

[0075] As examples of the monovalent alicyclic hydrocarbon group having 4-20 carbon atoms represented by R^5 or R^6 , and the divalent alicyclic hydrocarbon group having 4-20 carbon atoms formed by R^5 or R^6 , alicyclic groups derived from a cycloalkane such as norbornane, tricyclodecane, tetracyclododecane, adamantan, cyclobutane, cyclopentane, cyclohexane, cycloheptane, or cyclooctane, and groups obtained by replacing hydrogen atoms on these alicyclic groups with one or more linear, branched, or unbranched alkyl groups having 1-8 carbon atoms, such as methyl group, ethyl group, n-propyl group, i-propyl group, n-butyl group, 2-methyl propyl group, 1-methyl propyl group, or t-butyl group, can be given.

[0076] Of these monovalent and divalent alicyclic hydrocarbon groups, groups containing an alicyclic ring derived from norbornane, tricyclodecane, tetracyclododecane, adamantan, cyclopentane, or cyclohexane, or groups in which these alicyclic ring-containing groups are substituted with the above alkyl groups are preferable.

[0077] As examples of derivatives of the monovalent or divalent alicyclic hydrocarbon groups, groups having one or more substitutes, such as a hydroxyl group; a carboxyl group; a linear or branched hydroxyalkyl group having 1-4 carbon atoms such as a hydroxymethyl group, 2-hydroxyethyl group, 3-hydroxypropyl group, and 4-hydroxypropyl group; a linear or branched alkoxy group having 1-4 carbon atoms such as a methoxy group, ethoxy group, n-propoxy group, i-propoxy group, n-butoxy group, 2-methylpropoxy group, 1-methylpropoxy group, and t-butoxy group; a cyano group; a linear or branched cyanoalkyl group having 2-5 carbon atoms such as a cyanomethyl group, 2-cyanoethyl group, 3-cyanopropyl group, and 4-cyanobutyl group; and the like, can be given.

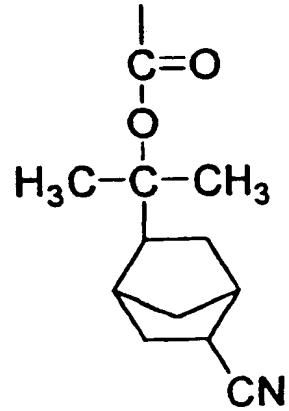
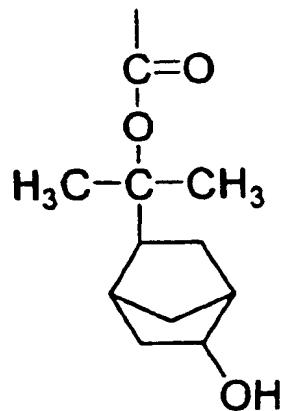
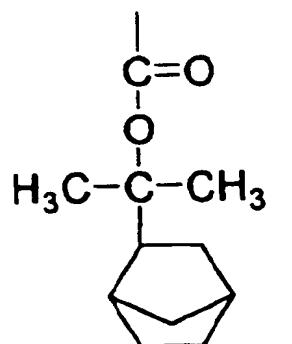
[0078] Of these substituents, a hydroxyl group, carboxyl group, hydroxymethyl group, cyano group, and the like are preferable.

[0079] In the resin (α), both the group $-COO(R^5)_3$ possessed by the recurring unit (i) and the group $-COO(R^6)_3$ possessed by the recurring unit (ii) dissociate in the presence of an acid and produce a carboxyl group. These groups $-COO(R^5)_3$ and $-COO(R^6)_3$ are hereinafter collectively referred to as "acid-dissociating groups (i)."

[0080] As specific preferable examples of the acid-dissociating groups (i), t-butoxycarbonyl group and groups shown by the following formulas (i-1) to (i-47) can be given.

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(i-1)

(i-2)

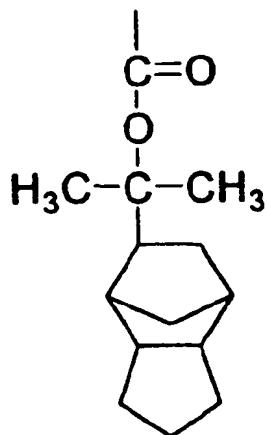
(i-3)

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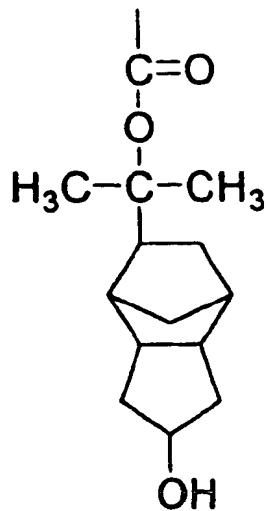
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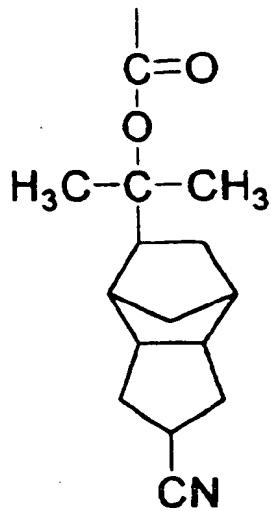
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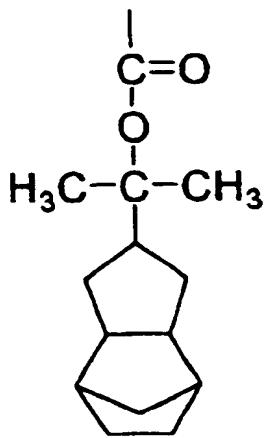
(i-4)

(i-5)

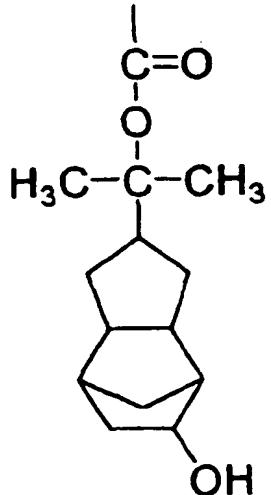
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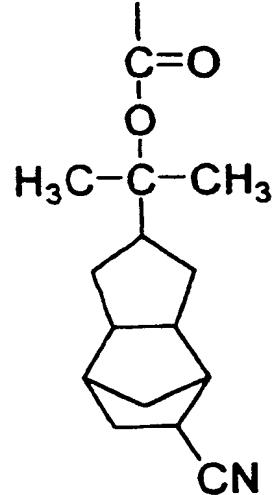
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(i-7)

(i-8)

(i-9)

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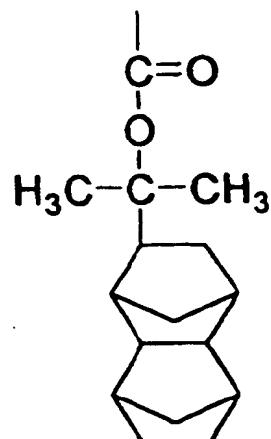
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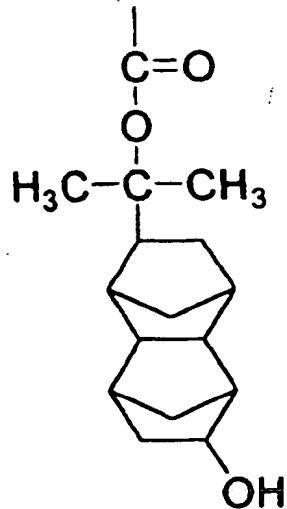
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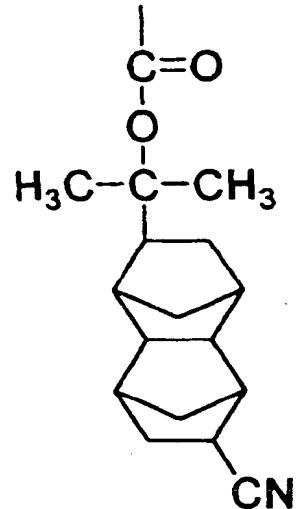
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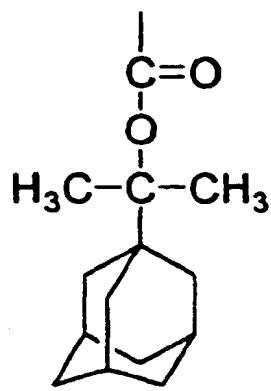
(i-10)



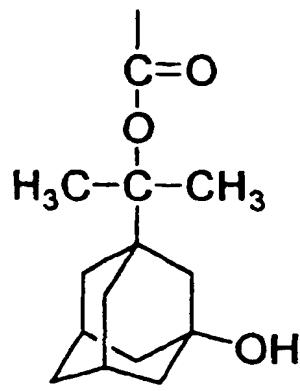
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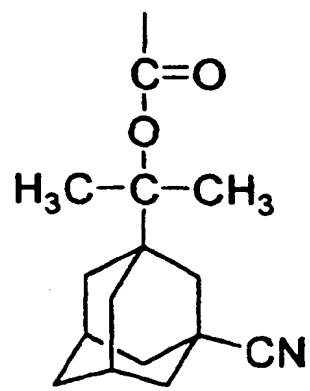
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(i-13)

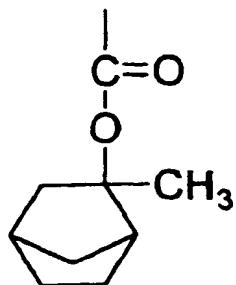


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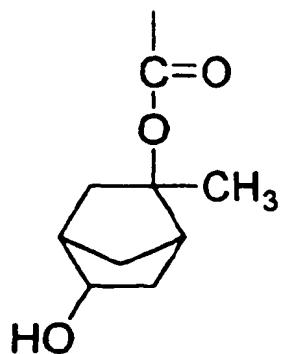


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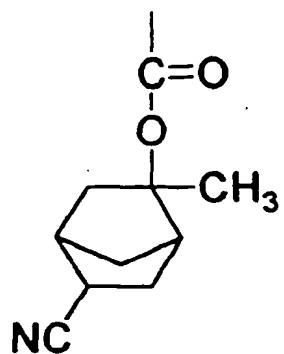
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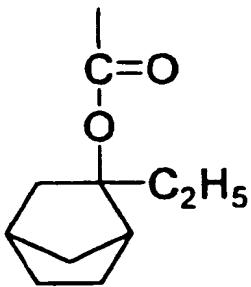


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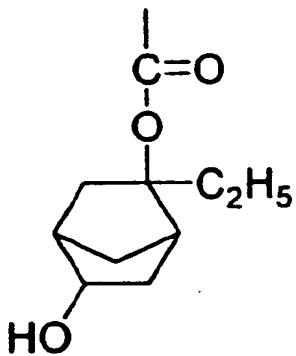


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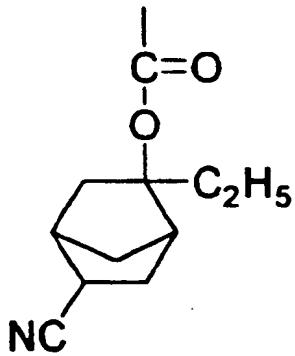
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(i-19)

(i-20)

(i-21)

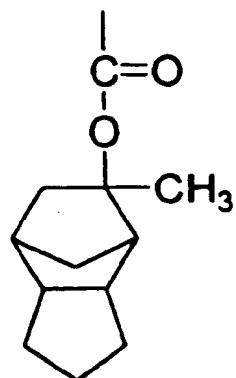
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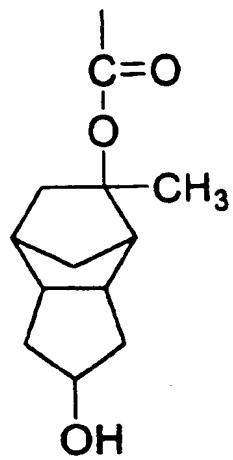
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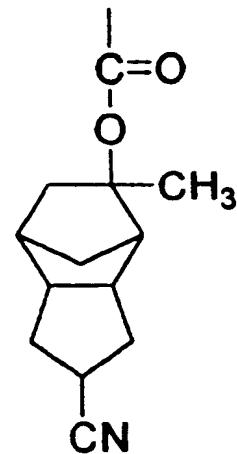
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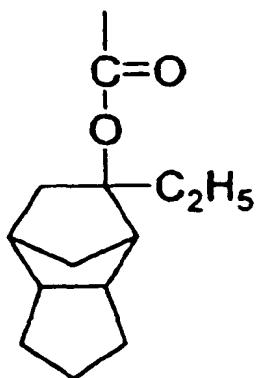
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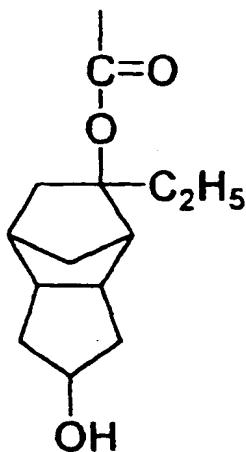
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(i-24)

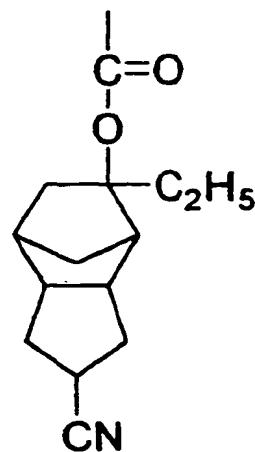
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(i-25)

(i-26)

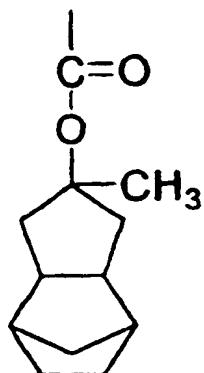
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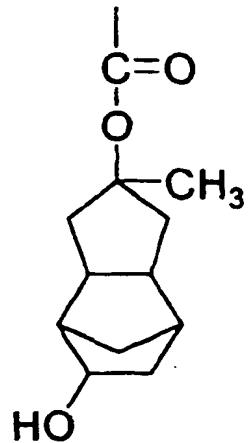
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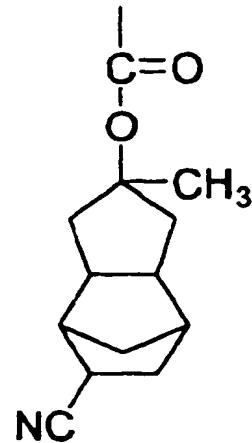
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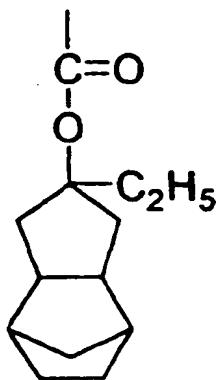
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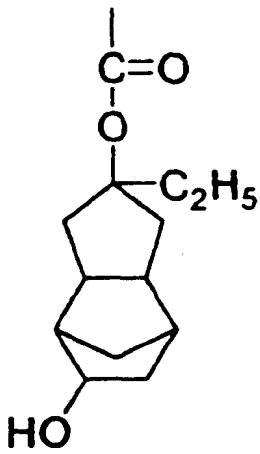
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(i-30)

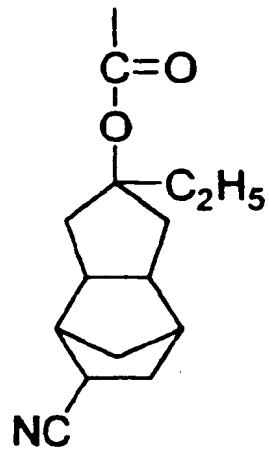
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(i-31)

(i-32)

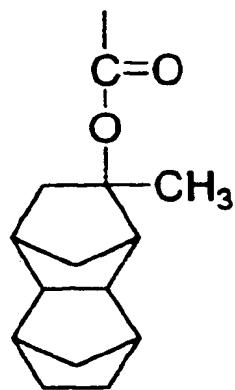
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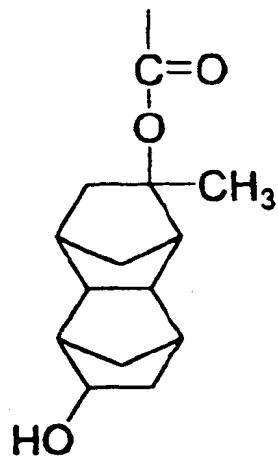
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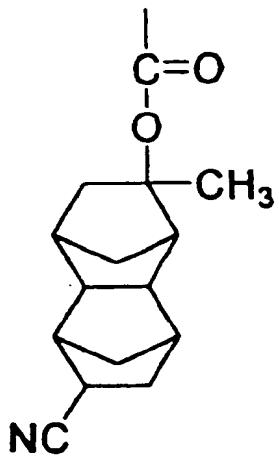
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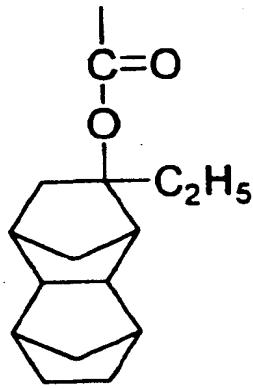
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(i-34)

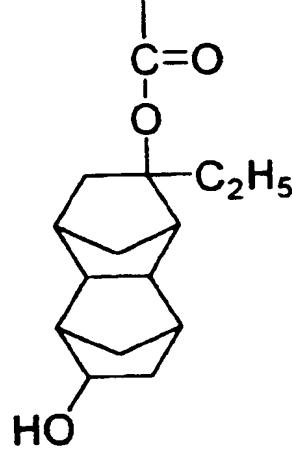
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(i-36)

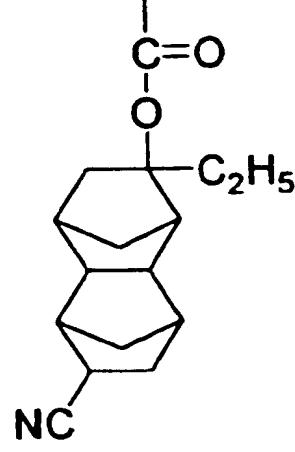
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(i-37)

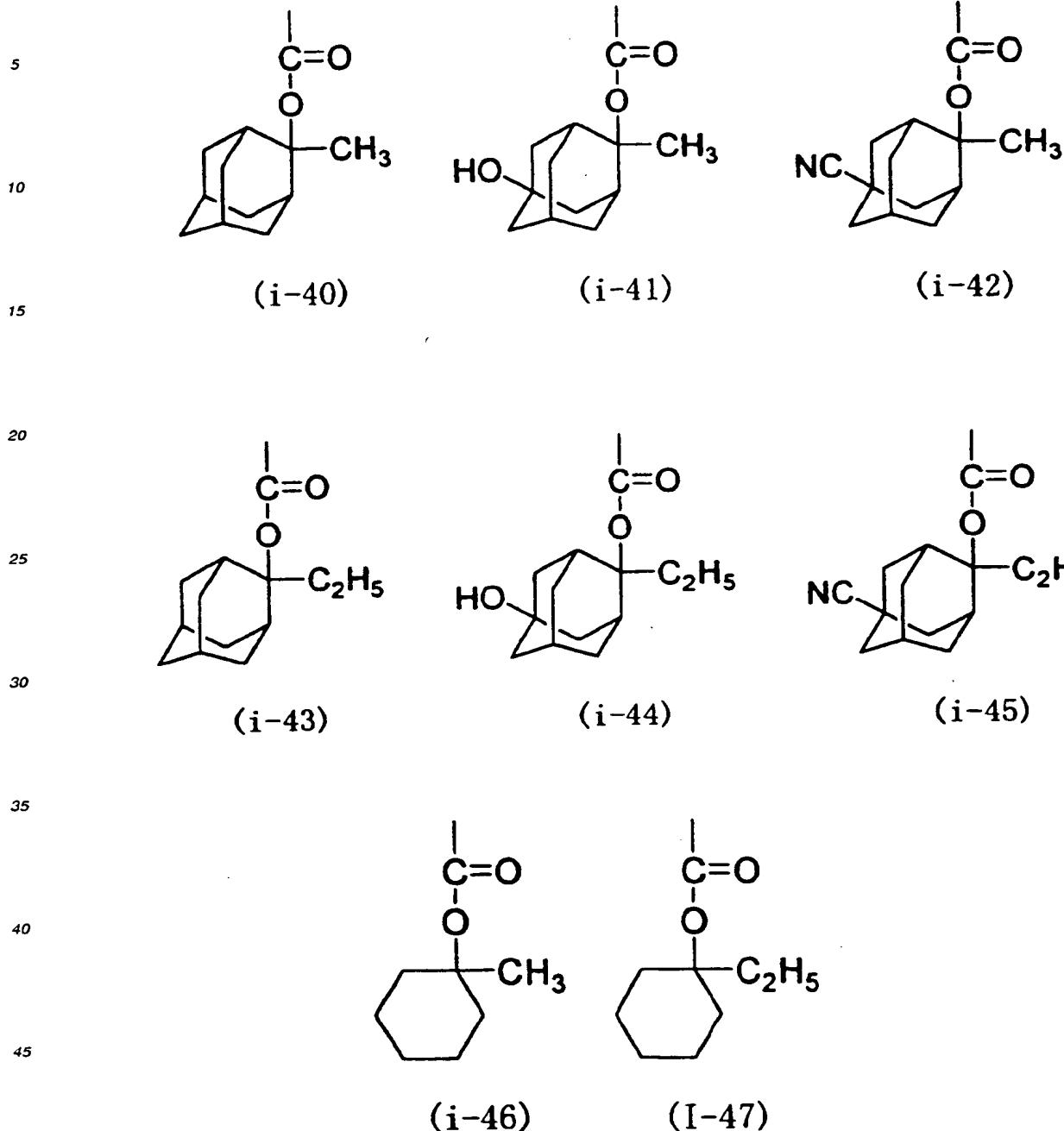
(i-38)

(i-39)

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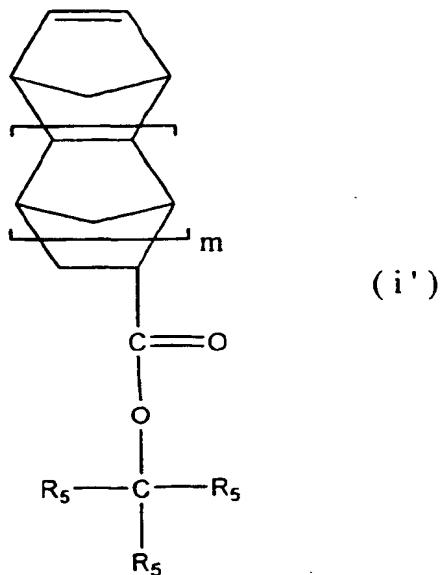


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wherein R⁵ and m are the same as defined for the above formula (i).

25 [0084] Examples of preferable norbornene derivatives (i') include: compounds having an acid-dissociating organic group (i) selected from the group consisting of t-butoxycarbonyl group and the groups shown by the formulas (i-1), (i-2), (i-10), (i-11), (i-13), (i-14), (i-16), (i-17), (i-34), (i-35), (i-40), (i-41), (i-46), or (i-47), and having m-0 in the formula (i'); and compounds having an acid-dissociating organic group (i) selected from the group consisting of t-butoxycarbonyl group and the groups shown by the formulas (i-1), (i-2), (i-10), (i-11), (i-13), (i-14), (i-16), (i-17), (i-34), (i-35), (i-40), (i-41), (i-46), or (i-47), and having m-1 in the formula (i').

[0085] The monomer providing the recurring unit (ii) is a compound derived from (meth)acrylic acid by converting the carboxyl group into the acid-dissociating group (i) (such a compound is hereinafter referred to as "(meth)acrylic acid derivatives (ii')").

30 [0086] Compounds having an acid-dissociating group (i) selected from the group consisting of t-butoxycarbonyl group and the groups shown by the formulas (i-1), (i-2), (i-10), (i-11), (i-13), (i-14), (i-16), (i-17), (i-34), (i-35), (i-40), (i-41), (i-46), or (i-47) can be given as preferable (meth) acrylic acid derivatives (ii') in the present invention.

[0087] The resin (A3) may comprise at least one recurring unit other than the recurring units (3-2), (3-1'), (i), and (ii) (hereinafter referred to as "other recurring unit (3)").

35 [0088] The following compounds can be given as examples of monomers providing such other recurring units (3): mono-functional monomers, which include:

bicyclo[2.2.1]hept-2-ene derivatives having an acid-dissociating group which dissociates in the presence of an acid and forms a carboxyl group in the resin such as 5-methoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-ethoxycarbonylbicyclo[2.2.1]hept-2-ene,

45 5-n-propoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-i-propoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-n-butoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-(2-methylpropoxy)carbonylbicyclo[2.2.1]hept-2-ene,

5-(1-methylpropoxy)carbonylbicyclo[2.2.1]hept-2-ene,

50 5-cyclohexyloxycarbonylbicyclo[2.2.1]hept-2-ene,

5-(4-t-butylcyclohexyloxy)carbonylbicyclo[2.2.1]hept-2-ene,

5-phenoxy carbonylbicyclo[2.2.1]hept-2-ene,

5-(1-ethoxyethoxy)carbonylbicyclo[2.2.1]hept-2-ene,

5-(1-cyclohexyloxyethoxy)carbonylbicyclo[2.2.1]hept-2-ene,

55 5-t-butoxycarbonylmethoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-tetrahydrofuranylmethoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-tetrahydropyranylmethoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-methyl-5-methoxycarbonylbicyclo[2.2.1]hept-2-ene,

5-*methyl*-5-*ethoxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*n-propoxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*i-propoxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*n-butoxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*(2-methylpropoxy)carbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*(1-methylpropoxy)carbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*t-butoxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*cyclohexyloxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*(4-t-butylcyclohexyloxy)carbonylbicyclo[2.2.1]hept-2-ene*,
10 5-*methyl*-5-*phenoxy carbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*(1-ethoxyethoxy)carbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*(1-cyclohexyloxyethoxy)carbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*t-butoxycarbonylmethoxycarbonylbicyclo[2.2.1]hept-2-ene*,
15 5-*methyl*-5-*tetrahydrofuranyloxycarbonylbicyclo[2.2.1]hept-2-ene*,
5-*methyl*-5-*tetrahydropyrananyloxycarbonylbicyclo[2.2.1]hept-2-ene*,
5,6-*di(methoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(ethoxycarbonyl)bicycle[2.2.1]hept-2-ene*,
5,6-*di(n-propoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
20 5,6-*di(i-propoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(n-butoxycarbonyl)bicycle[2.2.1]hept-2-ene*,
5,6-*di(2-methylpropoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(1-methylpropoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(t-butoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
25 5,6-*di(cyclohexyloxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(4-t-butylcyclohexyloxycarbonyl)bicyclo[2.2.1]hept-2-ene*, 5,6-*di(phenoxy carbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(1-ethoxyethoxy carbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(1-cyclohexyloxyethoxy carbonyl)bicyclo[2.2.1]hept-2-ene*,
30 5,6-*di(t-butoxycarbonylmethoxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(tetrahydrofuranyloxycarbonyl)bicyclo[2.2.1]hept-2-ene*,
5,6-*di(tetrahydropyrananyloxycarbonyl)bicyclo[2.2.1]hept-2-ene and the like*;
bicyclo[2.2.1]hept-2-ene and bicyclo[2.2.1]hept-2-ene derivatives such as norbornene (specifically, bicyclo[2.2.1]hept-2-ene), 5-*methylbicyclo[2.2.1]hept-2-ene*,
35 5-*ethylbicyclo[2.2.1]hept-2-ene*,
5-*n-propylbicyclo[2.2.1]hept-2-ene*,
5-*n-butylbicyclo[2.2.1]hept-2-ene*,
5-*n-pentylbicyclo[2.2.1]hept-2-ene*,
5-*n-hexylbicyclo[2.2.1]hept-2-ene*,
40 5-*hydroxybicyclo[2.2.1]hept-2-ene*,
5-*carboxybicyclo[2.2.1]hept-2-ene*,
5-*hydroxymethylbicyclo[2.2.1]hept-2-ene*,
5-*(2-hydroxyethyl)bicyclo[2.2.1]hept-2-ene*,
5-*methoxybicyclo[2.2.1]hept-2-ene*,
45 5-*ethoxybicyclo[2.2.1]hept-2-ene*,
5-*(1-methoxyethoxy)bicyclo[2.2.1]hept-2-ene*,
5-*(1-ethoxyethoxy)bicyclo[2.2.1]hept-2-ene*,
5-*(1-n-propoxyethoxy)bicyclo[2.2.1]hept-2-ene*,
5-*(1-n-butoxyethoxy)bicyclo[2.2.1]hept-2-ene*,
50 5-*(1-cyclohexyloxyethoxy)bicyclo[2.2.1]hept-2-ene*,
5-*methoxycarbonyloxybicyclo[2.2.1]hept-2-ene*,
5-*ethoxycarbonyloxybicyclo[2.2.1]hept-2-ene*,
5-*n-propoxycarbonyloxybicyclo[2.2.1]hept-2-ene*,
5-*n-butoxycarbonyloxybicyclo[2.2.1]hept-2-ene*,
55 5-*(1-methoxyethoxy)methylbicyclo[2.2.1]hept-2-ene*,
5-*(1-ethoxyethoxy)methylbicyclo[2.2.1]hept-2-ene*,
5-*(1-n-propoxyethoxy)methylbicyclo[2.2.1]hept-2-ene*,
5-*(1-n-butoxyethoxy)methylbicyclo[2.2.1]hept-2-ene*,
5-*(1-cyclohexyloxyethoxy)methylbicyclo[2.2.1]hept-2-ene*,

5-methoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5-ethoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5-n-propoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5-n-butoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5-tetrahydrofuranyloxybicyclo[2.2.1]hept-2-ene,
 5-tetrahydropyrananyloxybicyclo[2.2.1]hept-2-ene,
 5-tetrahydrofuranyloxymethylbicyclo[2.2.1]hept-2-ene,
 5-tetrahydropyrananyloxymethylbicyclo[2.2.1]hept-2-ene,
 5,6-dihydroxybicyclo[2.2.1]hept-2-ene,
 5,6-dicarboxybicyclo[2.2.1]hept-2-ene,
 5,6-di(hydroxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(2-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-dimethoxybicyclo[2.2.1]hept-2-ene,
 5,6-diethoxybicyclo[2.2.1]hept-2-ene,
 5,6-di(1-methoxyethoxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(1-ethoxyethoxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(1-n-propoxymethoxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(1-n-butoxyethoxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(1-cyclohexyloxyethoxy)bicyclo[2.2.1]hept-2-ene,
 5,6-dimethoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5,6-diethoxycarbonyloxymethylbicyclo[2.2.1]hept-2-ene,
 5,6-di(n-propoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(n-butoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di((1-methoxyethoxy)methyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di((1-ethoxyethoxy)methyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di((1-n-propoxymethoxy)methyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di((1-n-butoxyethoxy)methyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di((1-cyclohexyloxyethoxy)methyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(methoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(ethoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(n-propoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(n-butoxycarbonyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(tetrahydrofuranyloxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(tetrahydropyrananyloxy)bicyclo[2.2.1]hept-2-ene,
 5,6-di(tetrahydrofuranyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5,6-di(tetrahydropyrananyloxymethyl)bicyclo[2.2.1]hept-2-ene,
 5-hydroxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-hydroxy-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-carboxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-carboxy-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-Hydroxymethyl-5-methylbicyclo[2.2.1]hept-2-ene,
 5-Hydroxymethyl-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-(2-hydroxyethyl)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(2-hydroxyethyl)-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-methoxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-methoxy-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-ethoxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-ethoxy-5-ethylbicyclo[2.2.1]hept-2-ene,
 5-(1-methoxyethoxy)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(1-ethoxyethoxy)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(1-n-propoxymethoxy)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(1-n-butoxymethoxy)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(1-cyclohexyloxyethoxy)-5-methylbicyclo[2.2.1]hept-2-ene,
 5-methoxycarbonyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-ethoxycarbonyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-n-propoxycarbonyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-n-butoxycarbonyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
 5-(1-methoxyethoxy)methyl-5-methylbicyclo[2.2.1]hept-2-ene

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5-(1-ethoxyethoxy)methyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-(1-n-propoxyethoxy)methyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-(1-n-butoxyethoxy)methyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-(1-cyclohexyloxyethoxy)methyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-methoxycarbonyloxyethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-ethoxycarbonyloxyethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-n-propoxycarbonyloxyethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-n-butoxycarbonyloxyethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-tetrahydrofuranyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
5-tetrahydropyrananyloxy-5-methylbicyclo[2.2.1]hept-2-ene,
5-tetrahydropyrananyloxyethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-hydroxy-6-methylbicyclo[2.2.1]hept-2-ene,
5-hydroxy-6-ethylbicyclo[2.2.1]hept-2-ene,
5-carboxy-6-methylbicyclo[2.2.1]hept-2-ene,
5-carboxy-6-ethylbicyclo[2.2.1]hept-2-ene,
5-hydroxymethyl-6-methylbicyclo[2.2.1]hept-2-ene,
5-hydroxymethyl-6-ethylbicyclo[2.2.1]hept-2-ene,
5-(2-hydroxyethyl)-6-methylbicyclo[2.2.1]hept-2-ene,
5-(2-hydroxyethyl)-6-ethylbicyclo[2.2.1]hept-2-ene,
5-methoxy-6-methylbicyclo[2.2.1]hept-2-ene,
5-methoxy-6-ethylbicyclo[2.2.1]hept-2-ene,
5-ethoxy-6-methylbicyclo[2.2.1]hept-2-ene,
5-ethoxy-6-ethylbicyclo[2.2.1]hept-2-ene,
5-cyanobicyclo[2.2.1]hept-2-ene,
5-cyanomethylbicyclo[2.2.1]hept-2-ene,
5-(2-cyanoethyl)bicyclo[2.2.1]hept-2-ene,
5,6-dicyanobicyclo[2.2.1]hept-2-ene,
5,6-di(cyanomethyl)bicyclo[2.2.1]hept-2-ene,
5,6-di(2-cyanoethyl)bicyclo[2.2.1]hept-2-ene,
5-cyano-5-methylbicyclo[2.2.1]hept-2-ene,
5-cyano-5-ethylbicyclo[2.2.1]hept-2-ene,
5-cyanomethyl-5-methylbicyclo[2.2.1]hept-2-ene,
5-cyanomethyl-5-ethylbicyclo[2.2.1]hept-2-ene,
5-(2-cyanoethyl)-5-methylbicyclo[2.2.1]hept-2-ene,
5-(2-cyanoethyl)-5-ethylbicyclo[2.2.1]hept-2-ene,
5-cyano-6-methylbicyclo[2.2.1]hept-2-ene,
5-cyano-6-ethylbicyclo[2.2.1]hept-2-ene,
5-cyanomethyl-6-methylbicyclo[2.2.1]hept-2-ene,
5-cyanomethyl-6-ethylbicyclo[2.2.1]hept-2-ene,
5-(2-cyanoethyl)-6-methylbicyclo[2.2.1]hept-2-ene,
5-(2-cyanoethyl)-6-ethylbicyclo[2.2.1]hept-2-ene,
5,6-dicarboxybicyclo[2.2.1]hept-2-ene anhydride(hymic acid anhydride),
5-(2,2,2-trifluoro-1-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methyl-1-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-trifluoromethyl-1-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methoxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methyl-1-methoxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-trifluoromethyl-1-methoxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methylcarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methyl-1-methylcarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-trifluoromethyl-1-methylcarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-t-butoxycarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-methyl-1-t-butoxycarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2,2,2-trifluoro-1-trifluoromethyl-1-t-butoxycarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2-trifluoromethyl-2-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
5-(2-trifluoromethyl-2-methyl-2-hydroxyethyl)bicyclo[2.2.1]hept-2-ene,
5-[2,2-bis(trifluoromethyl)-2-hydroxyethyl]bicyclo[2.2.1]hept-2-ene,

5-(2-trifluoromethyl-2-methoxyethyl)bicyclo[2.2.1]hept-2-ene,
 5-(2-trifluoromethyl-2-methyl-2-methoxyethyl)bicyclo[2.2.1]hept-2-ene,
 5-[2,2-bis(trifluoromethyl)-2-methoxyethyl]bicyclo[2.2.1]hept-2-ene,
 5-[2-trifluoromethyl-2-methylcarbonyloxyethyl]bicyclo[2.2.1]hept-2-ene,
 5-(2-trifluoromethyl-2-methyl-2-methylcarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
 5-[2,2-bis(trifluoromethyl)-2-methylcarbonyloxyethyl]bicyclo[2.2.1]hept-2-ene,
 5-[2-trifluoromethyl-2-t-butoxycarbonyloxyethyl]bicyclo[2.2.1]hept-2-ene,
 5-(2-trifluoromethyl-2-methyl-2-t-butoxycarbonyloxyethyl)bicyclo[2.2.1]hept-2-ene,
 5-[2,2-bis(trifluoromethyl)-2-t-butoxycarbonyloxyethyl]bicyclo[2.2.1]hept-2-ene and the like;
 10 tetracyclo[4.4.0.12.5.17.10]dodec-3-ene derivatives having an acid-dissociating group which dissociates in the presence of an acid and forms a carboxyl group in the resin such as 8-methoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-ethoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-n-propoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 15 8-i-propoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-n-butoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(2-methylpropoxy) carbonyltetracyclo [4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-methylpropoxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 20 8-cyclohexyloxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene, 8-(4-t-butylcyclohexyloxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-phenoxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-ethoxyethoxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-cyclohexyloxyethoxy)carbonyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 25 8-t-butoxycarbonylmethoxycarbonyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8-tetrahydrofuranyloxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-methoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-ethoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 30 8-methyl-8-n-propoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-i-propoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-n-butoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-(2-methylpropoxy)carbonyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8-methyl-8-(1-methylpropoxy)carbonyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 35 8-methyl-8-t-butoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-cyclohexyloxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-(4-t-butylcyclohexyloxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-phenoxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec3-ene, 8-methyl-8-(1-ethoxyethoxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 40 8-methyl-8-(1-cyclohexyloxyethoxy)carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-t-butoxycarbonylmethoxycarbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-tetrahydrofuranyloxy carbonyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methyl-8-tetrahydropyrananyloxy carbonyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene.
 8,9-di(methoxycarbonyl)tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 45 8,9-di(ethoxycarbonyl)tetracyclo[4.9.0.12.5.17.10]dodec-3-ene,
 8,9-di(n-propoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(i-propoxycarbonyl)tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8, 9-di (n-butoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(2-methylpropoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 50 8,9-di (1-methylpropoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(t-butoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(cyclohexyloxy carbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(4-t-butylcyclohexyloxy carbonyl)tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8,9-di(phenoxy carbonyl)tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8,9-di(1-ethoxyethoxy carbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 55 8,9-di(1-cyclohexyloxyethoxy carbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(t-butoxycarbonylmethoxycarbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(tetrahydrofuranyloxy carbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(tetrahydropyrananyloxy carbonyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene;

tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene and other tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene derivatives such as: tetra-
 5 racyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-en ,
 8-methyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-ethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 10 8-n-propyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-n-butyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 15 8-n-pentyltetracyclo[4.4.0.1².5.1⁷.1⁰] dodec-3-ene,
 8-n-hexyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-fluorotetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 20 8-fluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-difluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-trifluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-pentafluoroethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 25 8,8-difluorotetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,9-difluorotetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,8-bis(trifluoromethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8, 9-bis (trifluoromethyl) tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-methyl-8-trifluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene, 8,8,9-trifluorotetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-
 3-ene,
 30 8,8, 9-tris (trifluoromethyl) tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene, 8,8,9,9-tetrafluorotetracyclo[4.4.0.1².5.1⁷.1⁰]do-
 dec-3-ene,
 8,8,9,9-tetrakis (trifluoromethyl) tetracyclo [4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 25 8,8-difluoro-9,9-bis(trifluoromethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,9-difluoro-8,9-bis(trifluoromethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,8,9-trifluoro-9-trifluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 30 8,8,9-trifluoro-9-trifluoromethoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,8,9-trifluoro-9-pentafluoro-n-propoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-fluoro-8-pentafluoroethyl-9,9-bis(trifluoromethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 35 8,9-difluoro-8-heptafluoro-i-propyl-9-trifluoromethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-chloro-8,9,9-trifluorotetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8,9-dichloro-8,9-bis(trifluoromethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 40 8-(2,2,2-trifluorocarboethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-methyl-8-(2,2,2-Trifluorocarboethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-hydroxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 45 8-carboxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-hydroxymethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(2-hydroxyethyl)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-methoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 50 8-ethoxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-methoxyethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-ethoxyethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8- (1-n-propoxyethoxy) tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 55 8-(1-n-butoxyethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-cyclohexyloxyethoxy)tetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-methoxycarbonyloxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-ethoxycarbonyloxytetracyclo [4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-n-propoxycarbonyloxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-n-butoxycarbonyloxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-methoxyethoxy)methyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-ethoxyethoxy)methyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-(1-n-propoxyethoxy)methyltetracyclo[4.4.0.1².5.1⁷.1⁰] dodec-3-ene,
 8- (1-cyclohexyloxyethoxy)methyltetracyclo [4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-methoxycarbonyloxyethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene ,
 55 8-ethoxycarbonyloxyethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-n-propoxycarbonyloxyethyltetracyclo [4.4.0.1².5.1⁷.1⁰]dodec-3-ene,
 8-n-butoxycarbonyloxyethyltetracyclo[4.4.0.1².5.1⁷.1⁰]dod c-3-ene,
 8-tetrahydrofuranyloxytetracyclo[4.4.0.1².5.1⁷.1⁰]dodec-3-ene,

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8-tetrahydropyranoyloxytetracyclo [4.4.0.12.5.17.10] dodec-3-ene,
 8-tetrahydrofuranoyloxyethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-tetrahydropyranoylmethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene.
 8, 9-dihydroxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 5 8, 9-dicarboxy tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8, 9-di (hydroxymethyl) tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(2-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-dimethoxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-diethoxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 10 8,9-di(1-methoxyethoxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(1-ethoxyethoxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(1-n-propoxyethoxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(1-n-butoxyethoxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(1-cyclohexyloxyethoxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 15 8,9-dimethoxycarbonyloxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-diethoxycarbonyloxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di-n-propoxycarbonyloxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di-n-butoxycarbonyloxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di[(1-methoxyethoxy)methyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 20 8,9-di[(1-ethoxyethoxy)methyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di[(1-n-propoxyethoxy)methyl]tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8,9-di[(1-n-butoxyethoxy)methyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di[(1-cyclohexyloxyethoxy)methyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 25 8,9-di(methoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene, 8,9-di(n-propoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(ethoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene, 8,9-di(n-propoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 30 8,9-di(n-butoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 8,9-di(tetrahydrofuranoyloxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(tetrahydropyranoyloxy)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 35 8,9-di(tetrahydrofuranoylmethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8,9-di(tetrahydropyranoylmethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene.
 8-hydroxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-hydroxy-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-carboxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 40 8-carboxy-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-hydroxymethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec3-ene,
 8-hydroxymethyl-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8- (2-hydroxyethyl)-8-methyltetracyclo [4.4.0.12.5.17.10]dodec-3-ene,
 8-(2-hydroxyethyl)-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 45 8-methoxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methoxy-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-ethoxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-ethoxy-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-methoxyethoxy)-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 45 8-(1-ethoxyethoxy)-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-n-propoxyethoxy)-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-n-butoxyethoxy)-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene, 8-(1-cyclohexyloxyethoxy)-8-methyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,
 50 8-methoxycarbonyloxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-ethoxycarbonyloxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-n-propoxycarbonyloxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-n-butoxycarbonyloxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene.
 8-(1-methoxyethoxy)methyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-ethoxyethoxy)methyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 55 8-(1-n-propoxyethoxy)methyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-n-butoxyethoxy)methyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-(1-cyclohexyloxyethoxy)methyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
 8-methoxycarbonyloxyethyl-8-methyltetracyclo[4.4.0.12.5.17.10] dodec-3-ene,

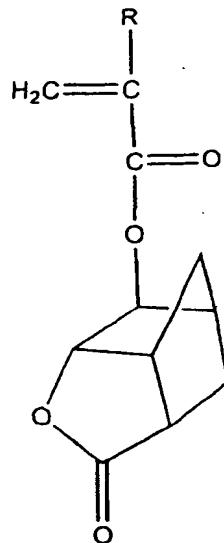
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8-ethoxycarbonyloxymethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-n-propoxycarbonyloxymethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-n-butoxycarbonyloxymethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-tetrahydrafuranyloxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-tetrahydropyranlyoxy-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-tetrahydrafuranyloxymethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-hydroxy-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-hydroxy-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-carboxyl-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-carboxyl-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-hydroxymethyl-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-hydroxymethyl-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-hydroxyethyl)-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-hydroxyethyl)-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-methoxy-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-methoxy-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-ethoxy-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-ethoxy-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanotetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanomethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-cyanoethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8,9-dicyanotetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8,9-di(cyanomethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8,9-di(2-cyanoethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyano-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyano-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanomethyl-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanomethyl-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-cyanoethyl)-8-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-cyanoethyl)-8-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyano-9-methyltetracyclo[4.4.0.12.5.17.10]dbdec-3-ene,
8-cyano-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanomethyl-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-cyanomethyl-9-ethyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-cyanoethyl)-9-methyltetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8,9-dicarboxytetracyclo[4.4.0.12.5.17.10]dodec-3-ene anhydride,
8-(2,2,2-trifluoro-1-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methyl-1-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-trifluoromethyl-1-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methoxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methyl-1-methoxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-trifluoromethyl-1-methoxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methylcarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methyl-1-methylcarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-trifluoromethyl-1-methylcarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-t-butoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-methyl-1-t-butoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2,2,2-trifluoro-1-trifluoromethyl-1-t-butoxycarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-trifluoromethyl-2-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-trifluoromethyl-2-methyl-2-hydroxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-[2,2-bis(trifluoromethyl)-2-hydroxyethyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-trifluoromethyl-2-methoxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-trifluoromethyl-2-methyl-2-methoxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-[2,2-bis(trifluoromethyl)-2-methoxyethyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-[2-trifluoromethyl-2-methylcarbonyloxyethyl]tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,
8-(2-trifluoromethyl-2-methyl-2-methylcarbonyloxyethyl)tetracyclo[4.4.0.12.5.17.10]dodec-3-ene,

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8-[2,2-bis(trifluoromethyl)-2-methylcarbonyloxyethyl]tetracyclo[4.4.0.1².5.1⁷.10]dodec-3-ene,
 8-[2-trifluoromethyl-2-t-butoxycarbonyloxyethyl]tetracyclo[4.4.0.1².5.1⁷.10] dodec-3-ene,
 8-(2-trifluoromethyl-2-methyl-2-t-butoxycarbonyloxyethyl)tetracyclo[4.4.0.1².5.1⁷.10]dodec-3-ene,
 8-[2,2-bis(trifluoromethyl)-2-t-butoxycarbonyloxyethyl]tetracyclo[4.4.0.1².5.1⁷.10] dodec-3-ene;
 5 dicyclopentadiene, tricyclo[5.2.1.0².6]dec-8-ene, tricyclo[5.2.1.0².6]dec-3-ene,
 Tricyclo[4.4.0.1².5]undec-3-ene,
 tricyclo[6.2.1.0¹.8]undec-9-ene,
 Tricyclo[6.2.1.0¹.8]undec-4-ene,
 10 tetracyclo[4.4.0.1².5.1⁷.10.0¹.6]dodec-3-ene,
 8-methyltetracyclo[4.4.0.1².5.1⁷.10.0¹.6]dodec-3-ene,
 8-ethylidenetetracyclo[4.4.0.1².5.1⁷.10.0¹.6]dodec-3-ene,
 8-ethylidenetetracyclo[4.4.0.1².5.1⁷.10.0¹.6]dodec-3-ene,
 15 pentacyclo[6.5.1.13.6.0².7.0⁹.13]pentadec-4-ene,
 pentacyclo[7.4.0.1².5.0⁹.12.0⁸.13]pentadec-3-ene,
 (meth)acrylates such as (meth)acrylic acid esters such as methyl (meth)acrylate, ethyl (meth)acrylate, n-propyl (meth)acrylate, n-butyl (meth)acrylate, 2-methylpropyl (meth)acrylate, 2-hydroxyethyl (meth)acrylate, 2-hydroxypropyl (meth)acrylate, 3-hydroxypropyl (meth)acrylate, and compounds shown by the following formula (9),

20



wherein R represents a hydrogen atom or methyl group; α -hydroxymethylacrylic acid esters such as methyl α -hydroxymethyl acrylate, ethyl α -hydroxymethyl acrylate, n-propyl α -hydroxymethyl acrylate, and n-butyl α -hydroxymethyl acrylate; vinyl esters such as vinyl acetate, vinyl propionate, and vinyl butyrate; unsaturated nitrile compounds such as (meth)acrylonitrile, α -chloroacrylonitrile, crotonitrile, maleinitrile, fumaronitrile, mesaconitrile, citraconitrile, and itaconitrile; other unsaturated amide compounds such as crotonamide, maleinamide, fumaramide, mesaconamide, citraconamide, and itaconamide; other nitrogen-containing vinyl compounds such as N-vinyl- ϵ -caprolactam, N-vinylpyrrolidone, 2-vinylpyridine, 3-vinylpyridine, 4-vinylpyridine, and N-vinylimidazole; unsaturated carboxylic acids (anhydrides) such as (meth)acrylic acid, crotonic acid, maleic acid, maleic anhydride, fumaric acid, itaconic acid, itaconic anhydride, citraconic acid, citraconic anhydride, and mesaconic acid; carboxyl group-containing esters of unsaturated carboxylic acids such as 2-carboxyethyl (meth)acrylate, 2-carboxypropyl (meth)acrylate, 3-carboxypropyl (meth)acrylate, 4-carboxybutyl (meth)acrylate; (meth)acryloyloxy lactone compounds such as:

55 α -(meth)acryloyloxy- β -methoxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -ethoxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -n-propoxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -i-propoxycarbonyl- γ -butyrolactone,

α -(meth)acryloyloxy- β -n-butoxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -(2-methylpropoxy)carbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -(1-methylpropoxy)carbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -t-butoxycarbonyl- γ -butyrolactone,
5 α -(meth)acryloyloxy- β -cyclohexyloxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -(4-t-butylcyclohexyloxy)carbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -phenoxy carbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -(1-ethoxyethoxy)carbonyl- γ -butyrolactone,
10 α -(meth)acryloyloxy- β -(1-cyclohexyloxyethoxy)carbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -t-butoxycarbonylmethoxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -tetrahydrofuranyloxycarbonyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -tetrahydropyrananyloxycarbonyl- γ -butyrolactone.
 α -methoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
15 α -ethoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -n-propoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -i-propoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -n-butoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -(2-methylpropoxy)carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
20 α -(1-methylpropoxy)carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -t-butoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -cyclohexyloxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -(4-t-butylcyclohexyloxy)carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -phenoxy carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
25 α -(1-ethoxyethoxy)carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -(1-cyclohexyloxyethoxy)carbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -t-butoxycarbonylmethoxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -tetrahydrofuranyloxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -tetrahydropyrananyloxycarbonyl- β -(meth)acryloyloxy- γ -butyrolactone.
 α -(meth)acryloyloxy- γ -butyrolactone,
30 α -(meth)acryloyloxy- β -fluoro- γ -butyrolactone,
 α -(meth)acryloyloxy- β -hydroxy- γ -butyrolactone,
 α -(meth)acryloyloxy- β -methyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -ethyl- γ -butyrolactone,
35 α -(meth)acryloyloxy- β , β -dimethyl- γ -butyrolactone,
 α -(meth)acryloyloxy- β -methoxy- γ -butyrolactone.
 β -(meth)acryloyloxy- γ -butyrolactone,
 α -fluoro- β -(meth)acryloyloxy- γ -butyrolactone,
40 α -hydroxy- β -(meth)acryloyloxy- γ -butyrolactone,
 α -methyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -ethyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α , α -dimethyl- β -(meth)acryloyloxy- γ -butyrolactone,
 α -methoxy- β -(meth)acryloyloxy- γ -butyrolactone,
45 α -(meth)acryloyloxy- δ -mevalonolactone, compounds in which a carboxyl group in the above unsaturated carboxylic acids or carboxyl group-containing esters of unsaturated carboxylic acids is converted into the following acid-dissociable organic group (ii); and polyfunctional monomers such as methylene glycol di(meth)acrylate, ethylene glycol di(meth)acrylate, propylene glycol di(meth)acrylate, 1,6-hexanediol di(meth)acrylate, 2,5-dimethyl-2,5-hexanediol di(meth)acrylate, 1,8-octanediol di(meth)acrylate, 1,9-nananediol di(meth)acrylate, 1,4-bis(2-hydroxypropyl)benzene di(meth)acrylate, 1,3-bis(2-hydroxypropyl)benzene di(meth)acrylate, 1,2-adamantanediol di(meth)acrylate, 1,3-adamantanediol di(meth)acrylate, 1,4-adamantanediol di(meth)acrylate, tricyclodecanyl dimethylol di(meth)acrylate, and the like.
50

[0089] As examples of the acid-dissociable organic group (ii), groups in which a hydrogen atom of a carboxyl group is replaced by a substituted methyl group, 1-substituted ethyl group, 1-branched alkyl group, silyl group, germyl group, alkoxy carbonyl group, acyl group, cyclic organic group (excluding the compounds in which a hydrogen atom in the carboxyl group in a (meth)acrylic acid is converted to the acid-dissociable group (ii) corresponds to the (meth)acrylic acid derivative (ii)), and the like can be given.

[0090] As examples of a substituted methyl group, a methoxymethyl group, methylthiomethyl group, ethoxymethyl group, ethylthiomethyl group, 2-methoxyethoxymethyl group, benzyloxymethyl group, benzylthiomethyl group, phen-

acyl group, 4-bromophenacyl group, 4-methoxyphenacyl group, 4-methylthiophenacyl group, α -methylphenacyl group, cyclopropylmethyl group, benzyl group, diphenylmethyl group, triphenylmethyl group, 4-bromobenzyl group, 4-nitrobenzyl group, 4-methoxybenzyl group, 4-methylthiobenzyl group, 4-ethoxybenzyl group, 4-ethylthiobenzyl group, piperonyl group, methoxycarbonylmethyl group, ethoxycarbonylmethyl group, n-propoxycarbonylmethyl group, i-propoxycarbonylmethyl group, n-butoxycarbonylmethyl group, t-butoxycarbonylmethyl group, adamantyl methyl group, and the like can be given.

5 [0091] As examples of a 1-substituted ethyl group, a 1-methoxyethyl group, 1-methylthioethyl group, 1,1-dimethoxyethyl group, 1-ethoxyethyl group, 1-ethylthioethyl group, 1,1-diethoxyethyl group, 1-phenoxyethyl group, 1-phenylthioethyl group, 1,1-diphenoxyethyl group, 1-benzyloxyethyl group, 1-benzylthioethyl group, 1-cyclopropylethyl group, 1-phenylethyl group, 1,1-diphenylethyl group, 1-methoxycarbonylethyl group, 1-ethoxycarbonylethyl group, 1-n-propoxycarbonylethyl group, 1-i-propoxycarbonylethyl group, 1-n-butoxycarbonylethyl group, 1-t-butoxycarbonylethyl group, and the like can be given.

10 [0092] As examples of a 1-branched alkyl group, an i-propyl group, 1-methylpropyl group, t-butyl group, 1,1-dimethylpropyl group, 1-methylbutyl group, 1,1-dimethylbutyl group, and the like can be given.

15 [0093] As examples of the silyl group, a trimethylsilyl group, ethyldimethylsilyl group, methyldiethylsilyl group, triethylsilyl group, i-propyldimethylsilyl group, methyldi-i-propylsilyl group, tri-i-propylsilyl group, t-butyldimethylsilyl group, methyldi-t-butylsilyl group, tri-t-butylsilyl group, phenyldimethylsilyl group, methyldiphenylsilyl group, triphenylsilyl group, and the like can be given.

20 [0094] As examples of the germyl group, a trimethylgermyl group, ethyldimethylgermyl group, methyldiethylgermyl group, triethylgermyl group, i-propyldimethylgermyl group, methyldi-i-propylgermyl group, tri-i-propylgermyl group, t-butyldimethylgermyl group, methyldi-t-butylgermyl group, tri-t-butylgermyl group, phenyldimethylgermyl group, methyldiphenylgermyl group, triphenylgermyl group, and the like can be given.

25 [0095] As examples of the alkoxy carbonyl group, a methoxycarbonyl group, ethoxycarbonyl group, i-propoxycarbonyl group, t-butoxycarbonyl group, and the like can be given.

30 [0096] As examples of the acyl group, an acetyl group, propionyl group, butyryl group, heptanoyl group, hexanoyl group, valeryl group, pivaloyl group, isovaleryl group, lauryloyl group, myristoyl group, palmitoyl group, stearoyl group, oxanyl group, malonyl group, succinyl group, glutaryl group, adipoyl group, piperoyl group, suberoyl group, azelaoyl group, sebacyoyl group, acryloyl group, propioloyle group, methacryloyl group, crotonoyl group, oleoyl group, maleoyl group, fumaroyl group, mesaconoyl group, campholoyl group, benzoyl group, phthaloyl group, isophthaloyl group, terephthaloyl group, naphthoyl group, toluoyl group, hydroatropoyl group, atropoyl group, cinnamoyl group, furoyl group, thenoyl group, nicotinoyl group, isonicotinoyl group, p-toluenesulfonyl group, mesyl group, and the like can be given.

35 [0097] As examples of the cyclic organic group, norbornyl group, isobornyl group, tricyclodecanyl group, carboxytricyclodecanyl group, tetracyclodecanyl group, carboxytetracyclodecanyl group, dicyclopentenyl group, adamantly group, cyclopropyl group, cyclopentyl group, cyclohexyl group, cyclohexenyl group, 4-methoxycyclohexyl group, 4-carboxycyclohexyl group, 3-oxocyclohexyl group, tetrahydropyranyl group, tetrahydrofuran group, tetrahydrothiopyranyl group, tetrahydrothiofuran group, 3-bromotetrahydropyranyl group, 4-methoxytetrahydropyranyl group, 2-oxo-4-methyltetrahydropyranyl group, 4-methoxytetrahydrothiopyranyl group, 3-tetrahydrothiophene-1,1-dioxide group, and the like can be given.

40 [0098] Of these acid-dissociable organic groups (ii), groups having a formula -COOR' (wherein R' represents a (cyclo) alkyl group having 1-19 carbon atoms) or -COOCH₂COOR" (wherein R" represents a (cyclo)alkyl group having 1-17 carbon atoms) are preferable, with a 1-methylpropoxycarbonyl group, t-butoxycarbonyl group, and t-butoxycarbonylmethoxycarbonyl group being particularly preferable.

45 [0099] As a monomer preferably used for providing the other recurring unit ③, 5-n-hexylbicyclo[2.2.1]hept-2-ene, (meth)acrylic acid, maleic anhydride, and a compound having the above formula (9) can be given. Maleic anhydride exhibits good copolymerizability with norbornene and its derivatives. Therefore, the molecular weight of the resulting resin can be increased to a desired value by adding maleic anhydride when norbornene derivatives (I) are copolymerized with norbornene or other norbornene derivatives.

50 [0100] These monomers providing the other recurring unit ③ may be used either individually or in combination of two or more.

[0101] In the resin (A3-1), the content of the recurring unit (3-2) is usually 0.5-20 mol%, preferably 0.5-15 mol%, and still more preferably 1-10 mol%, and the content of the recurring unit having an acid-dissociating group is usually 20-70 mol%, preferably 20-60 mol%, and still more preferably 30-60 mol%, of the total amount of the recurring units.

55 [0102] In the resin (A3-2), the content of the recurring unit (3-1') is usually 0.5-20 mol%, preferably 0.5-15 mol%, and still more preferably 1-10 mol%, and the content of the recurring unit having an acid-dissociating group is usually 20-70 mol%, preferably 20-60 mol%, and still more preferably 30-60 mol%, of the total amount of the recurring units.

[0103] In the resin (α), the content of the recurring unit (3-2) and the recurring unit (3-1') is usually 1-15 mol%, and preferably 1-10 mol%, the content of the recurring unit (i) and recurringunit (ii) is usually 10-90 mol%, preferably 20-90

mol%, and still more preferably 30-70 mol%, and the content of the other recurring units ③ is usually 65 mol% or less, and preferably 60 mol% or less, of the total amount of the recurring units.

[0104] In the resin ($\alpha 1$), the content of the recurring unit (3-2) and the recurring unit (3-1') is usually 1-15 mol%, and preferably 1-10 mol%, the content of the recurring unit (i) is usually 10-80 mol%, preferably 20-80 mol%, and still more preferably 30-60 mol%, and the content of the other recurring units ③ is usually 65 mol% or less, and preferably 60 mol% or less, of the total amount of the recurring units.

[0105] In the resin ($\alpha 2$), the content of the recurring unit (3-2) and the recurring unit (3-1') is usually 1-15 mol%, and preferably 1-10 mol%, the content of the recurring unit (ii) is usually 10-80 mol%, preferably 20-70 mol%, and still more preferably 30-60 mol%, and the content of the other recurring units ③ is usually 50 mol% or less, and preferably 40 mol% or less, of the total amount of the recurring units.

[0106] As discussed later, the total content of the recurring unit (3-2) and the recurring unit (3-1') in the resins used for the radiation-sensitive resin composition of the present invention should be sufficiently small taking into consideration the action of the resin as a resist. In many cases, industrial manufacture of a resin with such a small content of the recurring unit (3-2) and the recurring unit (3-1') in a stable manner is difficult. Therefore, the resins (A3-1), (A3-2), (α), (α 1), and (α 2) are preferably used in combination with other resins which do not contain the recurring units (3-2) and (3-1'), preferably a resin containing an acid-dissociating group which dissociates in the presence of an acid and forms a carboxyl group in the resin. The above-described contents of the recurring units in the resins used in the present invention are thus specified taking stable industrial manufacture of such resins into consideration.

[0107] The resins of the present invention can be prepared by copolymerizing the norbornene derivatives (I) and/or (meth)acrylic acid derivatives (II), preferably together with the norbornene derivatives (i) and/or (meth)acrylic acid derivatives (ii), and optionally monomers providing the recurring unit ③, in an appropriate solvent using a radical polymerization initiator such as a hydroperoxide, dialkyl peroxide, diacyl peroxide, or azo compound and, as required, in the presence of a chain-transfer agent.

[0108] As examples of the solvent used for copolymerization of the components, alkanes such as n-pentane, n-hexane, n-heptane, n-octane, n-nonane, and n-decane; cycloalkanes such as cyclohexane, cycloheptane, cyclooctane, decalin, and norbornane; aromatic hydrocarbons such as benzene, toluene, xylene, ethylbenzene, and cumene; halogenated hydrocarbons such as chlorobutanes, bromohexanes, dichloroethanes, hexamethylene dibromide, and chlorobenzene; saturated carboxylic acid esters such as ethyl acetate, n-butyl acetate, i-butyl acetate, and methyl propionate; ethers such as tetrahydrofuran, dimethoxyethanes, and diethoxyethanes; and the like can be given.

[0109] These solvents may be used either individually or in combination of two or more.

[0110] The copolymerization is carried out at a temerature of usually 40-120°C, and preferably 50-90°C for usually 1-48 hours, and preferably 1-24 hours.

[0111] The polystyrene-reduced weight average molecular weight (hereinafter referred to as "Mn") of the resins (A3-1), (A3-2), (α), (α 1), and (α 2) determined by gel permeation chromatography (GPC) is usually 3,000-300,000, preferably 4,000-200,000, and still more preferably 4,000-100,000. If M_w of these resins is less than 3,000, heat resistance as a resist tends to decrease; if more than 300,000, developability as a resist tends to decrease.

[0112] It is preferable that the above resins contain almost no impurities such as halogens or metals. The smaller the amount of such impurities, the better are the sensitivity, resolution, process stability, pattern shape, or the like as a resist. The resin can be purified using, for example, a chemical purification method such as washing with water or liquid-liquid extraction or a combination of the chemical purification method and a physical purification method such as ultrafiltration or centrifugation.

[0113] In the present invention, the resin (A3-1), (A3-2), (α), (α 1), or (α 2) may be used either individually or in combination of two or more.

[0114] The resin (A3) of the present invention is preferable used together with other resins having a group dissociating in the presence of an acid and forming an acidic functional group, preferably a carboxyl group, in the resin (hereinafter referred to as "other acid-dissociating group-containing resins").

[0115] As examples of such other acid-dissociating group-containing resins, resins containing at least one recurring unit selected from the above-mentioned recurring unit (i), the recurring unit (ii), and other recurring units having an acid-dissociating group, and optionally further containing one or more other recurring units having no acid-dissociating group can be given.

16), (i-17), (i-34), (i-35), (i-40), (i-41), (i-46), or (i-47); and at least one compound selected from the group consisting of 5-n-hexylbicyclo[2.2.1]hept-2-ene, (meth)acrylic acid, maleic anhydride, and a compound having the above formula (9), can be given.

5 [0117] Maleic anhydride exhibits good copolymerizability with norbornene and its derivatives. Therefore, the molecular weight of the resulting resin can be increased to a desired value by adding maleic anhydride when norbornene derivatives (i) is copolymerized with norbornene or other norbornene derivatives.

10 [0118] In the radiation-sensitive resin composition of the present invention, the content of the recurring unit (3-2) and the recurring unit (3-1') is preferably 0.01-5 mol%, more preferably 0.1-3 mol%, and particularly preferably 0.1-1 mol%, the content of the recurring unit having an acid-dissociating group is preferably 10-80 mol%, more preferably 20-60 mol%, and still more preferably 30-60 mol%, and the content of the other recurring units is preferably 70 mol% or less, and more preferably 60 mol% or less, of the total amount of the recurring units.

15 [0119] If the total amount of the recurring units (3-2) and (3-1') is less than 0.01 mol%, it is difficult for the resist to exhibit a sufficient effect of suppressing line width fluctuations due to an increase or decrease of space widths. If the amount exceeds 5 mol%, on the other hand, sensitivity as a resist tends to decrease. If the content of the recurring unit having an acid-dissociating group is less than 10 mol%, resolution as a resist tends to decrease. If the content exceeds 80 mol%, developability tends to decrease and scum tends to be easily produced.

20 [0120] The amount of the other acid-dissociating group-containing resins for the total amount of resin components may be appropriately determined so that the total content of the recurring units (3-2) and (3-1') and the content of recurring units having an acid-dissociable group may be in the above range. This amount is usually 70-99.9 wt%, preferably 80-99 wt%, and still more preferably 85-95 wt%.

Component (B)

25 [0121] The component (B) of the present invention is a photoacid generator which generates an acid upon exposure (hereinafter referred to as "acid generator").

[0122] As examples of the acid generator used in the present invention, (1) onium salt compounds, (2) sulfone compounds, (3) sulfonate compounds, (4) sulfonimide compounds, (5) diazomethane compounds, (6) disulfonylmethane compounds, and (7) halogen-containing compounds can be given.

30 [0123] Examples of these acid generators will be given below.

(1) Onium salt compounds:

35 [0124] As examples of onium salts, iodonium salt, sulfonium salt, phosphonium salt, diazonium salt, ammonium salt, pyridinium salt, and the like can be given.

[0125] Specific examples of onium salts include:

40 bis(4-t-butylphenyl)iodonium perfluoro-n-octanesulfonate,
 bis(4-t-butylphenyl)iodonium nonafluoro-n-butanesulfonate,
 bis(4-t-butylphenyl)iodonium trifluoromethanesulfonate,
 bis(4-t-butylphenyl)iodonium pyrenesulfonate,
 bis(4-t-butylphenyl)iodonium n-dodecylbenzenesulfonate,
 bis(4-t-butylphenyl)iodonium hexafluoroantimonate,
 bis(4-t-butylphenyl)iodonium p-toluenesulfonate,
 bis(4-t-butylphenyl)iodonium benzenesulfonate,
 45 bis(4-t-butylphenyl)iodonium naphthalenesulfonate,
 bis(4-t-butylphenyl)iodonium 10-camphorsulfonate,
 bis(4-t-butylphenyl)iodonium octanesulfonate,
 bis(4-t-butylphenyl)iodonium 2-trifluoromethylbenzenesulfonate,
 bis(4-t-butylphenyl)iodonium 4-trifluoromethylbenzenesulfonate,
 50 bis(4-t-butylphenyl)iodonium 2,4-difluorobenzenesulfonate,
 diphenyliodonium perfluoro-n-octanesulfonate,
 diphenyliodonium nonafluoro-n-butanesulfonate,
 diphenyliodonium trifluoromethanesulfonate, diphenyliodonium pyrenesulfonate, diphenyliodonium n-dodecylbenzenesulfonate,
 55 diphenyliodonium hexafluoroantimonate, diphenyliodonium p-toluenesulfonate, diphenyliodonium benzenesulfonate,
 diphenyliodonium naphthalenesulfonate, diphenyliodonium 10-camphorsulfonate, diphenyliodonium octanesulfonate,

diphenyliodonium 2-trifluoromethylbenzenesulfonate,
 diphenyliodonium 4-trifluoromethylbenzenesulfonate,
 diphenyliodonium 2,4-difluorobenzenesulfonate,
 5 triphenylsulfonium perfluoro-n-octanesulfonate,
 triphenylsulfonium nonafluoro-n-butanесulfonate,
 triphenylsulfonium trifluoromethanesulfonate,
 triphenylsulfonium pyrenesulfonate, triphenylsulfonium n-dodecylbenzenesulfonate, triphenylsulfonium hexafluoroantimonate, triphenylsulfonium p-toluenesulfonate,
 10 triphenylsulfonium benzenesulfonate, triphenylsulfonium naphthalenesulfonate, triphenylsulfonium 10-camphorsulfonate,
 triphenylsulfonium octanesulfonate, triphenylsulfonium 2-trifluoromethylbenzenesulfonate, triphenylsulfonium 4-trifluoromethylbenzenesulfonate, triphenylsulfonium 2,4-difluorobenzene sulfonate,
 15 4-t-butylphenyl-diphenylsulfonium nonafluorobutanesulfonate,
 4-t-butylphenyl-diphenylsulfonium trifluoromethanesulfonate.
 4-t-butylphenyl-diphenylsulfonium pyrenesulfonate,
 20 4-t-butylphenyl-diphenylsulfonium dodecylbenzenesulfonate,
 4-t-butylphenyl-diphenylsulfonium p-toluenesulfonate,
 4-t-butylphenyl-diphenylsulfonium benzenesulfonate,
 4-t-butylphenyl-diphenylsulfonium 10-camphorsulfonate,
 25 4-t-butylphenyl-diphenylsulfonium octanesulfonate,
 4-t-butylphenyl-diphenylsulfonium 2-trifluoromethylbenzenesulfonate,
 4-t-butylphenyl-diphenylsulfonium 4-trifluoromethylbenzenesulfonate,
 4-t-butylphenyl-diphenylsulfonium 2,4-difluorobenzenesulfonate,
 30 4-t-butoxyphenyl-diphenylsulfonium nonafluorobutanesulfonate,
 4-hydroxyphenyl-benzyl-methylsulfonium p-toluenesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium nonafluorobutanesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium trifluoromethanesulfonate,
 35 2,4,6-tristrimethylphenyl-diphenylsulfonium pyrenesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium dodecylbenzenesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium p-toluenesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium benzenesulfonate.
 40 2,4,6-tristrimethylphenyl-diphenylsulfonium 10-camphorsulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium octanesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium 2-trifluoromethylbenzenesulfonate,
 2,4,6-tristrimethylphenyl-diphenylsulfonium 4-trifluoromethylbenzenesulfonate,
 45 2,4,6-tristrimethylphenyl-diphenylsulfonium 2,4-difluorobenzenesulfonate,
 cyclohexyl-2-oxocyclohexyl-methylsulfonium trifluoromethanesulfonate,
 cyclohexyl-2-oxocyclohexyl-methylsulfonium nonafluoro-n-butanесulfonate,
 cyclohexyl-2-oxocyclohexyl-methylsulfonium perfluoro-n-octanesulfonate,
 dicyclohexyl-2-oxocyclohexylsulfonium trifluoromethanesulfonate,
 50 dicyclohexyl-2-oxocyclohexylsulfonium nonafluoro-n-butanесulfonate,
 dicyclohexyl-2-oxocyclohexylsulfonium perfluoro-n-octanesulfonate,
 2-oxocyclohexyldimethylsulfonium trifluoromethanesulfonate,
 2-oxocyclohexyldimethylsulfonium nonafluoro-n-butanесulfonate,
 2-oxocyclohexyldimethylsulfonium perfluoro-n-octanesulfonate,
 55 4-hydroxyphenyl-phenyl-methylsulfonium p-toluenesulfonate,
 4-hydroxyphenyl-benzyl-methylsulfonium p-toluenesulfonate,
 1-naphthylidimethylsulfonium trifluoromethanesulfonate,
 1-naphthylidimethylsulfonium nonafluoro-n-butanесulfonate,
 1-naphthylidimethylsulfonium perfluoro-n-octanesulfonate,
 1-naphthylidethyli sulfonium trifluoromethanesulfonate,
 1-naphthylidethyli sulfonium nonafluoro-n-butanесulfonate,
 1-naphthylidethyli sulfonium perfluoro-n-octanesulfonate,
 4-cyano-1-naphthylidimethylsulfonium trifluoromethan sulfonate,
 4-cyano-1-naphthylidimethylsulfonium nonafluoro-n-butanесulfonate,
 4-cyano-1-naphthylidimethylsulfonium perfluoro-n-octanesulfonate,
 4-cyano-1-naphthylidethyli sulfonium trifluoromethanesulfonate,
 4-cyano-1-naphthylidethyli sulfonium nonafluoro-n-butanесulfonate,

4-(2-methoxyethoxy)-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-(2-methoxyethoxy)-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-(2-methoxyethoxy)-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-methoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-methoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-methoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-ethoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-ethoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-ethoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-n-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-n-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-n-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-i-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-i-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-i-propoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-n-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-n-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-n-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-t-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-t-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-t-butoxycarbonyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-(2-tetrahydrofuryloxy)-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-(2-tetrahydrofuryloxy)-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-(2-tetrahydrofuryloxy)-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-(2-tetrahydropyranloxy)-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-(2-tetrahydropyranloxy)-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-(2-tetrahydropyranloxy)-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 4-benzyloxy-1-naphthyltetrahydrothiophenium trifluoromethanesulfonate,
 4-benzyloxy-1-naphthyltetrahydrothiophenium nonafluoro-n-butanesulfonate,
 4-benzyloxy-1-naphthyltetrahydrothiophenium perfluoro-n-octanesulfonate,
 1-(1-naphthylacetomethyl)tetrahydrothiophenium trifluoromethanesulfonate,
 1-(1-naphthylacetomethyl)tetrahydrothiophenium nonafluoro-n-butanesulfonate,
 1-(1-naphthylacetomethyl)tetrahydrothiophenium perfluoro-n-octanesulfonate,

35 (2) Sulfone compounds:

[0126] As examples of sulfone compounds, β -ketosulfone, β -sulfonylsulfone, and α -diazo compounds of these compounds, and the like can be given.

[0127] As specific examples of sulfone compounds, phenacylphenylsulfone, mesitylphenacylsulfone, bis(phenylsulfonyl)methane, 4-trisphenacylsulfone, and the like can be given.

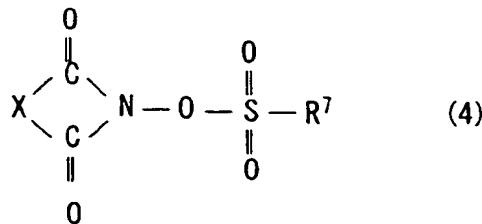
36 (3) Sulfonate compounds:

[0128] As examples of sulfonate compounds, alkyl sulfonate, haloalkyl sulfonate, aryl sulfonate, imino sulfonate, and the like can be given.

[0129] As specific examples of sulfonate compounds, benzointosylate, pyrogallol tristrifluoromethanesulfonate, pyrogallol trisnorfluorobutanesulfonate, pyrogallol methanetrisulfonate, nitrobenzyl-9,10-diethoxyanthracene-2-sulfonate, α -methylolbenzointosylate, α -methylolbenzoin octanesulfonate, α -methylolbenzoin trifluoromethanesulfonate, α -methylolbenzoin dodecylsulfonate, and the like can be given.

50 (4) Sulfonimide compounds:

[0130] As examples of sulfonimide compounds, compounds shown by the following formula (4) can be given:

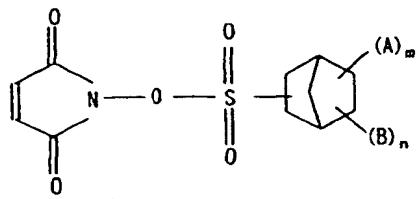


wherein X represents a divalent group such as an alkylene group, arylene group, and alkoxylen group, and R⁷ represents a monovalent group such as an alkyl group, aryl group, halogenated alkyl group, and halogenated aryl group.

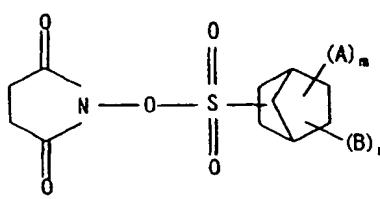
[0131] Specific examples of sulfonimide compounds include:

15 N-(trifluoromethylsulfonyloxy)succinimide,
 N-(trifluoromethylsulfonyloxy)phthalimide,
 N-(trifluoromethylsulfonyloxy)diphenylmaleimide,
 N-(trifluoromethylsulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 20 N-(trifluoromethylsulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(trifluoromethylsulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide,
 N-(trifluoromethylsulfonyloxy)naphthylimide,
 N-(nonafluorobutylsulfonyloxy)succinimide,
 25 N-(nonafluorobutylsulfonyloxy)phthalimide,
 N-(nonafluorobutylsulfonyloxy)diphenylmaleimide,
 N-(nonafluorobutylsulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(nonafluorobutylsulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 30 N-(nonafluorobutylsulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide,
 N-(nonafluorobutylsulfonyloxy)naphthylimide,
 N-(2-trifluoromethylbenzenesulfonyloxy)succinimide,
 N-(2-trifluoromethylbenzenesulfonyloxy)phthalimide,
 35 N-(2-trifluoromethylbenzenesulfonyloxy)diphenylmaleimide,
 N-(2-trifluoromethylbenzenesulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(2-trifluoromethylbenzenesulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(2-trifluoromethylbenzenesulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide,
 40 N-(2-trifluoromethylbenzenesulfonyloxy)naphthylimide,
 N-(10-camphorsulfonyloxy)succinimide,
 N-(10-camphorsulfonyloxy)phthalimide,
 N-(10-camphorsulfonyloxy)diphenylmaleimide,
 N-(10-camphorsulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 45 N-(10-camphorsulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(10-camphorsulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide, N-(10-camphorsulfonyloxy)naphthylimide,
 N-(p-toluenesulfonyloxy)succinimide,
 N-(p-toluenesulfonyloxy)phthalimide,
 50 N-(p-toluenesulfonyloxy)diphenylmaleimide,
 N-(p-toluenesulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(p-toluenesulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(p-toluenesulfonyloxy)bicyclo[2.2.1]heptane-5,6-oxy-2,3-dicarboxyimide, N-(p-toluenesulfonyloxy)naphthylimide,
 and compounds shown by the following formulas (4-1) to (4-6),

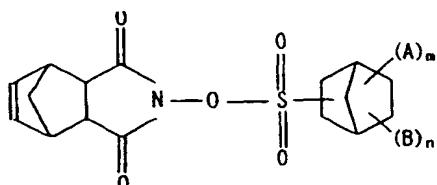
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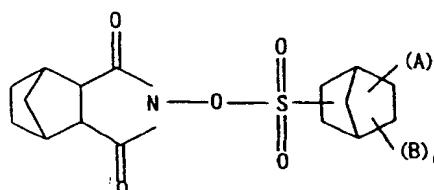
(4-1)



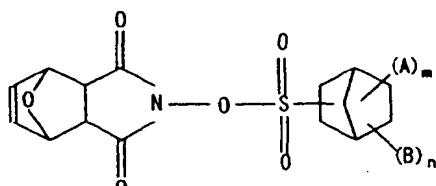
(4-2)



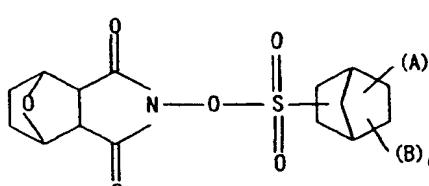
(A-3)



(4-4)



(4-5)

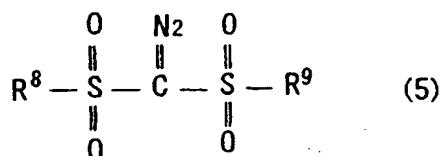


(4-6)

wherein A individually indicates an organic group having 2-10 carbon atoms and an ester bond, B individually represents an alkyl group having 1-10 carbon atoms or an alkoxy group having 1-10 carbon atoms, m is an integer of 1-11, and n is an integer of 0-10, provided that $m+n \leq 11$.

(5) Diazomethane compounds:

35 [0132] As examples of diazomethane compounds, compounds shown by the following formula (5) can be given:



45 wherein R⁸ and R⁹ individually represent a monovalent group such as an alkyl group, aryl group, halogenated alkyl group, and halogenated allyl group.

[0133] As specific examples of diazomethane compound,

bis(trifluoromethylsulfonyl)diazomethane,

50 bis(t-butylsulfonyl)diazomethane,

bis(cyclohexylsulfonyl)diazomethane,

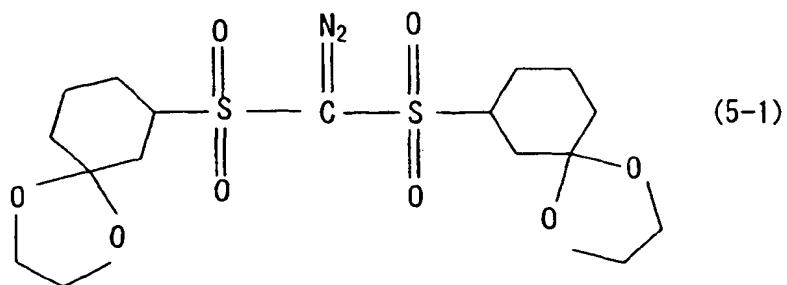
bis(phenylsulfonyl)diazomethane,

bis(p-toluenesulfonyl)diazomethane,

methylsulfonyl-p-toluenesulfonyldiazomethane,

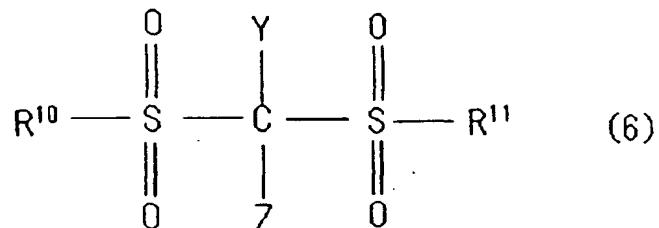
55 1-cyclohexylsulfonyl-1-(1,1-dimethylethylsulfonyl)diazomethane, bis(1,1-dimethylethylsulfonyl)diazomethane,

and a compound shown by the following formulas (5-1) can be given.

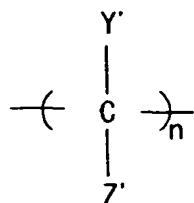


(6) Disulfonylmethane compounds

15 [0134] As examples of disulfonylmethane compounds, a compound shown by the following formula (6) can be given:

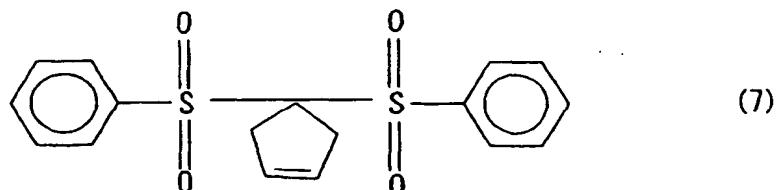


30 wherein R¹⁰ and R¹¹ individually represent a linear or branched alkyl group, cycloalkyl group, aryl group, aralkyl group, or a monovalent organic group having a hetero atom, Y and Z individually represent an aryl group, a hydrogen atom, a linear or branched alkyl group, a monovalent organic group having a hetero atom, provided that at least one of Y and Z represents an aryl group, or Y and Z bond to form a monocyclic or polycyclic ring having at least one unsaturated bond, or Y and Z bond to form a group shown by the following formula:

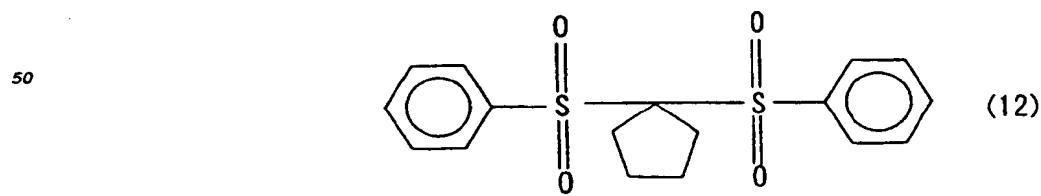
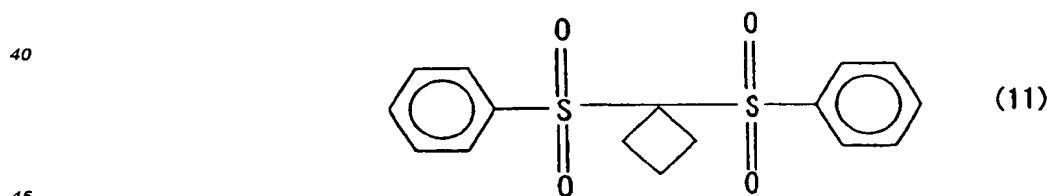
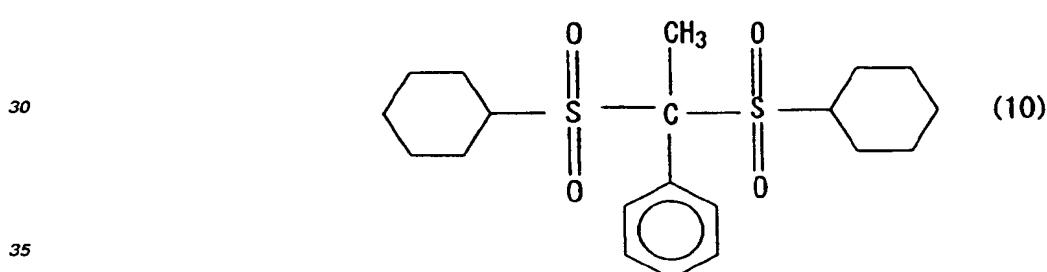
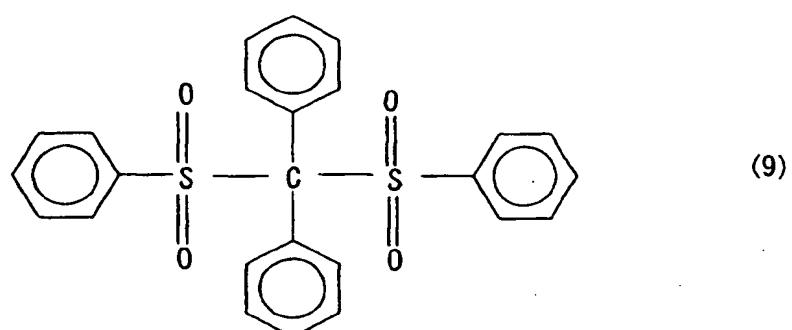
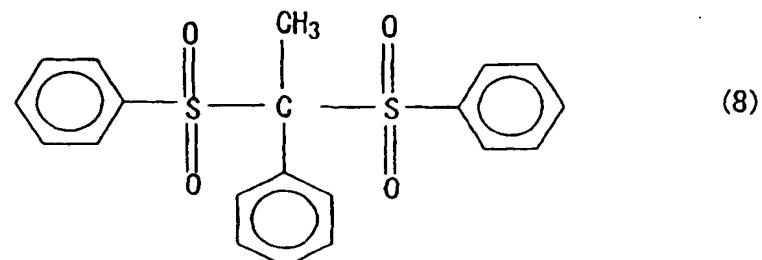


45 wherein Y' and Z' individually represent a hydrogen atom, halogen atom, alkyl group, cycloalkyl group, aryl group, or aralkyl group, or Y' and Z' bond to form a monocyclic carbon structure, and n is an integer of 2-10.

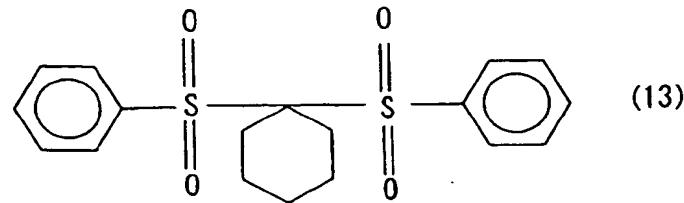
[0135] As preferable examples of disulfonylmethane compounds, compounds shown by the following formulas (7) to (14) can be given.



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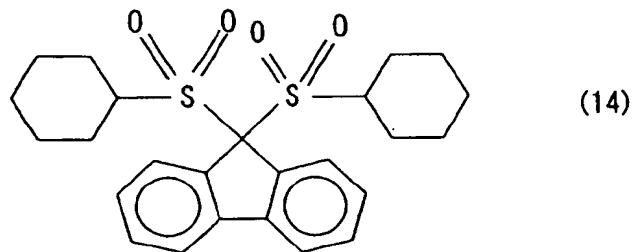


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(7) Halogen-containing compounds:

[0136] As examples of halogen-containing compounds, haloalkyl group-containing hydrocarbon compounds, haloalkyl group-containing heterocyclic compounds, and the like can be given.

[0137] As specific examples of preferable halogen-containing compounds, (trichloromethyl)-s-triazine derivatives such as phenylbis(trichloromethyl)-s-triazine, 4-methoxyphenylbis(trichloromethyl)-s-triazine, and 1-naphthylbis(trichloromethyl)-s-triazine, 1,1-bis(4-chlorophenyl)-2,2,2-trichloroethane, and the like can be given.

[0138] Of these acid generators, compounds having a boiling point higher than 165°C at normal pressure are preferable.

[0139] Particularly preferable compounds are:

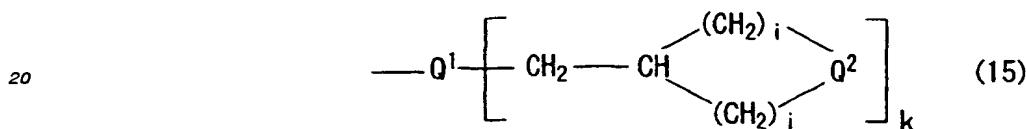
bis(4-t-butylphenyl)iodonium nonafluorobutanesulfonate,
 bis(4-t-butylphenyl)iodonium dodecylbenzenesulfonate,
 bis(4-t-butylphenyl)iodonium p-toluenesulfonate,
 bis(4-t-butylphenyl)iodonium 10-camphorsulfonate,
 bis(4-t-butylphenyl)iodonium octanesulfonate,
 diphenyliodonium p-toluenesulfonate, diphenyliodonium benzenesulfonate, diphenyliodonium 10-camphorsulfonate,
 diphenyliodonium octanesulfonate, diphenyliodonium nonafluorobutanesulfonate, diphenyliodonium dodecylbenzenesulfonate, triphenylsulfonium nonafluorobutanesulfonate, triphenylsulfonium 10-camphorsulfonate, triphenylsulfonium naphthalenesulfonate,
 4-t-butoxyphenyldiphenylsulfonium nonafluorobutanesulfonate,
 4-hydroxyphenylbenzylmethylsulfonium p-toluenesulfonate,
 N-(nonafluorobutylsulfonyloxy)succinimide,
 N-(nonafluorobutylsulfonyloxy)phthalimide,
 N-(nonafluorobutylsulfonyloxy)diphenylmaleimide,
 N-(nonafluorobutylsulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboximide,
 N-(nonafluorobutylsulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(nonafluorobutylsulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide,
 N-(nonafluorobutylsulfonyloxy)naphthylimide,
 N-(10-camphorsulfonyloxy)succinimide,
 N-(10-camphorsulfonyloxy)phthalimide,
 N-(10-camphorsulfonyloxy)diphenylmaleimide,
 N-(10-camphorsulfonyloxy)bicyclo[2.2.1]hept-5-ene-2,3-dicarboxyimide,
 N-(10-camphorsulfonyloxy)-7-oxabicyclo[2.2.1]hept-5-en-2,3-dicarboxyimide,
 N-(10-camphorsulfonyloxy)bicyclo[2.2.1]heptan-5,6-oxy-2,3-dicarboxyimide, and
 N-(10-camphorsulfonyloxy)naphthylimide.

5 [0140] In the present invention, the acid generators can be used either individually or in combination of two or more. The amount of the acid generators to be added is 0.5-20 parts by weight, and preferably 1-10 parts by weight for 100 parts by weight of the copolymer components when the copolymer (A1) or copolymer (A2) is used. When the copolymer (A3) is used, the amount of the acid generators is 0.1-10 parts by weight, and preferably 0.5-7 parts by weight for 100 parts by weight of the copolymer components.

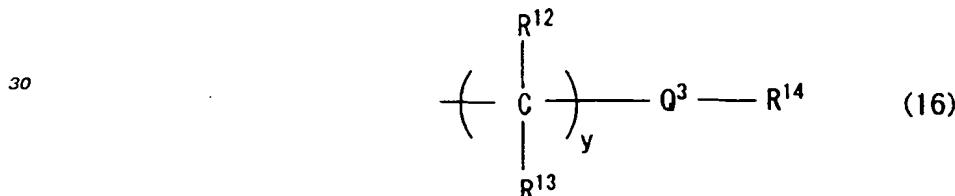
Component (C)

10 [0141] The component (C) of the negative tone radiation sensitive composition of the present invention is a compound crosslinkable with the copolymer (A2) in the presence of an acid (an acid generated by exposure, for example), for example, a compound having one or more functional groups exhibiting crosslinking reactivity with the copolymer (A2) (such a compound and functional group are hereinafter referred to respectively as "a crosslinking agent" and "a crosslinkable functional group").

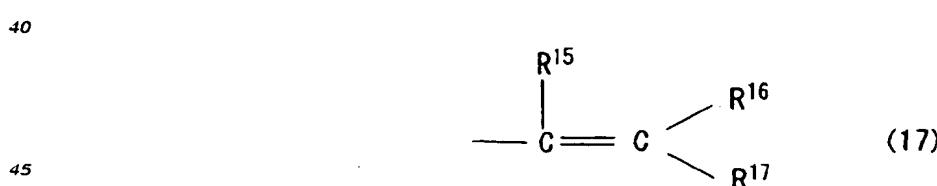
15 [0142] The groups shown by the following formulas (15) to (19) can be given as examples of the crosslinkable functional group,



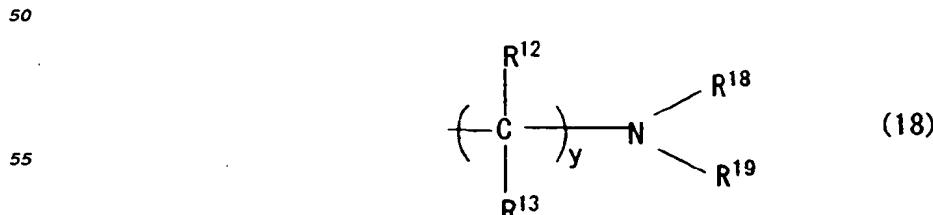
25 wherein k is an integer of 1 or 2, Q^1 indicates a single bond, $-\text{O}-$, $-\text{S}-$, $-\text{COO}-$, or $-\text{NH}-$ when $k=1$ and a trivalent nitrogen atom when $k=2$, Q^2 is $-\text{O}-$ or $-\text{S}-$, i is an integer of 0-3, and j is an integer of 1-3, provided that $i+j$ is 1 to 4,



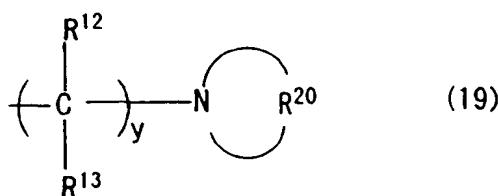
35 wherein Q^3 is $-\text{O}-$, $-\text{CO}-$, or $-\text{COO}-$, R^{12} and R^{13} individually represent a hydrogen atom or alkyl group having 1-4 carbon atoms, R^{14} represents an alkyl group having 1-5 carbon atoms, aryl group having 6-12 carbon atoms, or aralkyl group having 7-14 carbon atoms, and y is an integer of 1 or more,



45 wherein R^{15} , R^{16} , and R^{17} individually represent a hydrogen atom or an alkyl group having 1-4 carbon atoms,



wherein R¹², R¹³, and y are the same as defined in the formula (16) and R¹⁸ and R¹⁹ individually represent an alkyl group having 1-5 carbon atoms or an alkylol group having 1-5 carbon atoms, and



15 wherein R¹², R¹³, and y are the same as defined in the formula (16), and R²⁰ represents a divalent organic group having a 3-8 member cyclic structure containing a hetero atom selected from an oxygen atom, sulfur atom, and nitrogen atom.

20 [0143] As specific examples of such a crosslinkable functional group, a glycidyl ether group, glycidyl ester group, glycidyl amino group, methoxymethyl group, ethoxymethyl group, benzyloxymethyl group, acetoxyethyl group, benzoiloxy methyl group, formyl group, acetyl group, vinyl group, iso-propenyl group, dimethylaminomethyl group, diethylaminomethyl group, morpholinomethyl group, and the like can be given.

25 [0144] As examples of the compound having such a crosslinkable functional group, a bisphenol A epoxy compound, bisphenol F epoxy compound, bisphenol S epoxy compound, novolac resin epoxy compound, resol resin epoxy compound, poly(hydroxystyrene) epoxy compound, methyol group-containing melamine compound, methyol group-containing benzoquanamine compound, methyol group-containing urea compound, methyol group-containing phenol compound, alkoxyalkyl group-containing melamine compound, alkoxyalkyl group-containing benzoquanamine compound, alkoxyalkyl group-containing urea compound, alkoxyalkyl group-containing phenol compound, carboxymethyl group-containing melamine resin, carboxymethyl group-containing benzoquanamine resin, carboxymethyl group-containing urea resin, carboxymethyl group-containing phenol resin, carboxymethyl group-containing melamine compound, carboxymethyl group-containing benzoquanamine compound, carboxymethyl group-containing urea compound, carboxymethyl group-containing phenol compound, and the like can be given.

30 [0145] Of these compounds having crosslinkable functional groups, a methyol group-containing phenol compound, methoxymethyl group-containing melamine compound, methoxymethyl group-containing phenol compound, methoxymethyl group-containing glycoluril compound, methoxymethyl group-containing urea compound, and acetoxyethyl group-containing phenol compound are preferable, with particularly preferable compounds being a methoxymethyl group-containing melamine compound (for example, hexamethoxymethylmelamine), methoxymethyl group-containing glycoluril compound, methoxymethyl group-containing urea compound, and the like. Methoxymethyl group-containing melamine compounds are commercially available under the trademarks CYMEL300, CYMEL301, CYMEL303, and CYMEL305 (manufactured by Mitsui Cyanamid Co., Ltd.), methoxymethyl group-containing glycoluril compounds are commercially available under the trademark CYMEL 1174 (manufactured by Mitsui Cyanamid Co., Ltd.) and the like; and methoxymethyl group-containing urea compounds are commercially available under the trademark MX290 (manufactured by Sanwa Chemical Co., Ltd.) and the like.

35 [0146] A compound exhibiting a crosslinking function obtained by replacing a hydrogen atom of an acid functional group in the copolymer (A2) with the above-mentioned crosslinkable functional group can also be suitably used as a crosslinking agent. The amount of the crosslinkable functional group introduced is usually 5-60 mol%, preferably 10-50 mol%, and still more preferably 15-40 mol% of the total acid functional groups in the copolymer (A2), although the specific percentage varies depending on types of crosslinkable functional group and the alkali-soluble resin into which the crosslinkable functional group is introduced. The amount of crosslinkable functional group less than 5 mol% may decrease the rate of residual coatings and tends to induce meandering and swelling of the patterns. If the amount exceeds 60 mol%, developability of exposed areas tends to decrease.

40 [0147] Methoxymethyl group-containing compounds such as dimethoxymethyl urea and tetramethoxymethyl glycoluril are particularly preferable as the crosslinking agent. These crosslinking agents may be used either individually or in combination of two or more.

55 Other additives

[0148] It is preferable to add an acid diffusion controller to the positive tone radiation-sensitive resin composition of the present invention. The acid diffusion controller controls diffusion of an acid generated from the acid generator upon exposure in the resist film to hinder undesired chemical reactions in the unexposed area.

[0149] Use of such an acid diffusion controller improves the storage stability of the composition and resolution as a resist. Moreover, line width change of the resist pattern due to fluctuation of PED can be controlled, whereby remarkably superior process stability can be achieved.

5 [0150] As the acid diffusion controller, organic compounds containing nitrogen of which the basicity does not change during exposure or heating for forming a resist pattern are preferable.

[0151] As examples of such nitrogen-containing organic compounds, a compound shown by the following formula (20) (hereinafter called "nitrogen-containing compound (I)").



15 wherein R²¹, R²², and R²³ individually represent a hydrogen atom, alkyl group having 1-15 carbon atoms, aryl group having 6-15 carbon atoms, or aralkyl group having 7-15 carbon atoms, a diamino compound having two nitrogen atoms in the molecule (hereinafter referred to as "nitrogen-containing compound (II)"), a diamino polymer having three or more nitrogen atoms in the molecule (hereinafter referred to as "nitrogen-containing compound (III)"), an amide group-containing compound, urea compound, nitrogen-containing heterocyclic compound, and the like can be given.

20 [0152] Examples of the nitrogen-containing compound (I) include monoalkylamines such as n-hexylamine, n-heptylamine, n-octylamine, n-nonylamine, and n-decylamine; dialkylamines such as di-n-butylamine, di-n-pentylamine, di-n-hexylamine, di-n-heptylamine, di-n-octylamine, di-n-nonylamine, and di-n-decylamine; trialkylamines such as triethylamine, tri-n-propylamine, tri-n-butylamine, tri-n-pentylamine, tri-n-hexylamine, tri-n-heptylamine, tri-n-octylamine, tri-n-nonylamine, tri-n-decylamine, and tri-n-dodecylamine; aromatic amines such as aniline, N-methylaniline, N,N-dimethylaniline, 2-methylaniline, 3-methylaniline, 4-methylaniline, 4-nitroaniline, diphenylamine, triphenylamine, and 1-naphthylamine; and trialcoholamines such as triethanolamine.

25 [0153] Examples of the nitrogen-containing compounds (II) include ethylenediamine, N,N,N',N'-tetramethylethylenediamine, tetramethylenediamine, hexamethylenediamine, 4,4'-diaminodiphenylmethane, 4,4'-diaminodiphenyl ether, 4,4'-diaminobenzophenone, 4,4'-diaminodiphenylamine, 2,2'-bis(4-aminophenyl)propane, 2-(3-aminophenyl)-2-(4-aminophenyl)propane, 2-(4-aminophenyl)-2-(3-hydroxyphenyl)propane, 2-(4-aminophenyl)-2-(4-hydroxyphenyl)propane, 1,4-bis[1-(4-aminophenyl)-1-methylethyl]benzene, 1,3-bis[1-(4-aminophenyl)-1-methylethyl]benzene, and the like.

30 [0154] As examples of the nitrogen-containing compound (III), polyethyleneimine, polyallylamine, and the like can be given.

35 [0155] Examples of compounds containing an amide group include formamide, N-methylformamide, N,N-dimethylformamide, acetamide, N-methylacetamide, N,N-dimethylacetamide, propionamide, benzamide, pyrrolidone, N-methylpyrrolidone, and the like.

40 [0156] Examples of urea compounds include urea, methylurea, 1,1-dimethylurea, 1,3-dimethylurea, 1,1,3,3-tetramethylurea, 1,3-diphenylurea, tributylthiourea, and the like.

45 [0157] Examples of the nitrogen-containing heterocyclic compounds include imidazoles such as imidazole, benzimidazole, 4-methylimidazole, 4-methyl-2-phenylimidazole, 2-phenylbenzimidazole, 1-t-butoxycarbonyloxy-2-phenylbenzimidazole; pyridines such as pyridine, 2-methylpyridine, 4-methylpyridine, 2-ethylpyridine, 4-ethylpyridine, 2-phenylpyridine, 4-phenylpyridine, N-methyl-4-phenylpyridine, nicotine, nicotinic acid, nicotinamide, nicotinbenzyl, quinoline, 8-oxyquinoline, and acridine; pyrazine, pyrazole, pyridazine, quinoxaline, purine, pyrrolidine, piperidine, piperidine ethanol, morpholine, 4-methylmorpholine, piperazine, 1,4-dimethylpiperazine, 1,4-diazabicyclo[2.2.2]octane; and the like.

50 [0158] Of these nitrogen-containing organic compounds, the nitrogen-containing compound (I) and the nitrogen-containing heterocyclic compound are preferable. Trialkylamines are particularly preferable among the nitrogen-containing compound (I), and pyridines are particularly preferable among the nitrogen-containing heterocyclic compounds.

[0159] In the present invention, the acid diffusion controllers can be used either individually or in combination of two or more.

[0160] The amount of the acid diffusion controller to be used is usually 0.001-15 parts by weight, preferably 0.001-10 parts by weight, and still more preferably 0.005-5 parts by weight for 100 parts by weight of the copolymer components.

55 If the amount of the acid diffusion controller is too small, resolution as a resist and PED stability tends to be impaired; if too large, sensitivity as a resist and developability of exposed areas tend to decrease.

[0161] If necessary, a surfactant may be added to the positive tone radiation-sensitive resin composition of the present invention to improve coatability of the composition, striation, developability as a resist, and the like.

[0162] Examples of such a surfactant include polyoxyethylene lauryl ether, polyoxyethylene stearyl ether, polyoxyethylene oleyl ether, polyoxyethylene octyl phenyl ether, polyoxyethylene nonyl phenyl ether, polyethylene glycol dilaurate, polyethylene glycol distearate; and commercially available products such as FTOP EF301, EF303, EF352 (manufactured by TOHKEM PRODUCTS CORPORATION), MEGAFAC F171, F173 (manufactured by Dainippon Ink and Chemicals, Inc.), Fluorad FC430, FC431 (manufactured by Sumitomo 3M Ltd.), Asahi Guard AG710, Surflon S-382, SC-101, SC-102, SC-103, SC-104, SC-105, SC-106 (manufactured by Asahi Glass Co., Ltd.), KP341 (manufactured by Shin-Etsu Chemical Co., Ltd.), and Polyflow No. 75, No. 95 (manufactured by Kyoeisha Chemical Co., Ltd.).

[0163] The amount of the surfactants to be added is usually 2 parts by weight or less for 100 parts by weight of the copolymer components.

[0164] In addition, a sensitizer may be added to the positive tone or negative tone radiation sensitive composition of the present invention. The sensitizer absorbs energy of radiation and transmits the energy to the acid generator, thereby increasing the amount of an acid to be generated upon exposure. The sensitizer also improves apparent sensitivity of a resist.

[0165] As preferable examples of the sensitizers, benzophenones, rose bengals, anthracenes, carbazoles, and the like can be given.

[0166] The amount of sensitizers to be added is usually 50 parts by weight or less for 100 parts by weight of the component (A).

[0167] In addition, a dye and/or a pigment may be added to visualize latent images of exposed areas and to reduce the effect of halation during exposure. An adhesion adjuvant may be added to improve adhesiveness to the substrate.

[0168] As other additives, halation inhibitors such as 4-hydroxy-4'-methylchalcone, form improvers, preservation stabilizers, antifoaming agents, and the like can also be added.

Preparation and use of composition

[0169] The radiation-sensitive resin composition of the present invention is prepared into a composition solution when used by homogeneously dissolving the composition in a solvent so that the total solid concentration is 5-50 wt%, and preferably 10-40 wt%, and filtering the solution using a filter with a pore diameter of about 0.2 μm .

[0170] Examples of solvents used for the preparation of the composition solution include: ethylene glycol monoalkyl ether acetates such as ethylene glycol monomethyl ether acetate, ethylene glycol monoethyl ether acetate, ethylene glycol mono-n-propyl ether acetate, and ethylene glycol mono-n-butyl ether acetate; propylene glycol monoalkyl ethers such as propylene glycol monomethyl ether, propylene glycol monoethyl ether, propylene glycol mono-n-propyl ether, and propylene glycol mono-n-butyl ether; propylene glycol dialkyl ethers such as propylene glycol dimethyl ether, propylene glycol diethyl ether, propylene glycol di-n-propyl ether, and propylene glycol di-n-butyl ether; propylene glycol monoalkyl ether acetates such as propylene glycol monomethyl ether acetate, propylene glycol monoethyl ether acetate, propylene glycol mono-n-propyl ether acetate, and propylene glycol mono-n-butyl ether acetate; lactic acid esters such as methyl lactate, ethyl lactate, n-propyl lactate, and i-propyl lactate; aliphatic carboxylic acid esters such as n-amyl formate, i-amyl formate, ethyl acetate, n-propyl acetate, i-propyl acetate, n-butyl acetate, i-butyl acetate, n-amyl acetate, i-amyl acetate, i-propyl propionate, n-butyl propionate, and i-butyl propionate; other esters such as ethyl hydroxyacetate, ethyl 2-hydroxy-2-methylpropionate, methyl 2-hydroxy-3-methylbutyrate, ethyl methoxyacetate, ethyl ethoxyacetate, methyl 3-methoxypropionate, ethyl 3-methoxypropionate, methyl 3-ethoxypropionate, ethyl 3-ethoxypropionate, butyl 3-methoxyacetate, butyl 3-methyl-3-methoxyacetate, butyl 3-methyl-3-methoxypropionate, butyl 3-methyl-3-methoxybutyrate, methyl acetoacetate, ethyl acetoacetate, methyl pyruvate, and ethyl pyruvate; aromatic hydrocarbons such as toluene and xylene; ketones such as methyl ethyl ketone, methyl propyl ketone, methyl butyl ketone, 2-heptanone, 3-heptanone, 4-heptanone, and cyclohexanone; amides such as N-methylformamide, N,N-dimethylformamide, N-methylacetamide, N,N-dimethyl acetamide, and N-methylpyrrolidone; and lactones such as γ -butyrolactone.

[0171] These solvents may be used either individually or in combinations of two or more.

Formation of resist patterns

[0172] A resist pattern is formed from the radiation-sensitive resin composition of the present invention by applying the composition solution prepared as mentioned above to substrates such as a silicon wafer or a wafer covered with aluminum using an appropriate application method such as rotational coating, cast coating, and roll coating to form a resist film. The resist film is then optionally heated at a temperature of about 70-160°C (hereinafter referred to as "pre-bake") and exposed to light through a predetermined mask pattern. Radiation used here can be appropriately selected according to the types of acid generator from among ultraviolet rays such as i-line (wavelength: 365 nm), ultraviolet rays such as ArF excimer laser (wavelength: 193 nm) or KrF excimer laser (wavelength: 248 nm), X-rays such as synchrotron radiation, and charged particle rays such as electron beams. The exposure conditions such as the amount

of exposure are appropriately determined depending on the composition of the radiation-sensitive resin composition, types of additives, and the like.

[0173] In the present invention, it is preferable to heat the resist at 90-160°C for 30 second or more after exposure (hereinafter referred to as "post-exposure bake") in order to stably form high precision resist patterns exhibiting excellent resolution, developability, and pattern form, free from a pattern skirting problem, and exhibiting superior PED. If the temperature for post-exposure bake is less than 90°C, not only the effect of PED stability tends to be impaired, but also resist patterns tend to produce a skirt according to the resist pattern forming conditions such as a resist thickness when the patterns are formed on an SiN substrate or a BPSG substrate having an SiO₂ film in which ions such as boron ions phosphorous ions are injected. Such a resin composition may not be used in actual devices.

[0174] The exposed resist film is then developed using an alkaline developer at 10-50°C for 30-200 seconds to form a predetermined resist pattern.

[0175] As the alkaline developer, an alkaline aqueous solution prepared by dissolving an alkali such as an alkali metal hydroxide, aqueous ammonia, mono-, di-, or tri-alkylamine, mono-, di-, or tri-alkanolamine, heterocyclic amine, tetraalkylammonium hydroxide, choline, 1,8-diazabicyclo[5.4.0]-7-undecene, or 1,5-diazabicyclo[4.3.0]-5-nonene to a concentration of 1-10 wt%, and preferably 1-5 wt% can be used.

[0176] Moreover, an appropriate amount of a water-soluble organic solvent such as methanol and ethanol or a surfactant can be added to the developer comprising the above alkaline aqueous solution.

[0177] When using the developer comprising the alkaline aqueous solution, the resist film is washed with water after development.

[0178] When forming a resist pattern, a protective film may be provided on the resist film in order to prevent an adverse effect of basic impurities and the like which are present in the environmental atmosphere.

EXAMPLES

[0179] The embodiments of the present invention will be described in more detail by examples. However, these examples should not be construed as limiting the present invention.

Synthesis Examples of component (A1)

Synthesis Example 1

[0180] 86 g of p-acetoxystyrene, 5 g of styrene, 40 g of p-t-butoxystyrene, 11 g of N,N-dimethylacrylamide, 6 g of azobisisobutyronitrile (hereinafter referred to as "AIBN"), and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and was added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0181] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, styrene, p-t-butoxystyrene, and N,N-dimethylacrylamide of the copolymer was 62:5:23:10. This resin is referred to as a "resin (A-1)".

Synthesis Example 2

[0182] 80 g of p-acetoxystyrene, 19 g of t-butylacrylate, 35 g of p-t-butoxystyrene, 11 g of N,N-dimethylacrylamide, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 230 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the purified resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for eight hours while refluxing at a boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0183] The resin was found to have Mw and Mw/Mn of 11,500 and 1.6 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, t-butyl acrylate, p-t-butoxystyrene, and N,N-dimethylacrylamide of the copolymer was 55:15:20:10. This resin is referred to as a "resin (A-2)".

Synthesis Example 3

[0184] 91 g of p-acetoxystyrene, 50 g of p-t-butoxystyrene, 11 g of N,N-dimethylacrylamide, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0185] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization ratio of p-hydroxystyrene, p-t-butoxystyrene, and N,N-dimethylacrylamide of the copolymer was 62:28:10. This resin is referred to as a "resin (A-3)".

Synthesis Example 4

[0186] 146 g of p-acetoxystyrene, 11 g of N,N-dimethylacrylamide, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0187] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization ratio of p-hydroxystyrene and N,N-dimethylacrylamide was 90:10. This resin is referred to as a "resin (A-4)".

Synthesis Example 5

[0188] 86 g of p-acetoxystyrene, 5 g of styrene, 40 g of p-t-butoxystyrene, 28 g of 1-acryloyl-2-phenylbenzimidazole, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0189] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, styrene, p-t-butoxystyrene, and 1-acryloyl-2-phenylbenzimidazole of the copolymer was 62:5:23:10. This resin is referred to as a "resin (A-5)".

Synthesis Example 6

[0190] 80 g of p-acetoxystyrene, 19 g of t-butylacrylate, 35 g of p-t-butoxystyrene, 28 g of 1-acryloyl-2-phenylbenzimidazole, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 230 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the purified resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for eight hours while refluxing at a boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0191] The resin was found to have Mw and Mw/Mn of 11,500 and 1.6 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, t-butyl acrylate, p-t-butoxystyrene, and 1-acryloyl-2-phenylbenzimidazole of the copolymer was 55:15:20:10. This resin is referred to as a "resin (A-6)".

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Synthesis Example 7

[0192] 91 g of p-acetoxystyrene, 50 g of p-t-butoxystyrene, 14 g of 1-acryloyl imidazole, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0193] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization ratio of p-hydroxystyrene, p-t-butoxystyrene, and 1-acryloyl imidazole of the copolymer was 62:28:10. This resin is referred to as a "resin (A-7)".

Synthesis Example 8

[0194] 146 g of p-acetoxystyrene, 28 g of 1-acryloyl-2-phenylbenzimidazole, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0195] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization ratio of p-hydroxystyrene and 1-acryloyl-2-phenylbenzimidazole was 90:10. This resin is referred to as a "resin (A-8)".

Synthesis Example 9

[0196] 101 g of p-acetoxystyrene, 5 g of styrene, 42 g of p-t-butoxystyrene, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 160 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0197] The resin was found to have Mw and Mw/Mn of 16,000 and 1.7 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, styrene, and p-t-butoxystyrene of the copolymer was 72:5:23. This resin is referred to as a "resin (a-1)".

Synthesis Example 10

[0198] 100 g of p-acetoxystyrene, 25 g of t-butyl acrylate, 18 g of styrene, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 230 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0199] The resin was found to have Mw and Mw/Mn of 11,500 and 1.6 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, t-butyl acrylate, and styrene of the copolymer was 61:19:20. This resin is referred to as a "resin (a-2)".

Synthesis Example 11

[0200] 125 g of p-acetoxystyrene, 20 g of t-butyl acrylate, 10 g of styrene, 8 g of 2,5-dimethylhexane-2,5-diacrylate, 8 g of AIBN, and 6 g of t-dodecylmercaptan were dissolved in 170 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours while maintaining the reaction temperature at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for 8 hours while refluxing at the boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0201] The resin was found to have Mw and Mw/Mn of 40,000 and 2.6, respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, t-butyl acrylate, styrene, and 2,5-dimethylhexane-2,5-diacrylate of the copolymer was 72:10:15:3. This resin is referred to as a "resin (a-3)".

Synthesis Example 12

[0202] 140 g of p-acetoxystyrene, 50 g of p-t-butoxystyrene, 9 g of 2,5-dimethylhexane-2,5-diacrylate, 8 g of AIBN, and 6 g of t-dodecylmercaptan were dissolved in 240 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the purified resin, 300 g of methanol, 100 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for one hour while refluxing at a boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0203] The resin was found to have Mw and Mw/Mn of 40,000 and 2.6 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, p-t-butoxystyrene, and 2,5-hexanedimethanoldiacrylate of the copolymer was 67:30:3. This resin is referred to as a "resin (a-4)".

Synthesis Example 13

[0204] 176 g of p-t-butoxystyrene was anionically polymerized at -78°C in 500 ml of tetrahydrofuran using s-butyl-lithium as a catalyst. After polymerization, the resulting resin solution was coagulated in methanol to obtain 150 g of white poly(p-t-butoxystyrene). The poly(p-t-butoxystyrene) was dissolved in 600 g of dioxane. After the addition of diluted hydrochloric acid, the mixture was hydrolyzed at 70°C for 2 hours. The reaction product was caused to coagulate in a large quantity of water to obtain a white resin. A step of dissolving the resulting resin in acetone and adding dropwise to a large quantity of water to coagulate the resin was repeated. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

[0205] The Mw and Mw/Mn of this resin were 10,400 and 1.01, respectively. ¹³C-NMR analysis confirmed that only part of t-butyl group in the poly(p-t-butoxystyrene) had a hydrolyzed structure and the molar ratio of p-t-butoxystyrene and p-hydroxystyrene was 68:32. This resin is referred to as a "resin (a-5)".

Synthesis Example 14

[0206] 7 g of di-t-butyl carbonate was added to a solution in which 12 g of poly(p-hydroxystyrene) and 5 g of triethylamine were dissolved in 50 g of dioxane while stirring. The mixture was stirred for 6 hours at room temperature. Oxalic acid was then added to neutralize triethylamine. The reaction solution was dropped into a large quantity of water to coagulate the resin. The coagulated resin was washed with purified water several times. The resin was then filtered and dried at 50°C overnight under reduced pressure.

[0207] Mw and Mw/Mn of this resin were respectively 9,200 and 1.8. As a result of ¹³C-NMR analysis, the resin was found to have a structure in which 30 mol% of hydrogen atoms of a phenolic hydroxyl group in poly(p-hydroxystyrene) was replaced by t-butoxycarbonyl groups. This resin is referred to as a "resin (a-6)".

Synthesis Example 15

[0208] 176 g of p-t-butoxystyrene was anionically polymerized at -78°C in 500 ml of tetrahydrofuran using s-butyl-lithium as a catalyst. After polymerization, the resulting resin solution was coagulated in methanol to obtain 150 g of

white poly(p-t-butoxystyrene). The poly(4-t-butoxystyrene) was dissolved in 600 g of dioxane. After the addition of diluted hydrochloric acid, the mixture was hydrolyzed at 70°C for 12 hours. The reaction product was caused to coagulate in a large quantity of water to obtain a white resin. A step of dissolving the resulting resin in acetone and adding dropwise to a large quantity of water to coagulate the resin was repeated. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

5 [0209] The resin was confirmed to be poly(p-hydroxystyrene) having Mw of 11,400 and Mw/Mn of 1.01.

[0210] Then, 24 g of this poly(p-hydroxystyrene) was dissolved in 100 g of n-butyl acetate. Nitrogen gas was bubbled through the mixture for 30 minutes. After the addition of 8 g of cyclohexyl vinyl ether and 1 g of pyridinium p-toluenesulfonate as a catalyst, the mixture was allowed to react at room temperature for 12 hours. The reaction solution was dropped into a large quantity of 1 wt% ammonium aqueous solution to coagulate the resin. The resin was filtered and dried overnight in a vacuum drier at 50°C.

10 [0211] Mw and Mw/Mn of this resin were respectively 13,000 and 1.01. As a result of ¹³C-NMR analysis, the resin was found to have a structure in which 23 mol% of hydrogen atoms of a phenolic hydroxyl group in poly(p-hydroxystyrene) was replaced by 1-cyclohexyloxyethyl groups. This resin is referred to as a "resin (a-7)".

15 Synthesis Example 16

[0212] 24 g of poly(p-hydroxystyrene) with Mw of 12,000 was dissolved in 100 g of dioxane. Nitrogen gas was bubbled through the mixture for 30 minutes. After the addition of 3 g of ethyl vinyl ether and 3 g of ethyl-1-propenyl ether, and 1 g of pyridinium p-toluenesulfonate as a catalyst, the mixture was reacted for 12 hours at room temperature. The reaction solution was dropped into a large quantity of 1 wt% ammonium aqueous solution to coagulate the resin. The resin was filtered and dried overnight in a vacuum drier at 50°C.

20 [0213] Mw and Mw/Mn of this resin were respectively 15,000 and 1.6. As a result of ¹³C-NMR analysis, the resin was found to have a structure in which 20 mol% of hydrogen atoms of a phenolic hydroxyl group in poly(p-hydroxystyrene) was replaced by 1-ethoxyethyl groups, and 15 mol% by 1-ethoxy propyl groups. This resin is referred to as a "resin (a-8)".

25 Synthesis Example 17

30 [0214] 25 g of a copolymer of p-hydroxystyrene and p-t-butoxystyrene was dissolved in 100 g of n-butyl acetate. Nitrogen gas was bubbled through the mixture for 30 minutes. After the addition of 3.3 g of ethyl vinyl ether and 1 g of pyridinium p-toluenesulfonate as a catalyst, the mixture was reacted at room temperature for 12 hours. The reaction solution was dropped into a large quantity of 1 wt% ammonium aqueous solution to coagulate the resin. The resin was filtered and dried overnight in a vacuum drier at 50°C.

35 [0215] Mw and Mw/Mn of this resin were respectively 13,000 and 1.01. As a result of ¹³C-NMR analysis, the resin was found to have a structure in which 23 mol% of hydrogen atoms of a phenolic hydroxyl group in poly(p-hydroxystyrene) was replaced by ethoxyethyl groups and 10 mol% by t-butyl groups. This resin is referred to as a "resin (a-10)".

40 Synthesis Example 18

45 [0216] 114 g of p-acetoxystyrene, 19 g of t-butylacrylate, 32 g of p-t-butoxystyrene, 6 g of AIBN, and 1 g of t-dodecylmercaptan were dissolved in 230 g of propylene glycol monomethyl ether. The mixture was polymerized for 16 hours at 70°C in a nitrogen atmosphere. After polymerization, the reaction solution was added dropwise to a large quantity of hexane to coagulate and purify the resulting resin. After the addition of 150 g of propylene glycol monomethyl ether to the purified resin, 300 g of methanol, 80 g of triethylamine, and 15 g of water were added. The mixture was hydrolyzed for eight hours while refluxing at a boiling point. After the reaction, the solvent and triethylamine were evaporated under reduced pressure. The resulting resin was dissolved in acetone and added dropwise to a large quantity of water to coagulate the resin. The resulting white powder was filtered and dried overnight at 50°C under reduced pressure.

50 [0217] The resin was found to have Mw and Mw/Mn of 11,500 and 1.6 respectively. The result of ¹³C-NMR analysis confirmed that the copolymerization molar ratio of p-hydroxystyrene, t-butyl acrylate, and p-t-butoxystyrene of the copolymer was 65:15:20. This resin is referred to as a "resin (a-11)".

55 Acid generator (B)

[0218]

B-1: Bis(4-t-butylphenyl)iodonium nonafluoro-n-butanesulfonate

B-2: Bis(4-t-butylphenyl)iodonium 10-camphorsulfonate
B-3: Bis(4-t-butylphenyl)iodoniumtrifluoromethane sulfonate
B-4: n-Trifluoromethanesulfonyloxy-5-norbornene-2,3-dicarboxyimide
5 B-5: Bis(cyclohexylsulfonyl)diazomethane
B-6: Triphenylsulfoniumtrifluoromethanesulfonate
B-7: N-(10-Camphorsulfonyloxy)succinimide

Crosslinking agent (C)

10 [0219]

C-1: Dimethoxymethylurea ("MX290" manufactured by Sanwa Chemical Co., Ltd.)
C-2: Tetramethoxymethyl glycoluril ("CYMEL 1174" manufactured by Mitsui Cyanamid Co., Ltd.)

15 Acid diffusion control agent

[0220]

20 D-1: Tri-n-octylamine
D-2: Triethanolamine
D-3: 2-Phenylpyridine
D-4: N,N,N,N-Tetrakis(2-hydroxypropyl)ethylenediamine
D-5: 1-t-Butylcarboxyloxy-2-phenylbenzimidazole

25 Alkali-soluble resin (E)

[0221]

30 E-1: Poly(p-hydroxystyrene) (Mw=7,500, Mw/Mn=1.1)
E-2: p-Hydroxystyrene/styrene copolymer (copolymerization ratio: 8:2, Mw=4,500, Mw/Mn=11)

Other additives

[0222]

35 F-1: Poly(p-hydroxystyrene) (Mw=3,000)
F-2: 2,2-Bis(4-t-butoxyphenyl)propane
F-3: 1-Adamantane carboxylic acid

40 Solvent

[0223]

45 G-1: Ethyl lactate
G-2: Ethyl 3-ethoxypropionate
G-3: Propylene glycol monoethyl ether

<Chemically amplified positive tone radiation sensitive resin composition>

50 Examples 1-40 and Comparative Examples 1-4

55 [0224] Components shown in Table 1 and Table 2 (part(s) indicates part(s) by weight) were mixed to prepare homogeneous solutions. The solutions were filtered through a membrane filter with a pore diameter of 0.2 μ m to prepare solution compositions. The solution compositions were spin-coated on a silicon wafer and pre-baked under the conditions shown in Tables 3 and 4 to form a resist films with a thickness of 0.5 μ m.

[0225] The resist films were exposed under the conditions shown in Tables 3 and 4 using a stepper "NSR2205 EX12B" (manufactured by Nikon Corp., numerical aperture: 0.55) in Examples 1-17, Examples 21-38, and Comparative Examples 1-3. In Examples 18-20, Examples 39-40, and Comparative Example 4, the resist films were exposed using

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5 ' an electron beam lithography system "HL700" (manufactured by Hitachi, Ltd., acceleration voltage: 30 KeV) in which the acceleration voltage was remodeled to 50 KeV. PEB was performed under the conditions shown in Tables 3 and 4. The resist films were developed at 23°C for 1 minute by a paddle method using a 2.38 wt% tetramethyl ammonium hydroxide aqueous solution. The resist films were then washed with deionized water and dried to form a resist pattern.

The evaluation results of each resist are shown in Tables 5 and 6.

Table 1

	Acid generator (parts)	Resin (parts)	Additives (parts)	Acid diffusion control agent (parts)	Solvent (parts)
10	Example 1 B-1(2) B-3(2)	a-1(95) A-1(5)	F-3(0.1)	D-4(0.2)	G-1(200)
15	Example 2 B-4(8)	a-1(90), A-1(10)	-	D-5(0.15)	G-1(200)
20	Example 3 B-1(2) B-3(0.5)	a-11(95), A-3(5)	-	D-5(0.2)	G-1(160) G-3(40)
25	Example 4 B-1(2) B-3(2)	a-4(80),A-2(20)	F-3(0.1)	D-4(0.2)	G-1(200)
30	Example 5 B-4(6)	a-1(60),A-1(40)	-	D-5(0.2)	G-1(200)
35	Example 6 B-1(2) B-2(2)	a-2(90) A-3(10)	-	D-5(0.2)	G-1(140) G-3(60)
40	Example 7 B-4(4)	a-3(80),A-3(20)	-	D-5(0.2)	G-1(140) G-3(60)
45	Example 8 B-4(6) B-2(2)	a-4(80) A-3(20)	F-3(0.1)	D-2(0.2)	G-1(140) G-3(60)
50	Example 9 B-3(4)	a-5(80), A-3(10)	-	D-5(0.1)	G-1(200)
	Example 10 B-4(6)	a-6(90),A-3(10)	-	D-5(0.1)	G-1(200)
	Example 11 B-5(1)	a-7(85) E-1(10),A-3(5)	-	D-2(0.2)	G-2(200)
	Example 12 B-5(1)	a-8(60) E-1(10), A-3(20)	F-3(0.2)	D-1(0.2)	G-1(140) G-2(60)
	Example 13 B-4(8)	a-1(90),A-4(10)	-	D-5(0.15)	G-1(200)
	Example 14 B-6(3)	a-10(70) E-2(20),A-3(10)	F-3(0.2)	D-1(0.1) D-2(0.1)	G-1(140) G-2(60)
	Example 15 B-1(2) B-3(0.5)	a-11(92) E-1(5), A-2(3)	-	D-5(0.2)	G-1(200)
	Example 16 B-5(4)	a-1(90),A-2(10)	-	D-5(0.2)	G-1(200)
	Example 17 B-5(4)	a-1(100),A-1(10)	-	D-5(0.15)	G-1(200)
	Example 18 B-6(5)	a-11(80),A-2(20)	F-2(5)	D-5(0.1)	G-1(140) G-3(60)
	Example 19 B-6(5)	a-4(90),A-3(10)	-	D-5(0.1)	G-1(200)
	Example 20 B-6(5)	a-1(100),A-1(10)	-	D-5(0.1)	G-1(200)

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Table 2

	Acid generator (parts)	Resin (parts)	Additives (parts)	Acid diffusion control agent (parts)	Solvent (parts)
5	Example 21 B-1(2) B-3(2)	a-1(95) A-5(5)	F-3(0.1)	D-4(0.2)	G-1(200)
10	Example 22 B-4(8)	a-1(90), A-5(10)	-	D-5(0.15)	G-1(200)
15	Example 23 B-1(2) B-3(0.5)	a-11(95), A-7(5)	-	D-5(0.2)	G-1(160) G-3(40)
20	Example 24 B-1(2) B-3(2)	a-4(80),A-6(20)	F-3(0.1)	D-4(0.2)	G-1(200)
25	Example 25 B-4(6)	a-1(60),A-5(40)	-	D-5(0.2)	G-1(200)
30	Example 26 B-1(2) B-2(2)	a-2(90) A-7(10)	-	D-5(0.2)	G-1(140) G-3(60)
35	Example 27 B-4(4)	a-3(80),A-7(20)	-	D-5(0.2)	G-1(140) G-3(60)
40	Example 28 B-4(6) B-2(2)	a-4(80) A-7(20)	F-3(0.1)	D-2(0.2)	G-1(140) G-3(60)
45	Example 29 B-3(4)	a-5(80),A-7(10)	-	D-5(0.1)	G-1(200)
50	Example 30 B-4(6)	a-6(90), A-7(10)	-	D-5(0.1)	G-1(200)
55	Example 31 B-5(1)	a-7(85) E-1(10),A-7(5)	-	D-2(0.2)	G-2(200)
	Example 32 B-5(1)	a-8(60) E-1(10), A-7(20)	F-3(0.2)	D-1(0.2)	G-1(140) G-2(60)
	Example 33 B-4(8)	a-1(90), A-8(10)	-	D-5(0.15)	G-1(200)
	Example 34 B-6(3)	a-10(70) E-2(20),A-7(10)	F-3(0.2)	D-1(0.1) D-2(0.1)	G-1(140) G-2(60)
	Example 35 B-1(2) B-3(0.5)	a-11(92) E-1(5), A-6(3)	-	D-5(0.2)	G-1(200)
	Example 36 B-5(4)	a-1(90),A-6(10)	-	D-5(0.2)	G-1(200)
	Example 37 B-5(4)	a-1 (100) A-5(10)	-	D-5(0.15)	G-1(200)
	Example 38 B-4(5) B-7(5) B-2(1)	a-1(90), A-1 (10)	-	D-5(0.15)	G-1(140) G-3(60)
	Example 39 B-6(5)	a-4(90), A-7(10)	-	D-5(0.1)	G-1(200)
	Example 40 B-6(5)	a-1(100),A-5(10)	-	D-5(0.1)	G-1(200)
	Comparative Example 1 B-1(2) B-3(2)	a-4(100)	F-3(0.1)	D-4(0.2)	G-1(200)
	Comparative Example 2 B-3(8)	a-1(100)	-	D-5(0.2)	G-1(200)
	Comparative Example 3 B-4(6) B-2(2)	a-11(100)	-	D-5(0.2)	G-1(200)
	Comparative Example 4 B-6(3) B-4(4)	a-1(100)	-	D-5(0.15)	G-1(200)

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Table 3

	Pre-bake		Exposure source	Post-exposure bake		
	Temperature (°C)	Time (S)		Temperature (°C)	Time (S)	
5	Example 1	130	60	KrF excimer laser	130	60
10	Example 2	130	60	KrF excimer laser	130	60
15	Example 3	130	60	KrF excimer laser	130	60
20	Example 4	130	60	KrF excimer laser	130	60
25	Example 5	130	60	KrF excimer laser	130	60
30	Example 6	110	60	KrF excimer laser	130	60
35	Example 7	110	60	KrF excimer laser	130	60
40	Example 8	130	60	KrF excimer laser	130	60
45	Example 9	110	60	KrF excimer laser	100	60
50	Example 10	90	60	KrF excimer laser	100	60
55	Example 11	90	60	KrF excimer laser	100	60
60	Example 12	90	60	KrF excimer laser	100	60
65	Example 13	130	60	KrF excimer laser	130	60
70	Example 14	90	60	KrF excimer laser	100	60
75	Example 15	130	60	KrF excimer laser	130	60
80	Example 16	130	60	KrF excimer laser	130	60
85	Example 17	130	60	KrF excimer laser	130	60
90	Example 18	110	60	Electron beam	130	60
95	Example 19	110	60	Electron beam	130	60
100	Example 20	110	60	Electron beam	130	60

Table 4

	Pre-bake		Exposure source	Post-exposure bake		
	Temperature (°C)	Time (S)		Temperature (°C)	Time (S)	
40	Example 21	130	60	KrF excimer laser	130	60
45	Example 22	130	60	KrF excimer laser	130	60
50	Example 23	130	60	KrF excimer laser	130	60
55	Example 24	130	60	KrF excimer laser	130	60
60	Example 25	130	60	KrF excimer laser	130	60
65	Example 26	110	60	KrF excimer laser	130	60
70	Example 27	110	60	KrF excimer laser	130	60
75	Example 28	130	60	KrF excimer laser	130	60
80	Example 29	110	60	KrF excimer laser	100	60
85	Example 30	90	60	KrF excimer laser	100	60
90	Example 31	90	60	KrF excimer laser	100	60
95	Example 32	90	60	KrF excimer laser	100	60

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Table 4 (continued)

	Pre-bake		Exposure source	Post-exposure bake		
	Temperature (°C)	Time (S)		Temperature (°C)	Time (S)	
5	Example 33	130	60	KrF excimer laser	130	60
10	Example 34	90	60	KrF excimer laser	100	60
15	Example 35	130	60	KrF excimer laser	130	60
20	Example 36	130	60	KrF excimer laser	130	60
25	Example 37	130	60	KrF excimer laser	130	60
30	Example 38	130	60	KrF excimer laser	130	60
35	Example 39	110	60	Electron beam	130	60
40	Example 40	110	60	Electron beam	130	60
45	Comparative Example 1	130	60	KrF excimer laser	130	60
50	Comparative Example 2	130	60	KrF excimer laser	130	60
55	Comparative Example 3	130	60	KrF excimer laser	130	60
	Comparative Example 4	130	60	Electron beam	130	60

Table 5

	Sensitivity (mJ/cm ²)	Resolution (μm)	PED	Iso-dense bias	Storage stability
25	Example 1	25	0.20	Good	Good
30	Example 2	22	0.18	Good	Good
35	Example 3	24	0.19	Good	Good
40	Example 4	23	0.18	Good	Good
45	Example 5	23	0.17	Good	Good
50	Example 6	25	0.19	Good	Good
55	Example 7	24	0.20	Good	Good
	Example 8	24	0.20	Good	Good
	Example 9	23	0.20	Good	Good
	Example 10	26	0.20	Good	Good
	Example 11	23	0.20	Good	Good
	Example 12	22	0.20	Good	Good
	Example 13	22	0.21	Good	Good
	Example 14	23	0.20	Good	Good
	Example 15	25	0.18	Good	Good
	Example 16	25	0.19	Good	Good
	Example 17	24	0.17	Good	Good
	Example 18	4uC	0.17	Good	Good
	Example 19	5uC	0.17	Good	Good
	Example 20	3uC	0.18	Good	Good

Table 6

	Sensitivity (mJ/cm ²)	Resolution (μm)	PED	Iso-dense bias	Storage stability
5	Example 21	25	0.19	Good	Good
10	Example 22	22	0.18	Good	Good
15	Example 23	24	0.18	Good	Good
20	Example 24	23	0.18	Good	Good
25	Example 25	23	0.17	Good	Good
30	Example 26	25	0.19	Good	Good
35	Example 27	24	0.20	Good	Good
40	Example 28	24	0.20	Good	Good
45	Example 29	23	0.20	Good	Good
50	Example 30	26	0.19	Good	Good
55	Example 31	23	0.20	Good	Good
60	Example 32	22	0.20	Good	Good
65	Example 33	22	0.19	Good	Good
70	Example 34	23	0.19	Good	Good
75	Example 35	25	0.17	Good	Good
80	Example 36	25	0.18	Good	Good
85	Example 37	24	0.18	Good	Good
90	Example 38	30	0.17	Good	Good
95	Example 39	5uC	0.14	Good	Good
100	Example 40	3uC	0.14	Good	Good
105	Comparative Example 1	34	0.22	Good	Bad
110	Comparative Example 2	27	0.20	Bad	Bad
115	Comparative Example 3	26	0.22	Bad	Bad
120	Comparative Example 4	5uC	0.22	Bad	Good

[0226] Measurement of Mw and Mn in the above Examples 1-40, Comparative Examples 1-4 and the following Examples 21-23 and Comparative Example 5, and evaluation of each composition were carried out as follows.

Mw and Mn

[0227] Mw was measured by gel permeation chromatography (GPC) using GPC columns (manufactured by Tosoh Corp., G2000HXL x 2, G3000HXL x 1, G4000HXL x 1) under the following conditions. Flow rate: 1.0 ml/minute, eluate: tetrahydrofuran, column temperature: 40°C, standard reference material: monodispersed polystyrene

Sensitivity

[0228] Sensitivity was evaluated based on an optimum exposure dose which is a dose capable of forming a 1:1 line and space pattern (1L1S) with a line width of 0.22 μm, when a resist film formed on a silicon wafer is exposed to light, immediately followed by baking, alkali development, washing with water, and drying.

Resolution (1L1S)

[0229] A minimum dimension of line-and-space patterns (1L1S) resolved at an optimum dose at which a 1:1 1L1S with a line width of 0.25 μm is formed is taken as a standard for resolution.

Iso-dense bias

5 [0230] An iso-dense bias was determined by subtracting 0.18 μm from a 1L5S pattern size when a resist is exposed to an optimum dose, which is a dose capable of forming a 1:1 line width from a line-and-space (1L1S) pattern with a designed line width of 0.18 μm . A resist not forming a 1L5S pattern with the optimum dose is judged "incapable of forming patterns".

PED stability

10 [0231] A resist, exposed to radiation at a dose equivalent to an optimum dose when a resist is baked and developed immediately after exposure, was placed for two hours in a chamber in which an ammonia concentration is controlled at 5 ppb, followed by post exposure baking to form a line-and-space (1L1S) pattern with a designed line width of 0.18 μm . PED stability was judged to be "Excellent" when the line width at the top of the pattern (L_{top}) satisfies an inequality $0.85 \times 0.18 < L_{\text{top}} < 1.1 \times 0.18$, otherwise judged to be "Bad". A judgment of "No pattern separation" was given when 15 no line-and-space (1L1S) pattern with a designed line width of 0.18 μm was formed.

Storage stability

20 [0232] Storage stability was judged to be "Excellent" when sensitivity within 72 hours after preparation (a) and the sample sensitivity after storing for 3 months or longer at 23°C (b) satisfy an inequality $-0.1 < (b-a)/a < 0.1$, otherwise judged to be "Bad".

<Chemically amplified negative tone radiation sensitive resin composition>

25 Examples 41-42 and Comparative Example 5

30 [0233] Components shown in Table 7 (part(s) indicates part(s) by weight) were mixed to prepare homogeneous solutions. The solutions were filtered through a membrane filter with a pore diameter of 0.2 μm to prepare solution compositions. The solution composition was spin-coated on a silicon wafer. PB was then performed under the conditions shown in Table 8 to form a resist coating with a thickness of 0.5 μm .

35 [0234] The resist films were exposed under the conditions shown in Table 8 using a stepper "NSR2205 EX12B" (manufactured by Nikon Corp., numerical aperture: 0.55) and baked (PEB) under the conditions shown in Table 8. The resist films were developed at 23°C for 1 minute by a paddle method using a 2.38 wt% tetramethyl ammonium hydroxide aqueous solution. The resist films were then washed with deionized water and dried to form a resist pattern. The results of the evaluation of each resist are shown in Table 9.

Table 7

	Acid generator (parts)	Resin (parts)	Added Crosslinking agent (parts)	Acid diffusion control agent (parts)	Solvent (parts)
Example 41	B-6(2)	c-2(90) A-1(10)	C-1(7)	D-1(0.5)	G-1(600)
Example 42	B-6(2)	c-1(90) A-3(10)	C-2(7)	D-1(0.5)	G-1(600)
Comparative Example 5	B-6(2)	c-2(100)	C-1(7)	D-1(0.5)	G-1(600)

Table 8

	Pre-bake		Exposure source	Post-exposure bake	
	Temperature (°C)	Time (S)		Temperature (°C)	Time (S)
Example 41	90	60	KrF excimer laser	110	60
Example 42	90	60	KrF excimer laser	110	60
Comparative Example 5	90	60	KrF excimer laser	110	60

Table 9

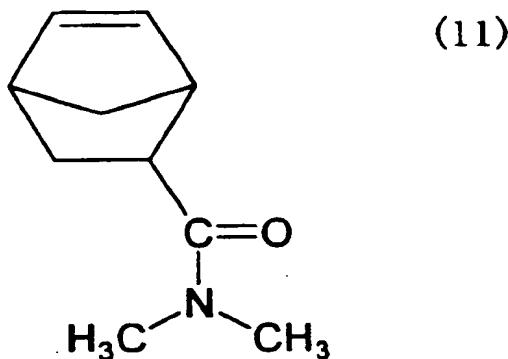
	Sensitivity (mJ/cm ²)	Resolution (fm)	PED	Iso-dense bias	Storage stability
Example 41	30	0.20	Good	Good	Good
Example 42	29	0.20	Good	Good	Good
Comparative Example 5	30	0.21	Bad	Bad	Good

<Synthesis of component (A3)>

Synthesis Example 19

[0235] A 1 l three necked egg plant flask was charged with 396.2 g (4 mol) of N,N-dimethylacrylamide, followed by nitrogen gas purge. A 500 ml dripping funnel was charged with 318 ml (4 mol) of cyclopentadiene under nitrogen gas atmosphere. The flask was heated at 50°C and cyclopentadiene was slowly added dropwise from the dripping funnel at a rate of 2 ml/min. After the addition, the mixture was allowed to stand for 5 hours while heating at 50°C. The conversion rate was determined by gas chromatography to confirm that the yield of the target compound was 85 mol%. The reaction solution was purified by vacuum distillation at 87°C and 0.8 mmHg to obtain N,N-dimethylbicyclo[2.2.1]hepto-2-ene-5-carboxylic acid amide at a yield of 70 mol%. This compound is referred to as a "Norbornene derivative (I-1)".

25

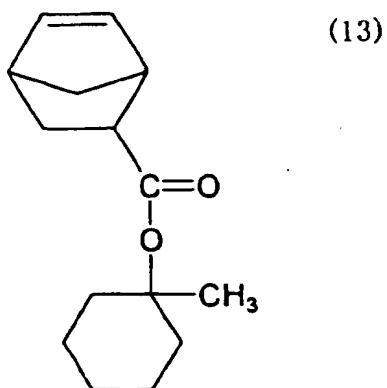
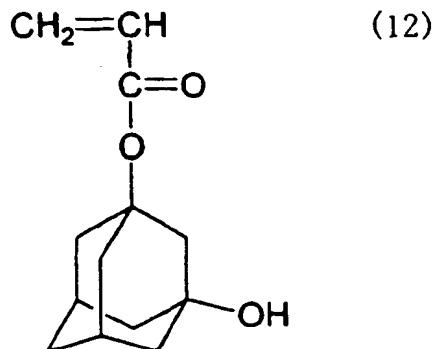


Synthesis Example 20

[0236] 4.9 g of the norbornene derivative (I-1), 13.0 g of a (meth)acrylic acid derivative shown by the following formula (12) (hereinafter referred to as "(meth)acrylic acid derivative ①"), 20.6 g of a norbornene derivative shown by the following formula (13) (hereinafter referred to as "norbornene derivative ②"), and 11.5 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.9 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 35 g (yield: 70 wt%) of white resin powder.

[0237] This resin was confirmed to be a copolymer having an Mw of 4,300, consisting of norbornene derivative (I-1), (meth)acrylic acid derivative ①, norbornene derivative ②, and maleic anhydride at a proportion of 10 mol%, 20 mol%, 30 mol%, and 40 mol% respectively. This resin is referred to as a "resin (A-9)".

55



Synthesis Example 21

[0238] 2.9 g of N,N-dimethylacrylamide, 13.0 g of (meth) acrylic acid derivative ①, 24.0 g norbornene derivative ②, and 10.1 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.9 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 37 g (yield: 74 wt%) of white resin powder.

[0239] This resin was confirmed to be a copolymer having an Mw of 4,900, consisting of recurring units derived from N,N-dimethylacrylamide, (meth)acrylic acid derivative ①, norbornene derivative ②, and maleic anhydride at a proportion of 10 mol%, 20 mol%, 35 mol%, and 35 mol% respectively. This resin is referred to as a "resin (A-10)".

45 Synthesis Example 22

[0240] 4.5 g of the norbornene derivative (I-1), 12.2 g of (meth)acrylic acid derivative ①, 22.6 g of a norbornene derivative shown by the following formula (14) (hereinafter referred to as "norbornene derivative ③"), and 10.7 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.7 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 36 g (yield: 72 wt%) of white resin powder.

[0241] This resin was confirmed to be a copolymer having an Mw of 4,500, consisting of the recurring units derived from the norbornene derivative (I-1), (meth)acrylic acid derivative ①, norbornene derivative ③, and maleic anhydride at a proportion of 10 mol%, 20 mol%, 30 mol%, and 40 mol% respectively. This resin is referred to as a "resin (A-11)".

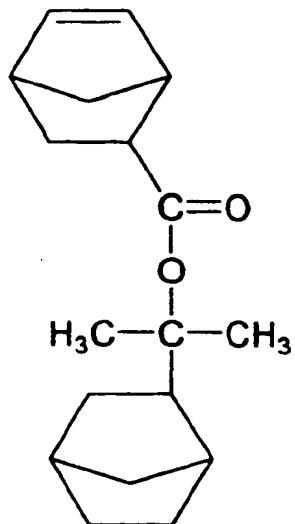
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(14)



Synthesis Example 23

25 [0242] 2.7 g of N,N-dimethylacrylamide, 12.0 g of (meth) acrylic acid derivative ①, 26.0 g norbornene derivative ③, and 9.3 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.7 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 37 g (yield: 74 wt%) of white resin powder.

30 [0243] This resin was confirmed to be a copolymer having an Mw of 4,500, consisting of the recurring units derived from N,N-dimethylacrylamide, (meth)acrylic acid derivative ①, norbornene derivative ③, and maleic anhydride at a proportion of 10 mol%, 20 mol%, 35 mol%, and 35 mol% respectively. This resin is referred to as a "resin (A-12)".

Synthesis Example 24

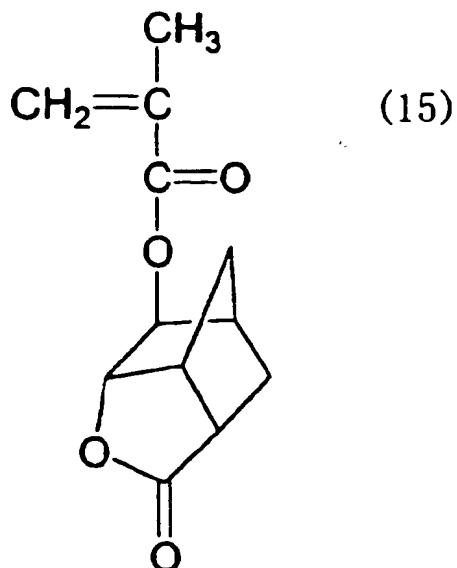
35 [0244] 2.4 g of N,N-dimethylacrylamide, 18.6 g of 2-methyl-2-adamantyl methacrylate, 28.0 g of a compound shown by the following formula (15), and 1.0 g of methacrylic acid were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.4 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 38 g (yield: 76 wt%) of white resin powder.

40 [0245] This resin was confirmed to be a copolymer having an Mw of 11,900, consisting of the recurring units derived from N,N-dimethylacrylamide, 2-methyl-2-adamantyl methacrylate, the compound shown by the formula (15), and methacrylic acid at a proportion of 10 mol%, 35 mol%, 50 mol%, and 5 mol% respectively. This resin is referred to as a "resin (A-13)".

50

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A14
A13



Synthesis Example 25

25 [0246] 2.5 g of N,N-dimethylacrylamide, 17.1 g of 1-ethylcyclohexyl methacrylate, 29.3 g of a compound shown by the above formula (15), and 1.1 g of methacrylic acid were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.4 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 39 g (yield: 78 wt%) of white resin powder.

30 [0247] This resin was confirmed to be a copolymer having an Mw of 10,900, consisting of the recurring units derived from N,N-dimethylacrylamide, 1-ethylcyclohexyl methacrylate, the compound shown by the formula (15), and methacrylic acid at a proportion of 10 mol%, 35 mol%, 50 mol%, and 5 mol% respectively. This resin is referred to as a "resin (A-14)".

35 Synthesis Example 26

40 [0248] 12.5 g of (meth)acrylic acid derivative ①, 26.4 g norbornene derivative ②, and 11.1 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.8 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 33 g (yield: 67 wt%) of white resin powder.

45 [0249] This resin was confirmed to be a copolymer having an Mw of 4,800, consisting of the recurring units derived from the (meth)acrylic acid derivative ①, norbornene derivative ②, and maleic anhydride at a proportion of 20 mol%, 40 mol%, and 40 mol% respectively. This resin is referred to as a "resin (a-12)".

Synthesis Example 27

50 [0250] 11.5 g of (meth)acrylic acid derivative ①, 28.4 g norbornene derivative ③, and 11.1 g of maleic anhydride were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.5 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 33 g (yield: 66 wt%) of white resin powder.

55 [0251] This resin was confirmed to be a copolymer having an Mw of 4,200, consisting of the recurring units derived from (meth)acrylic acid derivative ①, norbornene derivative ③, and maleic anhydride at a proportion of 20 mol%, 40 mol%, and 40 mol% respectively. This resin is referred to as a "resin (a-13)".

Synthesis Example 28

[0252] 20.0 g of 2-methyl-2-adamantyl methacrylate, 29.0 g of a compound shown by the above formula (15), and 1.0 g of methacrylic acid were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.2 g of azobisisobutyronitrile was added as an initiator. The mixture was heated to 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 39 g (yield: 78 wt%) of white resin powder.

[0253] This resin was confirmed to be a copolymer having an Mw of 11,500, consisting of the recurring units derived from 2-methyl-2-adamantyl methacrylate, the compound shown by the formula (15), and methacrylic acid at a proportion of 40 mol%, 55 mol%, and 5 mol% respectively. This resin is referred to as a "resin (a-14)".

Synthesis Example 29

[0254] 30.4 g of a compound shown by the above formula (15), 1.0 g of methacrylic acid, and 18.6 g of 1-ethylcyclohexyl methacrylate were dissolved in 50 g of tetrahydrofuran to obtain a homogeneous solution. After injection of nitrogen for 30 minutes, 2.2 g of azobisisobutyronitrile was added as an initiator. The mixture was heated at 65°C and stirred for 6 hours at this temperature. After the reaction, the reaction solution was cooled to room temperature and diluted with 50 g of tetrahydrofuran. The diluted solution was poured into 1,000 ml of n-hexane to cause the resin to precipitate, thereby obtaining 40 g (yield: 80 wt%) of white resin powder.

[0255] This resin was confirmed to be a copolymer having an Mw of 11,000, consisting of recurring units derived from the compound shown by the formula (15), methacrylic acid, 1-ethylcyclohexyl methacrylate at a proportion of 55 mol%, 5 mol%, and 40 mol% respectively. This resin is referred to as a "resin (a-15)".

[0256] Measurement and evaluation in the following examples and comparative examples were carried out as follows.

Mw:

[0257] Mw was measured by gel permeation chromatography (GPC) using GPC columns (manufactured by Tosoh Corp., G2000HXL x 2, G3000HXL x 1, G4000HXL x 1) under the following conditions. Flow rate: 1.0 ml/minute, eluate: tetrahydrofuran, column temperature: 40°C, standard reference material: monodispersed polystyrene

Radiation transmittance:

[0258] A solution composition was applied to a quartz plate and the coating was post-baked on a hot plate at 90°C for 60 seconds to obtain a resist film with a thickness of 1 μm. Radiation transmittance of the resist film was calculated from absorbance at a wavelength of 193 nm and was adopted as a standard for transparency in the deep UV ray region.

Sensitivity:

[0259] A solution composition was applied to a silicon wafer with a 520Å thickness Deep UV30 film (manufactured by Brewer Science Corp.) coated on the surface by spin coating and post-baked on a hot plate under the conditions shown in Table 2 to obtain a resist coating with a thickness of 0.34 μm. The coating was exposed to radiation through a mask pattern using an ArF excimer laser exposure apparatus (manufactured by Nikon Corp., lens numerical aperture: 0.55, wavelength: 193 nm). After performing PEB under the conditions shown in Table 2, the resist films were developed in a 38 wt% tetramethylammonium hydroxide aqueous solution, developed at 25°C for 1 minute, washed with water, and dried to form a positive-tone resist pattern. An optimum dose at which a line-and-space (1L1S) pattern with a line width of 0.16 μm was formed was taken as sensitivity.

Resolution:

[0260] The minimum dimension of a resist pattern resolved at the optimum dose was taken as the resolution of the resist coating.

Line width fluctuation value:

[0261] In the same manner as in the measurement of sensitivity described above, line-and-space patterns (1L1S) and (1L10S) were formed by exposing a resist sample with a light at the optimum optimum dose at which a one to one line-and-space pattern (1L1S) with a line width of 0.16 μm can be formed. The line width fluctuation value due to

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fluctuation of the space width was determined by measuring the difference between the line width for the line-and-space pattern (1L1S) and the line width for the line-and-space pattern (1L10S) by a scanning electron microscope.

Pattern configuration:

[0262] The dimensions of the lower side L_1 and the upper side L_2 of the rectangular cross-section of a line and space pattern (1L1S) with a line width of $0.16 \mu\text{m}$ were measured using a scanning electron microscope. A pattern shape which satisfied a formula " $0.85 = L_2/L_1 = 1$ " and was straight with no extended skirt was evaluated as "Good", and otherwise evaluated as "Bad".

10 Examples 43-48

[0263] Each composition solution having components shown in Table 10 was evaluated. The evaluation conditions are shown in Table 11, and the results are shown in Table 12. Components other than the polymers (A-9) to (A-14), and polymers (a-12) to (a-15) shown in Table 10 are as follows.

Acid generator (B)

[0264]

20 B-8: 1-(3,5-dimethyl-4-hydroxyphenyl)tetrahydrothiopheniumperfluoro-n-octanesulfonate
B-9: Bis(4-t-butylphenyl)iodonium perfluoro-n-octanesulfonate
B-10: Nonfluoro-n-butanesulfonylcyclo[2.2.1]hepto-5-ene-2,3-dicarboxyimide
B-11: Perfluoro-n-octanesulfonylcyclo[2.2.1]hepto-5-ene-2,3-dicarboxyimide

25 Acid diffusion control agent

[0265]

30 D-5: N-t-butoxycarbonyl-2-phenylbenzimidazole
D-6: N-t-butoxycarbonyldicyclohexylamine

Other additives

[0266]

35 F-4: Di-t-butyl 1,3-adamantanedicarboxylate
F-5: 2,5-Dimethyl-2,5-di(adamantylcarbonyloxy)hexane
F-6: 2-Methyl-2-adamantylcarbonyloxyadamantane

40 Solvent

[0267]

45 G-4: 2-Heptanone
G-5: Cyclohexanone
G-6: Propylene glycol monoethyl ether acetate

50 Table 10

	Copolymer	Acid Generator	Acid diffusion control agent	Other additives	Solvent
Example 43	A-9(9.0) a-12(81.0)	B-8(2.0) B-10(1.5)	D-5(0.10)	F-5(10)	G-6(530)
Example 44	A-10(9.0) a-12(81.0)	B-9(2.0) B-11(2.0)	D-5(0.01) D-6(0.09)	F-6(10)	G-4(430) G-5(100)

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Table 10 (continued)

	Copolymer	Acid Generator	Acid diffusion control agent	Other additives	Solvent
Example 45	A-11(9.0) a-12(81.0)	B-8(2.0) B-10(1.5)	D-5(0.02) D-6(0.08)	F-5(10)	G-4(430) G-5(100)
Example 46	A-12(9.0) a-13(81.0)	B-9(2.0) B-11(2.0)	D-5(0.10)	F-4(10)	G-6(530)
Example 47	A-13(9.0) a-14(81.0)	B-8(2.0) B-10(1.5)	D-5(0.06)	F-4(3)	G-4(430) G-5(100)
Example 48	A-14(9.0) a-15(81.0)	B-9(2.0) B-11(2.0)	D-5(0.06)	F-4(3)	G-4(430) G-5(100)

* check structures

Table 11

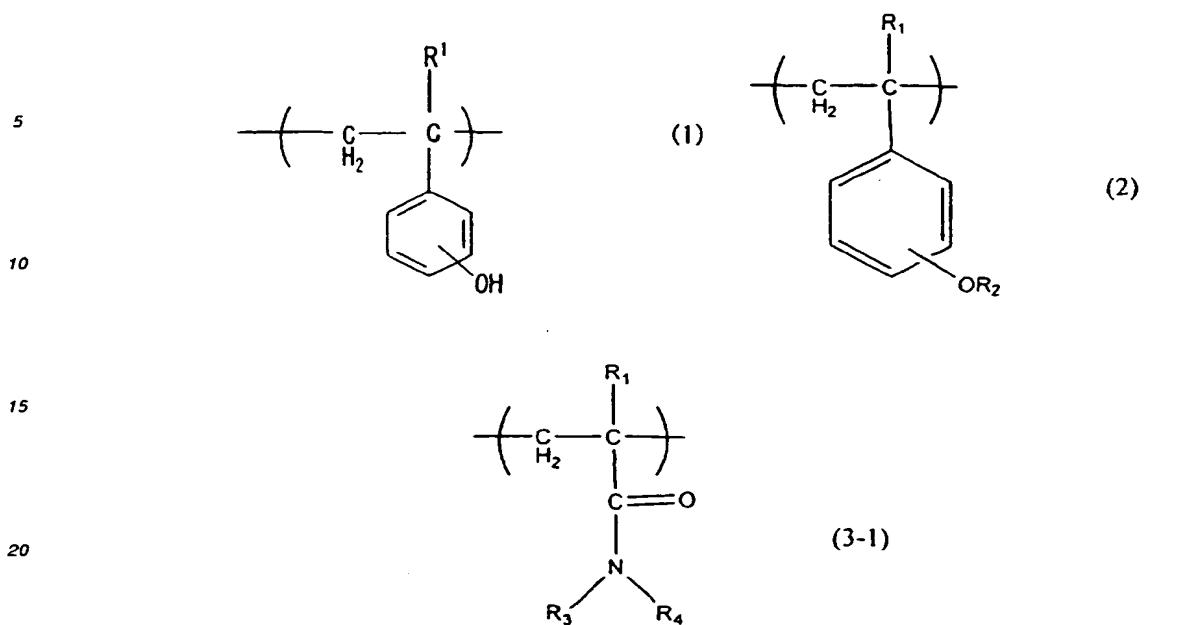
	Resist film thickness	Substrate form	PB		PEB	
			Temperature (°C)	Time (S)	Temperature (°C)	Time (S)
Example 43	0.34	ARC	130	90	120	90
Example 44	0.34	ARC	130	90	110	90
Example 45	0.34	ARC	130	90	120	90
Example 46	0.34	ARC	130	90	120	90
Example 47	0.34	ARC	130	90	130	90
Example 48	0.34	ARC	130	90	120	90

Table 12

	Radiation transmittance (193nm %)	Sensitivity (J/m ²)	Resolution (μm)	Line width fluctuation value (nm)	Pattern configuration
Example 43	70	300	0.14	10	Good
Example 44	74	260	0.14	5	Good
Example 45	69	320	0.14	9	Good
Example 46	68	290	0.14	11	Good
Example 47	70	300	0.14	9	Good
Example 48	72	270	0.14	13	Good

[0268] The radiation-sensitive resin composition of the present invention exhibits excellent resolution and pattern configuration, particularly excellent narrow space processing performance, is affected by PED only to a minimal extent, exhibits a minimal iso-dense bias, and capable of forming fine patterns at a high precision and in a stable manner. In addition, the radiation-sensitive resin composition effectively responds to various radiations such as ultraviolet rays, deep ultraviolet rays, X-rays, electron beams, and the like. Therefore, the radiation-sensitive resin composition of the present invention is suitable as a chemically-amplified positive resist used for fabricating semiconductor devices, which will become more and more minute.

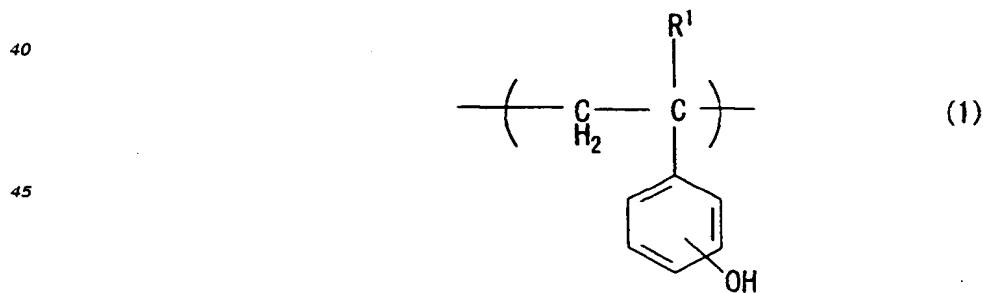
[0269] A chemically amplified radiation-sensitive resin composition comprising a specific copolymer and a photoacid generator, wherein the copolymer contains the following recurring unit (1) and/or the recurring unit (2), and the recurring unit (3-1),



Claims

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1. A positive-tone radiation-sensitive resin composition comprising (A1) a copolymer which comprises a recurring unit shown by the following formula (1) and/or a recurring unit shown by the following formula (2), and a recurring unit shown by the following formula (3-1), and (B) a photoacid generator,

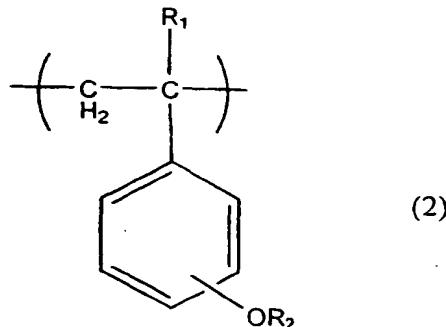


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wherein R¹ represents a hydrogen atom or a methyl group;

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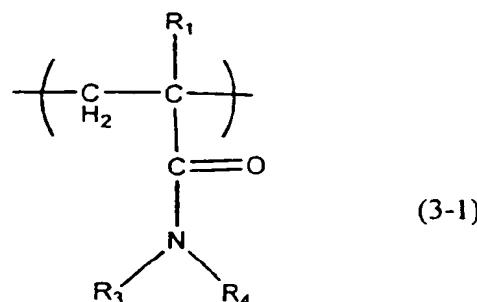


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wherein R¹ represents a hydrogen atom or a methyl group, and R² represents a tertiary alkyl group having 4-10 carbon atoms;

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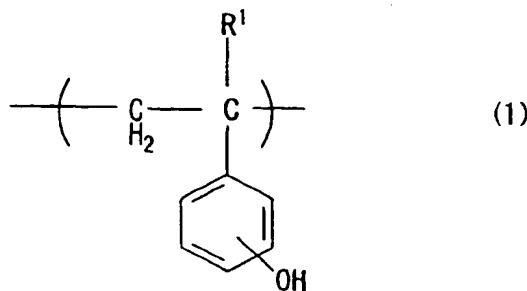
wherein R¹ represents a hydrogen atom or a methyl group, R³ and R⁴ individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted aromatic group having 6-15 carbon atoms, or a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or R³ and R⁴ may form, in combination and together with the nitrogen atom with which the R³ and R⁴ groups bond, a cyclic structure having 3-15 carbon atoms, provided that R³ and R⁴ are not a hydrogen atom at the same time.

35

2. The composition according to claim 1, wherein the recurring unit shown by the formula (3-1) is a unit derived from N,N-dimethyl(meth)acrylamide.
- 40 3. The composition according to claim 1, wherein the recurring unit shown by the formula (3-1) is a unit derived from 1-(meth)acryloyl-2-phenylbenzimidazole.
4. The composition according to claim 1, wherein the recurring unit shown by the formula (3-1) is a unit derived from 1-(meth)acryloyl imidazole.
- 45 5. The composition according to claim 1, wherein the component (B) is at least one compound selected from the group consisting of onium salt compounds and sulfonimide compounds.
6. The composition according to claim 1, wherein the copolymer (A1) comprises a recurring unit derived from a styrene compound in addition to the recurring units (1), (2), and (3-1).
- 50 7. A negative-tone radiation-sensitive resin composition comprising (A2) a copolymer which comprises a recurring unit shown by the following formula (1) and a recurring unit shown by the following formula (3-1), (B) a photoacid generator, and (C) a compound which can cross-link the copolymer (A1) in the presence of an acid,

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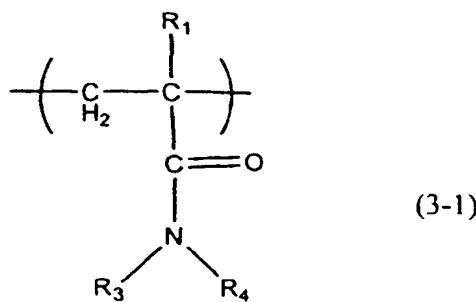
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wherein R^1 is the same as defined in claim 1;

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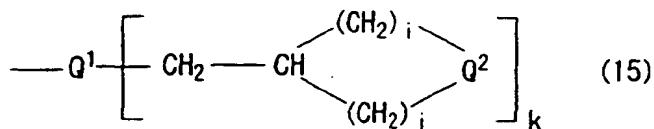
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wherein R^1 , R^3 , and R^4 are the same as defined in claim 1.

30 8. The composition according to claim 7, wherein the component (C) is a compound containing a group shown by the following formula (15), (16), (17), (18), or (19).

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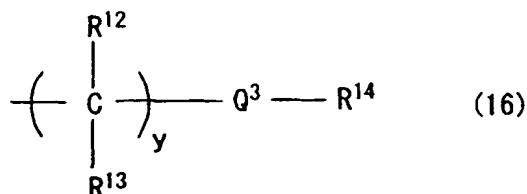


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wherein k is an integer of 1 or 2, Q^1 indicates a single bond, $-\text{O}-$, $-\text{S}-$, $-\text{COO}-$, or $-\text{NH}-$ when $k=1$ and a trivalent nitrogen atom when $k=2$, Q^2 is $-\text{O}-$ or $-\text{S}-$, i is an integer of 0-3, and j is an integer of 1-3, provided that $i+j$ is 1 to 4,

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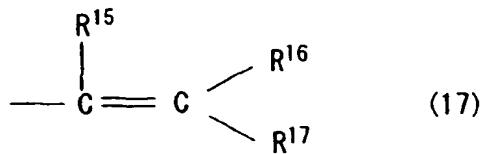
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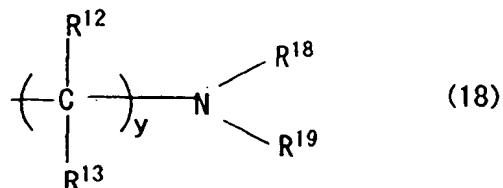
wherein Q^3 is $-\text{O}-$, $-\text{CO}-$, or $-\text{COO}-$, R^{12} and R^{13} individually represent a hydrogen atom or alkyl group having 1-4 carbon atoms, R^{14} represents an alkyl group having 1-5 carbon atoms, aryl group having 6-12 carbon atoms, or aralkyl group having 7-14 carbon atoms, and y is an integer of 1 or more,

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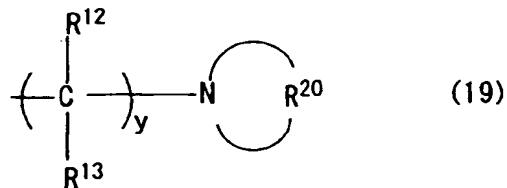
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10 wherein R¹⁵, R¹⁶, and R¹⁷ individually represent a hydrogen atom or an alkyl group having 1-4 carbon atoms,



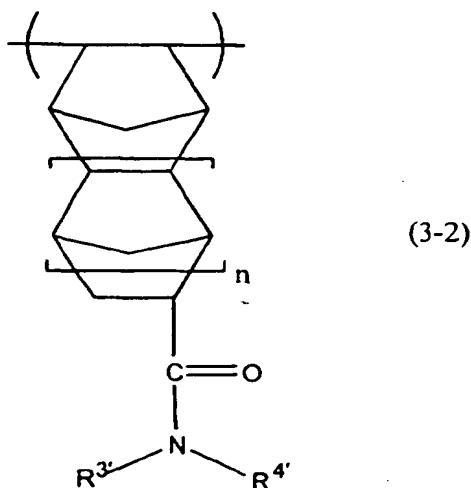
20 wherein R¹², R¹³, and y are the same as defined in the formula (16) and R¹⁸ and R¹⁹ individually represent an alkyl group having 1-5 carbon atoms or an alkylol group having 1-5 carbon atoms, and



30 wherein R¹², R¹³, and y are the same as defined in the formula (16), and R²⁰ represents a divalent organic group having a 3-8 member cyclic structure containing a hetero atom selected from an oxygen atom, sulfur atom, and nitrogen atom.

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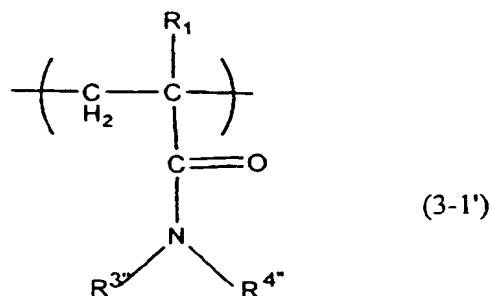
9. A radiation-sensitive resin composition comprising: (A) a resin which is insoluble or scarcely soluble in alkali and becomes alkali soluble by the action of an acid, the resin comprising the recurring unit (A3-1) of the following formula (3-2), and (B) a photoacid generator,



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R^{3'} and R^{4'} individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or a substituted or unsubstituted alkoxy carbonyl group having 2-13 carbon atoms, or R^{3'} and R^{4'} may form, in combination and together with the nitrogen atom with which the R^{3'} and R^{4'} groups bond, a cyclic structure having 3-15 carbon atoms, and n is an integer of 0-3.

10. A radiation-sensitive resin composition comprising: (A) a resin which is insoluble or scarcely soluble in alkali and becomes alkali soluble by the action of an acid, the resin comprising the recurring unit (A3-2) of the following formula (3-1') and having an alicyclic structure, and (B) a photoacid generator,



wherein R¹ represents a hydrogen atom or a methyl group, R3" and R4" individually represent a hydrogen atom, a substituted or unsubstituted alkyl group having 1-12 carbon atoms, a substituted or unsubstituted alkoxy group having 1-12 carbon atoms, or a substituted or unsubstituted alkoxy carbonyl group having 2-13 carbon atoms, or R3" and R4" may form, in combination and together with the nitrogen atom with which the R3" and R4" groups bond, a cyclic structure having 3-10 carbon atoms.

11. A radiation-sensitive resin composition comprising: (A) a resin which is insoluble or scarcely soluble in alkali and becomes alkali soluble by the action of an acid, the resin comprising the recurring unit (3-2) and/or the recurring unit (3-1') of the following formula, and the recurring unit (i) and/or the recurring unit (ii) of the following formula, and (B) a photoacid generator,

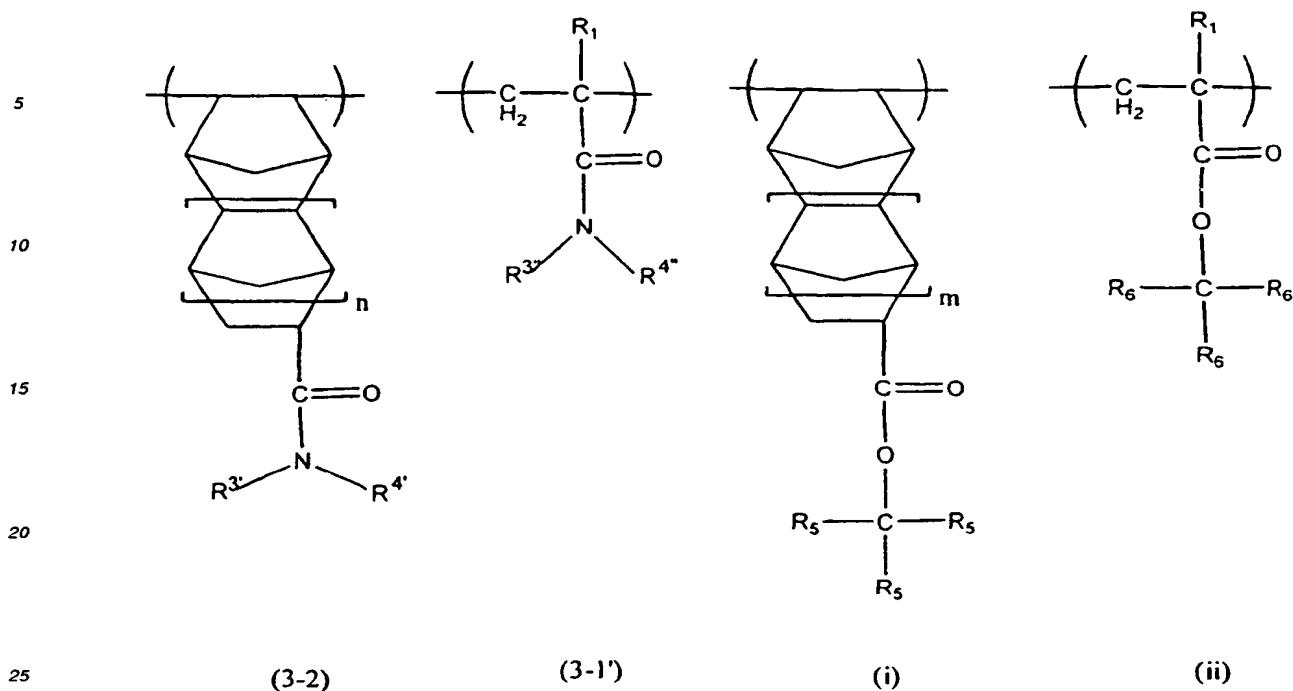
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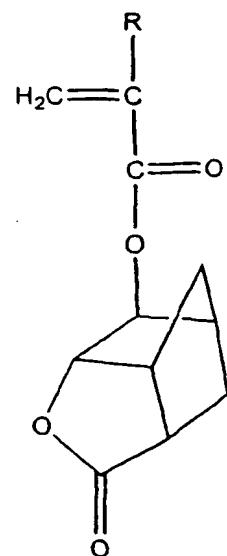
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wherein R1, R3', R4', R3", and R4" are the same as defined in claims 3 or 4; R5 individually represents a linear or branched alkyl group having 1-4 carbon atoms or a monoivalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, provided that at least one R5 is a linear or branched alkyl group having 1-4 carbon atoms, or any two R5 groups form, in combination and together with the carbon atoms to which the two R5 groups bond, a divalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, with the remaining R5 groups being a linear or branched alkyl group having 1-4 carbon atoms; R6 individually represents a linear or branched alkyl group having 1-4 carbon atoms or a monoivalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, provided that at least one R6 is a linear or branched alkyl group having 1-4 carbon atoms, or any two R6 groups form, in combination and together with the carbon atoms to which the two R6 groups bond, a divalent alicyclic hydrocarbon group having 4-20 carbon atoms or derivatives thereof, with the remaining R5 groups being a linear or branched alkyl group having 1-4 carbon atoms; and m and n are an integer of 0-3.

40 12. The composition according to claim 11, wherein the resin (A) comprises the recurring unit (3-1') and the recurring unit (ii).

13. The composition according to claim 12, wherein the resin (A) further comprises a recurring unit derived from a compound shown by the following formula (9),



14. The composition according to claim 11, further comprising a nitrogen-containing organic compound as an acid diffusion controller.

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EUROPEAN PATENT APPLICATION

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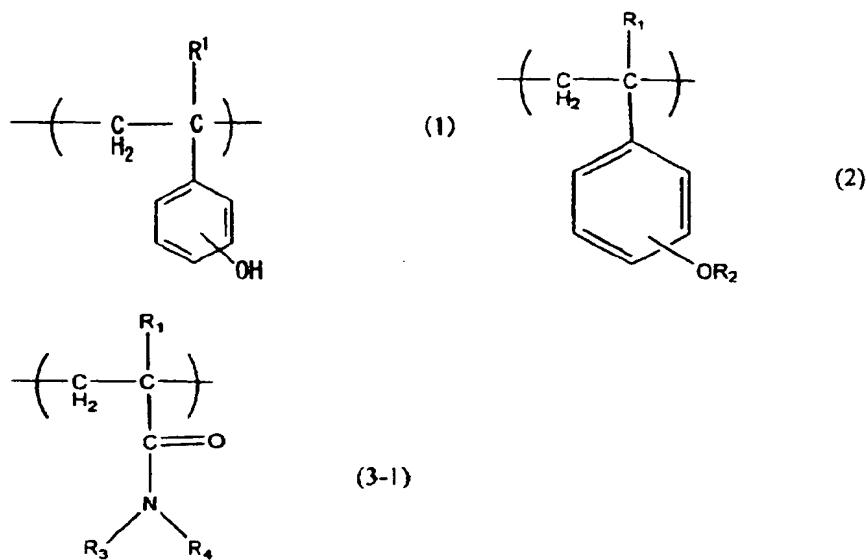
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(54) Radiation-sensitive resin composition

(57) A chemically amplified radiation-sensitive resin composition comprising a specific copolymer and a photoacid generator, wherein the copolymer contains the following recurring unit (1) and/or the recurring unit (2), and the recurring unit (3-1),



wherein R¹ is a hydrogen or methyl, R² is a C₄₋₁₀ tertiary alkyl, R³ and R⁴ are a hydrogen, C₁₋₁₂ alkyl, C₆₋₁₅ aromatic, C₁₋₁₂ alkoxy, or R³ and R⁴ may form, in combination and together with the nitrogen atom with which the R³ and R⁴ groups bond, a C₃₋₁₅ cyclic structure, provided that R³ and R⁴ are not a hydrogen atom at the same time. The composition effectively responds to various radiations, exhibits excellent resolution and pattern configuration and minimal iso-dense bias, and can form fine patterns at a high precision and in a stable manner.



DOCUMENTS CONSIDERED TO BE RELEVANT			CLASSIFICATION OF THE APPLICATION (Int.Cl.)
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	
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The present search report has been drawn up for all claims			
Place of search	Date of completion of the search	Examiner	
THE HAGUE	12 June 2002	Heywood, C	
CATEGORY OF CITED DOCUMENTS		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons R : member of the same patent family, corresponding document	
X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background D : non-written disclosure P : intermediate document			

**CLAIMS INCURRING FEES**

The present European patent application comprised at the time of filing more than ten claims.

Only part of the claims have been paid within the prescribed time limit. The present European search report has been drawn up for the first ten claims and for those claims for which claims fees have been paid, namely claim(s):

No claims fees have been paid within the prescribed time limit. The present European search report has been drawn up for the first ten claims.

LACK OF UNITY OF INVENTION

The Search Division considers that the present European patent application does not comply with the requirements of unity of invention and relates to several inventions or groups of inventions, namely:

see sheet B

All further search fees have been paid within the fixed time limit. The present European search report has been drawn up for all claims.

As all searchable claims could be searched without effort justifying an additional fee, the Search Division did not invite payment of any additional fee.

Only part of the further search fees have been paid within the fixed time limit. The present European search report has been drawn up for those parts of the European patent application which relate to the inventions in respect of which search fees have been paid, namely claims:

None of the further search fees have been paid within the fixed time limit. The present European search report has been drawn up for those parts of the European patent application which relate to the invention first mentioned in the claims, namely claims:



European Patent
Office

LACK OF UNITY OF INVENTION
SHEET B

Application Number
EP 01 12 2213

The Search Division considers that the present European patent application does not comply with the requirements of unity of invention and relates to several inventions or groups of inventions, namely:

1. Claims: 1-8

Radiation-sensitive resin composition containing copolymer including (t-alkyl protected) hydroxystyrene and (meth)acrylamide derivative(3-1)

2. Claims: 9-14

Radiation-sensitive resin composition including resin having bridged alicycle and amide functionality (either in the form of polymerized (meth)acrylamide derivative or pendant on bridged alicycle).

**ANNEX TO THE EUROPEAN SEARCH REPORT
ON EUROPEAN PATENT APPLICATION NO.**

EP 01 12 2213

This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EPO file on www.europeanpatentoffice.org. The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information.

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For more details about this annex : see Official Journal of the European Patent Office, No. 12/82

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